



INTERNATIONAL ATOMIC ENERGY AGENCY
UNITED NATIONS EDUCATIONAL, SCIENTIFIC AND CULTURAL ORGANIZATION
INTERNATIONAL CENTRE FOR THEORETICAL PHYSICS
I.C.T.P., P.O. BOX 586, 34100 TRIESTE, ITALY, CABLE: CENTRATOM TRIESTE



H4.SMR/845-8

Second Winter College on Optics

20 February - 10 March 1995

Optical Storage

K. Tatsuno

**Hitachi Ltd.,
Central Research Laboratory
Kokubunji, Tokyo
Japan**

Lecture Notes

- 2nd Winter College on Optics (ICO) -

" Optical Storage "

Kimio Tatsuno, Ph.D.

Central Research Laboratory, Hitachi Ltd.,
Kokubunji, Tokyo, Japan

Tel: 81-423-23-1111

Fax: 81-423-27-7673

E-mail: tatsuno@crl.hitachi.co.jp

February 28- March 1, 1995
International Center for Theoretical Physics
Trieste, Italy

Contents

1. Introduction

1.1 History, Advantages

1.2 Working principles

1.3 Aberration & Tolerance

2. Components & Applications

2.1 Optical Heads

Objective Lens, Diode lasers,
O/E detector,

2.2 Applications

Compact Disk, Disk Mastering,
Magneto-optical disks,
Phase-change-optical disks

3. Future

3.1 Multimedia System

3.2 Red/Green/Blue Lasers

3.3 Approaches for higher density

3.4 Evanescent wave Near Field memory

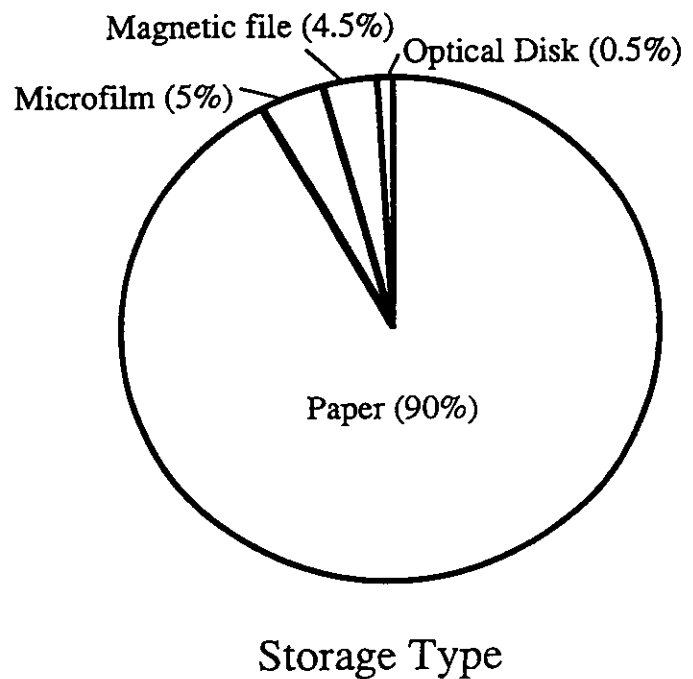
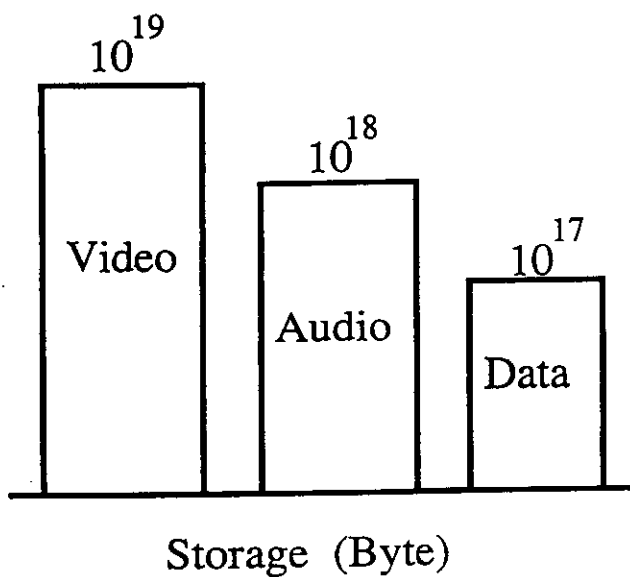
3.5 Photo-chemical Hole Burning

4. Conclusions

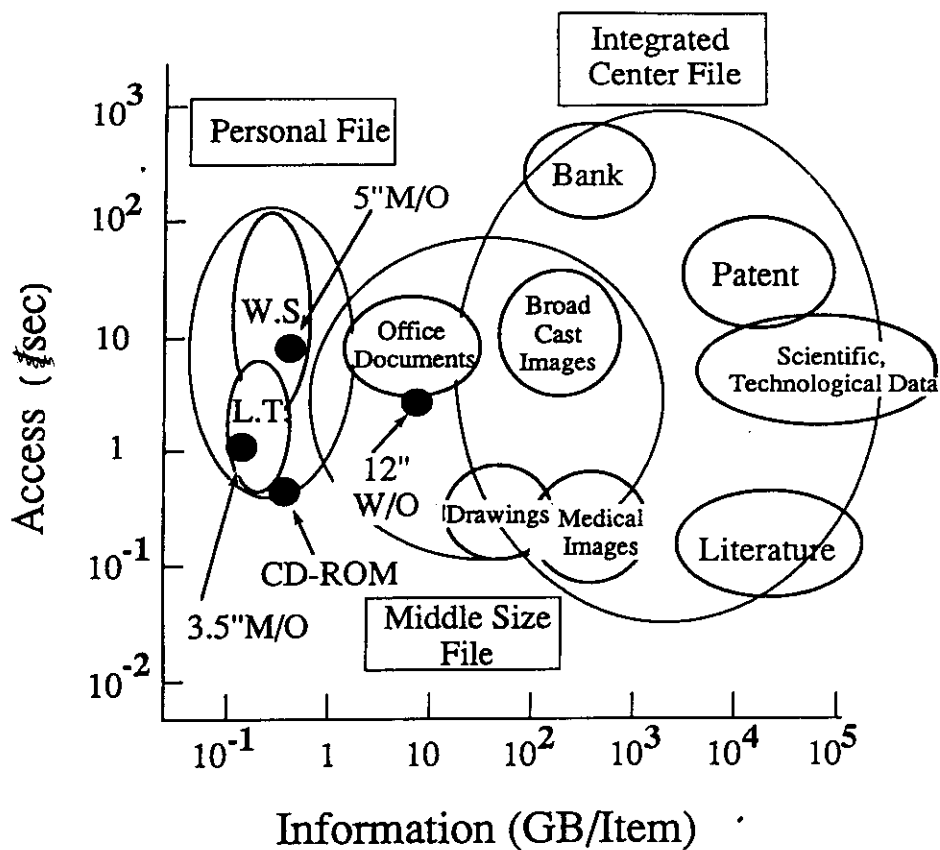
Package Media and Optical Network

History

	'60	'70	'80	'90	'00
Phase	1st Generation			2nd Generation	
	Research	Read Only	Eraserability	Higher Density	
Optical Disk	Holographic (BTL, Hitachi)	Phase Pit (Philips)	VD Prod. (Pioneer He-Ne) CD Prod. (Philips/Sony)	W/O Prod. (Toshiba) 5" M/O (Hitachi) 5" P/C (Matsushita)	DVD (Toshiba, Hitachi, Matsushita etc.) 3.5" M/O (Hitachi/Sony)
LD	Diode Laser (GE)	LD-RT-CW (BTL)	Low Power 780nm High Power 830nm	780nm	635nm 680nm



Optical Disk Market



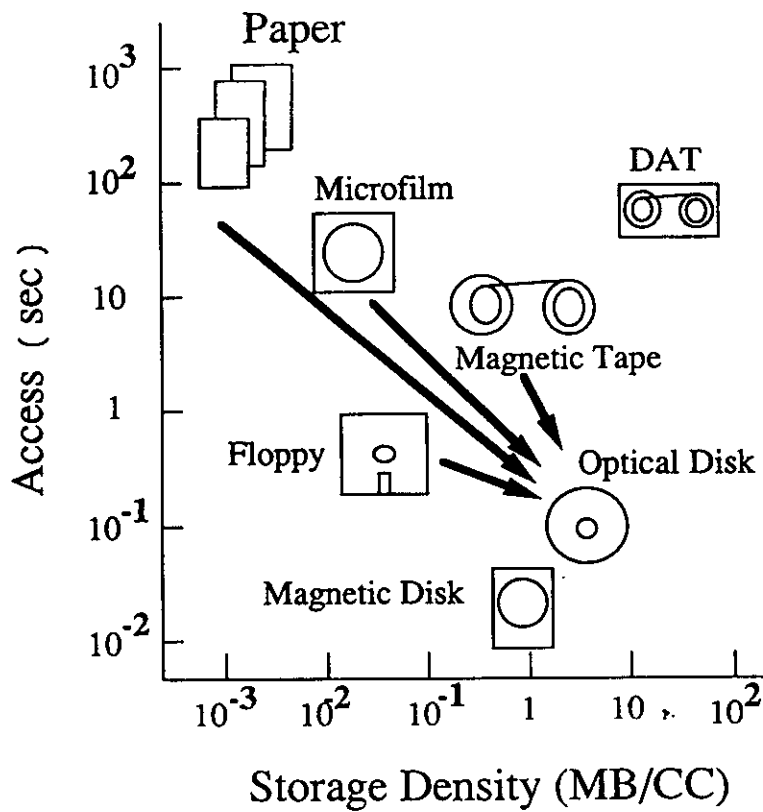
3

Advanteges of Optical Disks

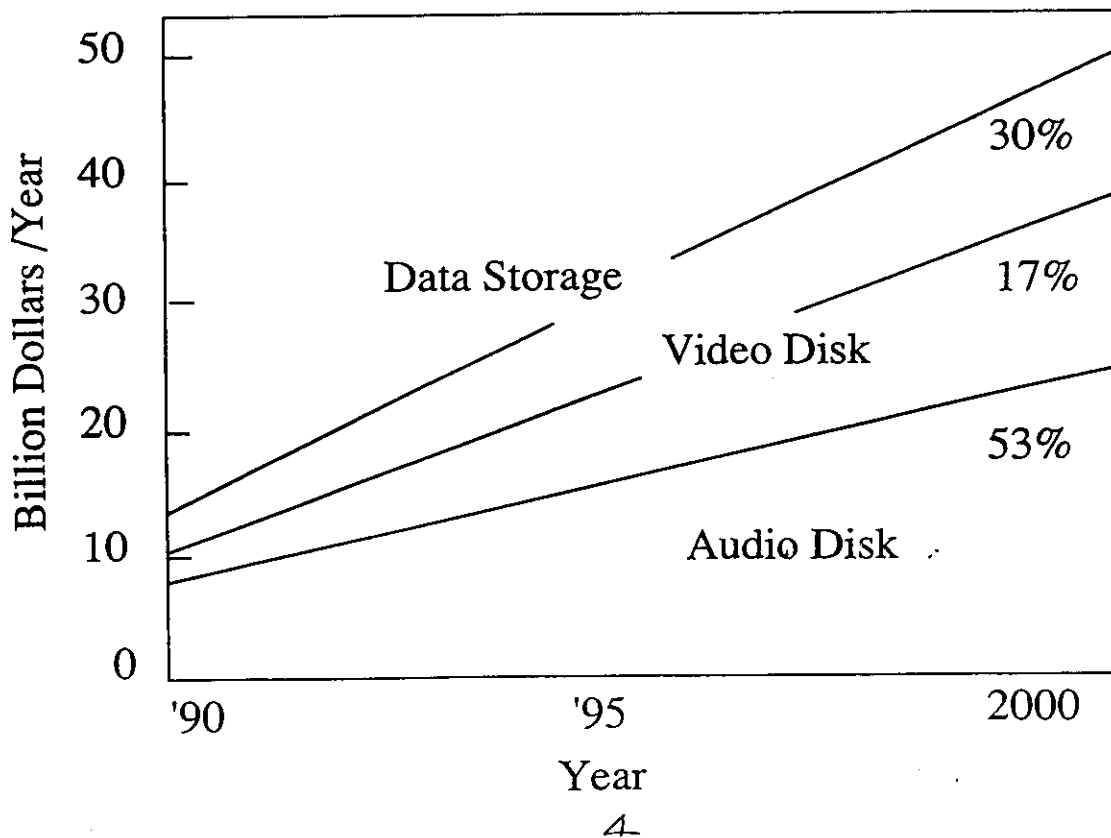
	Optical Disk	Magnetic Disk	Floppy	Magnetic Tape
Storage Density	⊙	○	△	⊙
Carrier	○	×	○	△
Access	△	○	×	×
Duplication	○ (CD, CD-ROM)	×	×	△
Bit Cost	△	△	⊙	○

- ⊙ Excelent
- Good
- △ Fair
- × No Good

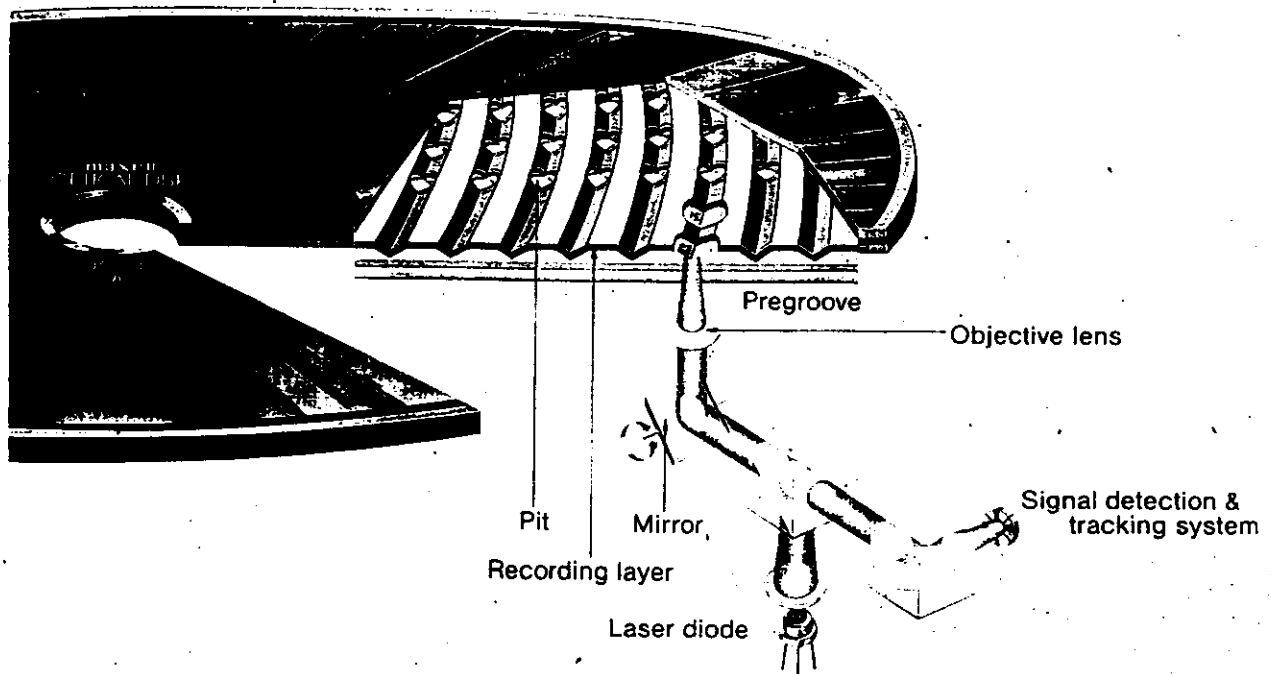
Optical Disk Replacement



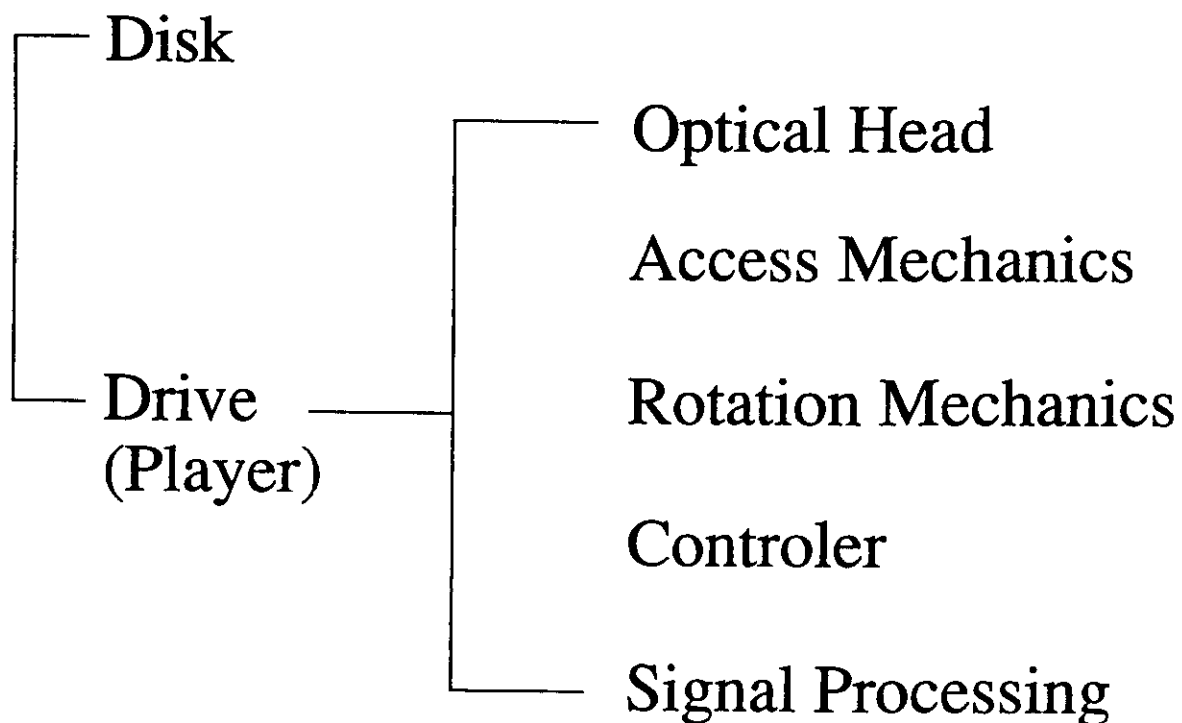
Optical Disk Market Size



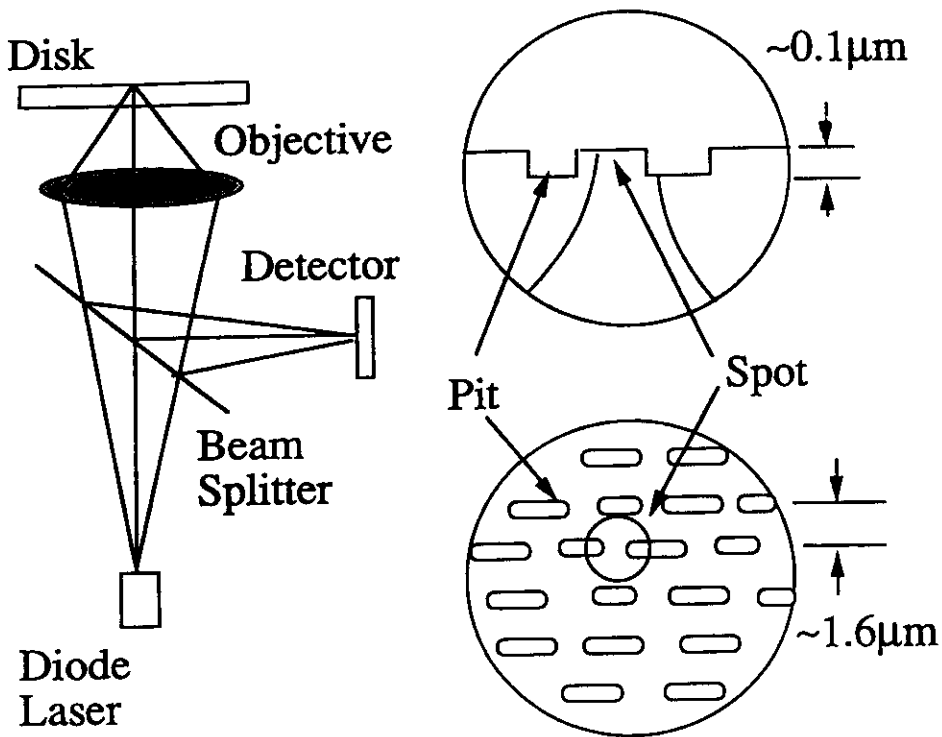
Structure of the optical disk



Optical Disk Memory Structure

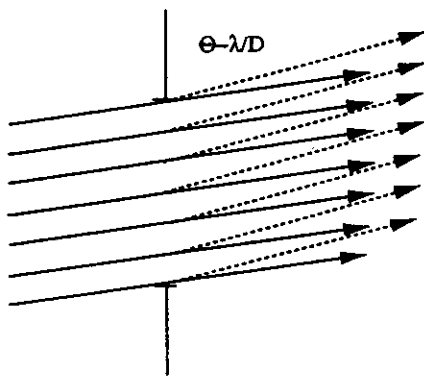


Optical Disk & Pick-Up

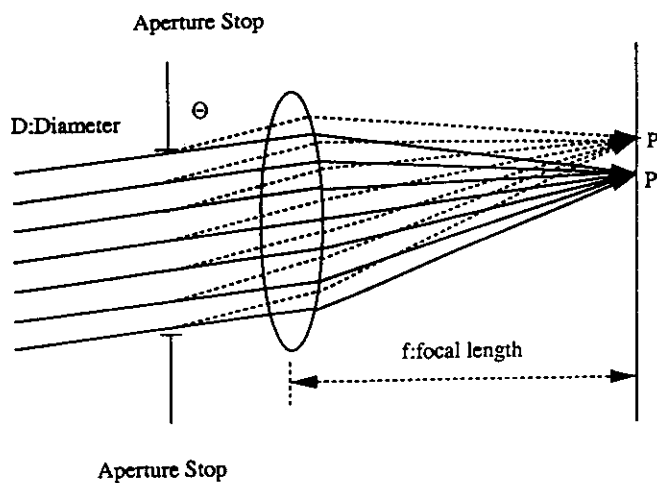


- 1) Diode laser facet is imaged and a spot is formed on the surface of the disk.
- 2) The spot size is about λ/NA and equal to the track pitch.
- 3) The storage density is $\sim (\lambda/\text{NA})^2$ approximately.
- 4) Auto-Focusing and Tracking are essential for the system.

Spot Profile



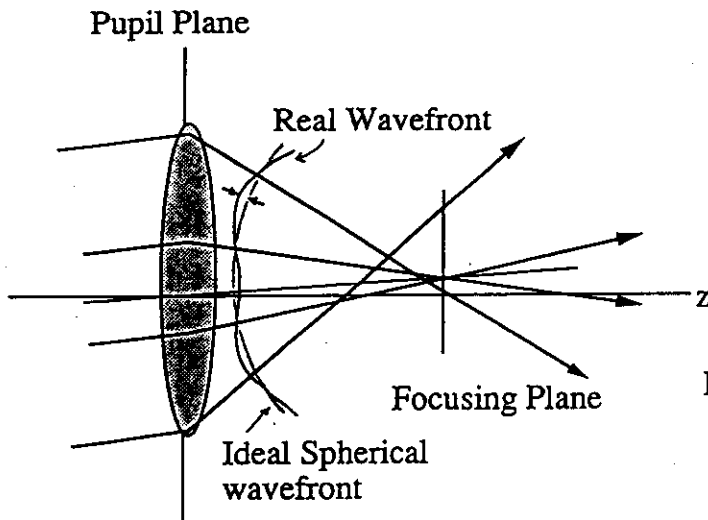
- 1) Diffraction by an aperture



- 2) Focusing by an aberration free lens

$$\text{Spot Size} = 2.44 f \lambda / D$$

Spot Profile & Pupil Function



Pupil Function:

$$P(\rho, \theta) = T(\rho, \theta) \exp \{ 2\pi i \Phi(\rho, \theta) \}$$

Amplitude :

$$T(\rho, \theta) = \exp \{ -\sigma \rho^2 \}$$

Phase of Wavefront =
(Wavefront - Ideal spherical wavefront)

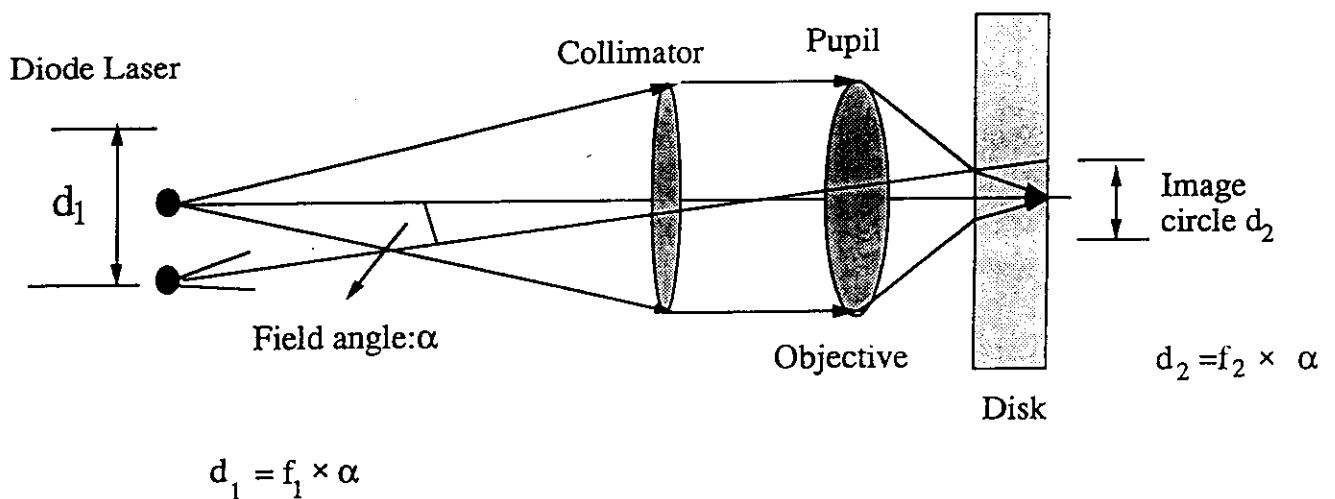
$\Phi(\rho, \theta)$ in units of λ

Spot Profile = Fourier Transform of a Pupil Function

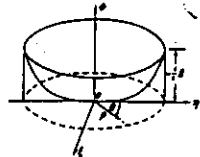
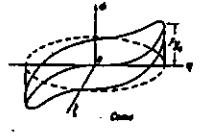
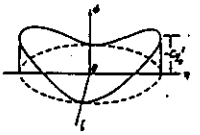
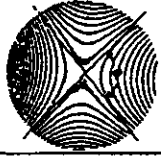
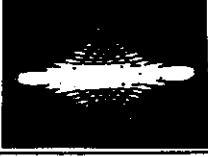
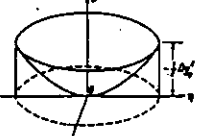
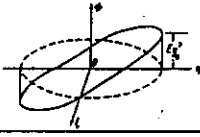
//2

Imaging Optics for a Diode Laser

Diffraction Limited, aberration free imaging optics with some field angle is required.



Third order Wave Aberration

Type	Expressin	Wavefront	Interference pattern	Image plane
Spherical	$A_{40} \rho^4$			
Coma	$A_{31} \rho^3 \cos(\theta - \theta_1)$			
Astigmatism	$A_{22} \rho^2 \cos^2(\theta - \theta_2)$			
Defocus (Curvature of field)	$A_{20} \rho^2$:Defocus			
Tilt (Distortion)	$A_{11} \rho \cos(\theta - \theta_1)$			

13

Distribution of the Aberration Margin

$$\begin{aligned} \sqrt{\iint (\Phi_1 + \Phi_2)^2} &= \sqrt{\iint (\Phi_1^2 + \Phi_2^2 + 2\Phi_1\Phi_2)} \\ &= \sqrt{\iint (\Phi_1^2 + \Phi_2^2)} \end{aligned}$$

$$\iint \Phi_1 \Phi_2 \rho \, d\rho \, d\theta = 0 \quad \text{Orthogonal (No Correlation)}$$

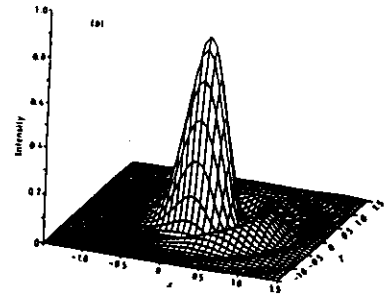
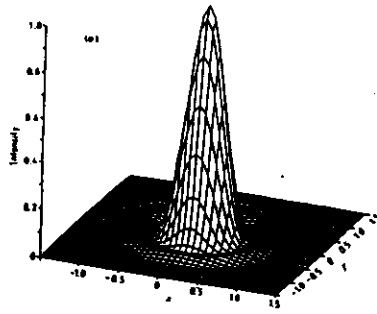
$$(\text{RMS})_p = (\text{RMS})_d \leq 0.05 \lambda$$

Aberration Tolerance for the Diode Lasers

$$(\text{RMS})_{\text{DL}} = (\text{RMS})_{\text{Ob}} \leq 0.035 \lambda$$

Marechal Criterion

$$\text{RMS} < 0.07\lambda$$



Strehl Intensity

$$I = \frac{1}{\pi^2} \left| \int_0^1 \int_0^{2\pi} e^{ik\Phi} \rho d\rho d\theta \right|^2$$

$$= \frac{1}{\pi^2} \left| \int_0^1 \int_0^{2\pi} \left\{ 1 + ik\Phi + \frac{1}{2}(ik\Phi)^2 + \dots \right\} \rho d\rho d\theta \right|^2$$

$$= 1 - (2\pi/\lambda)^2 (\text{RMS})^2 > 0.8$$

Root Mean Square of the Wave Aberration

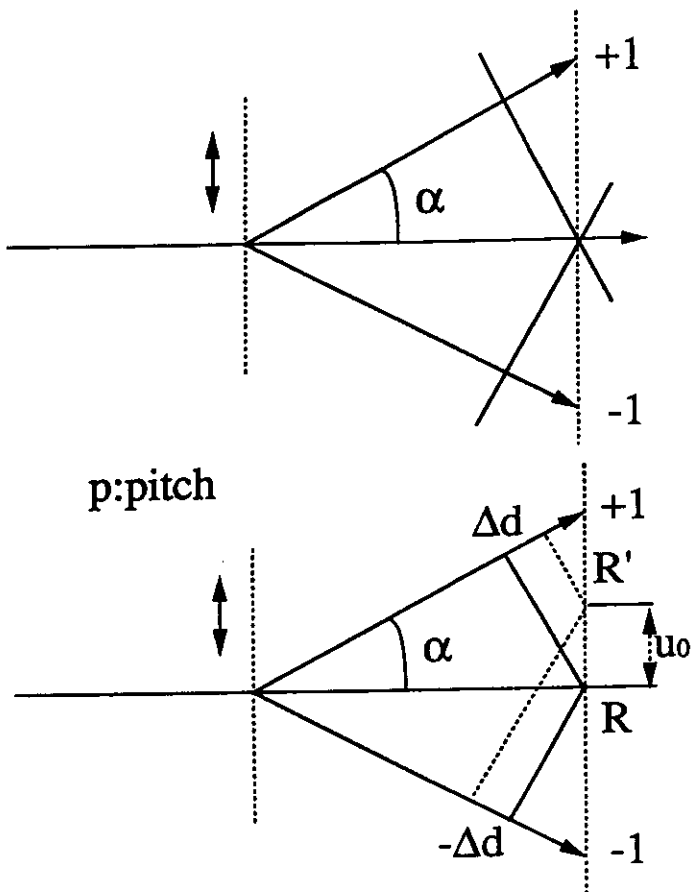
$$(\text{RMS})^2 = \frac{\int_0^1 \int_0^{2\pi} \Phi^2(\rho, \theta) \rho d\rho d\theta}{\int_0^1 \int_0^{2\pi} \rho d\rho d\theta}$$

14

Aberrations in Optical Disk

Aberration	Player	Disk
Spherical	Objective lens	Thickness Err.
Coma	Objective, Turn table Tilt	Bending
Astigmatism	Diode Laser, Objective	Shrink
Defocus	Objective	—
Tolerance	$< 0.05\lambda$	$< 0.05\lambda$
System Tolerance	$< 0.07\lambda$ Marechal Criterion	

$\lambda \rightarrow$ 短
 $\downarrow$
 残差精度



- 1) Relationship between Diffraction angle α and grating pitch p ;

$$\sin \alpha = \lambda / p$$

where λ is wavelength.

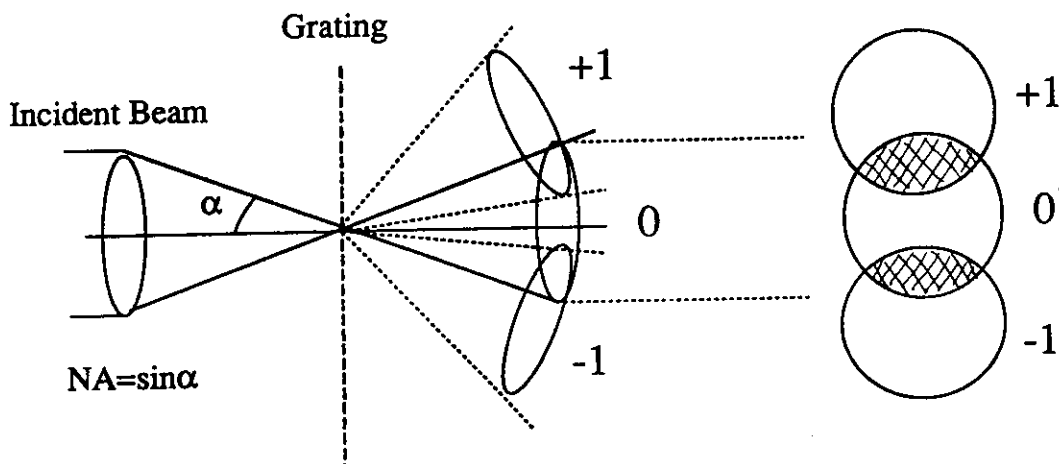
- 2) Phase difference between zeroth and first order diffracted beam;

$$\Delta \phi = 2\pi \Delta d / \lambda = 2\pi u_0 / p$$

where,

$$\Delta d = u_0 \sin \alpha = u_0 \lambda / p$$

Interference of Diffracted beams



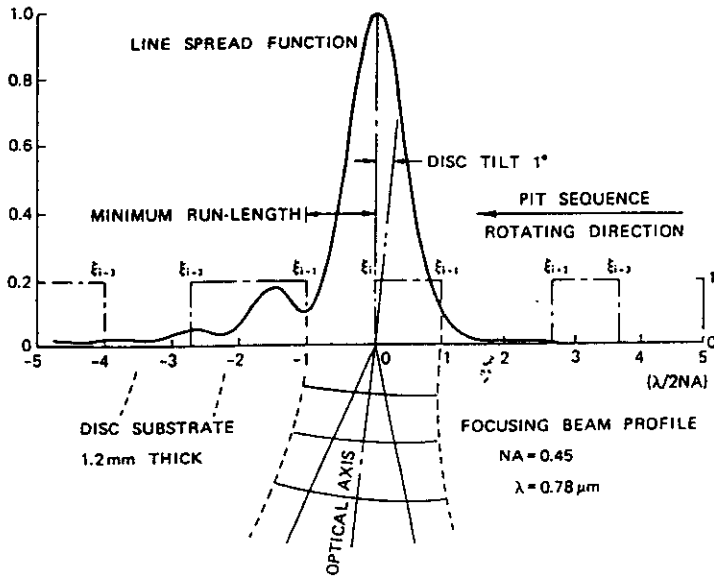
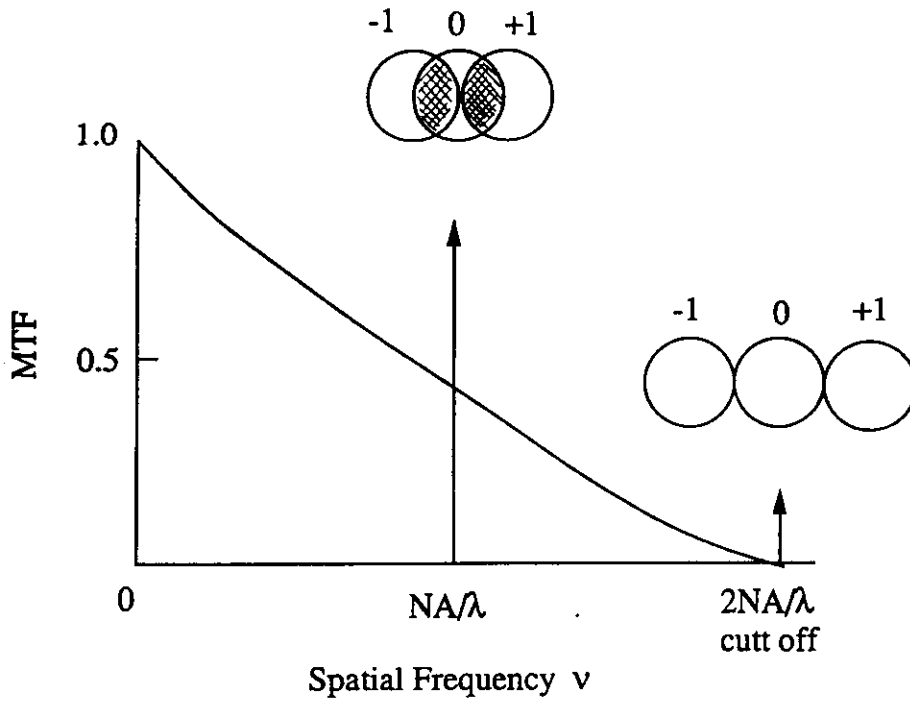
Time dependent Intensity is given by

frequency:
 $v = s/p$
 s : speed (m/s)

$$I(t) = |A_0 + A_{+1} \exp(i\Delta\phi_{+1}) + A_{-1} \exp(-i\Delta\phi_{+1})|^2$$

$$\sim A_0^2 \left\{ 1 + \frac{4A_{+1}}{A_0} \cos(2\pi vt) \right\}$$

Modulation Transfer Function



$$x = \xi_i, (\xi_0 < \xi_1 < \dots < \xi_N)$$

$$p_i = \xi_i - \xi_{i-1}$$

$$g(x) = \begin{cases} 1 & \xi_{2i-1} < x < \xi_{2i} \\ 0 & \text{otherwise} \end{cases} \quad (2)$$

$$f(x) = \int_{-\infty}^{\infty} g(\xi) h(x - \xi) d\xi \quad (3)$$

$$= \sum_{i=1}^{\infty} \int_{\xi_{2i-1}}^{\xi_{2i}} h(x - \xi) d\xi$$

$$= \sum_{i=1}^{\infty} (-1)^{i-1} H(x - \xi_i) \quad (4)$$

$$H(x) = \int_{-\infty}^x h(\xi) d\xi \quad (5)$$

$$f(x) = \sum_{i=2m-2r+1}^{2m} (-1)^{i-1} H(x - \xi_i) \quad (6)$$

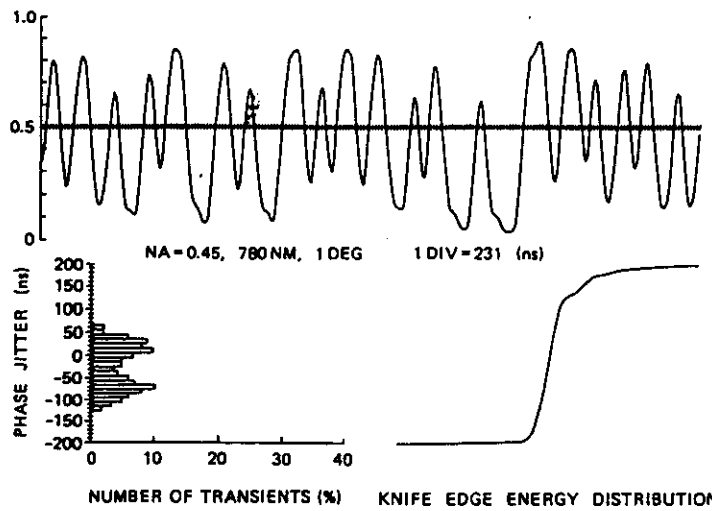


Fig. 12 Simulated eye diagram, jitter histogram and knife edge energy distribution function when disc tilts 1°.

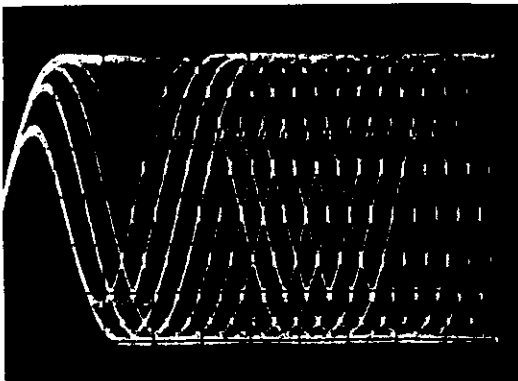


Fig. 3 Eye diagram when disc tilts 0°. $NA=0.47$, $\theta=0^\circ$, $\lambda=0.78 \mu\text{m}$

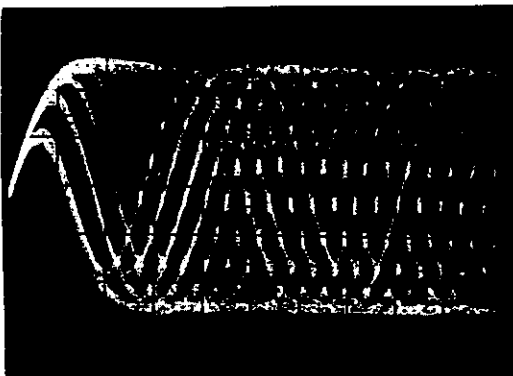


Fig. 5 Eye diagram when disc tilts 1°.

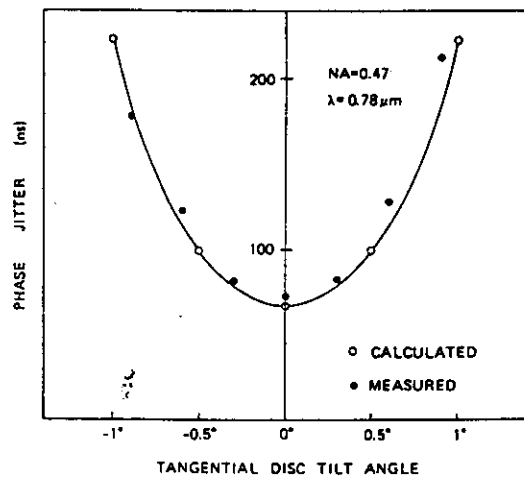
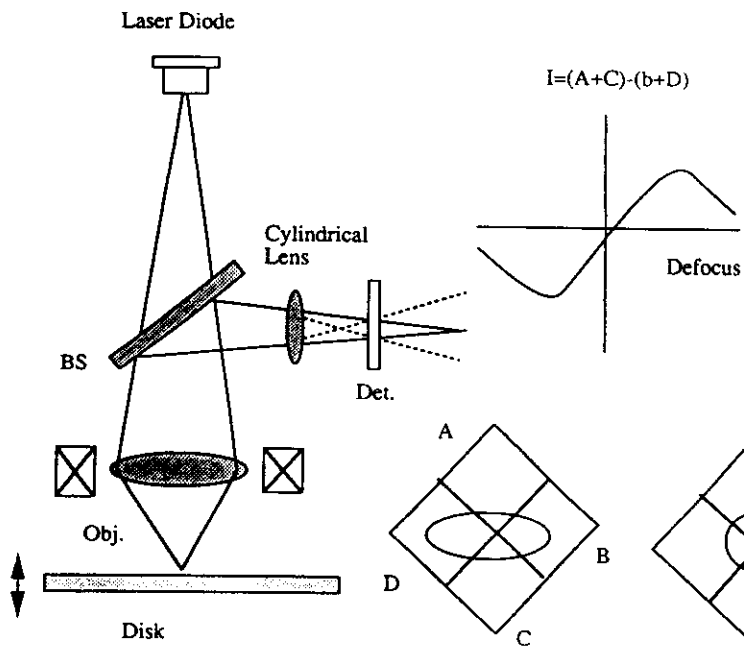
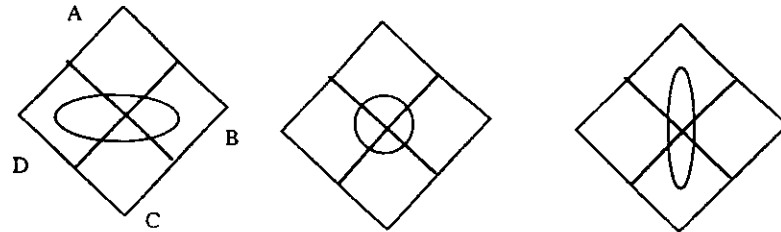


Fig. 13 Peak-to-Peak phase jitter vs. disc tilt angle in the scanning direction; Calculated and measured values are shown.

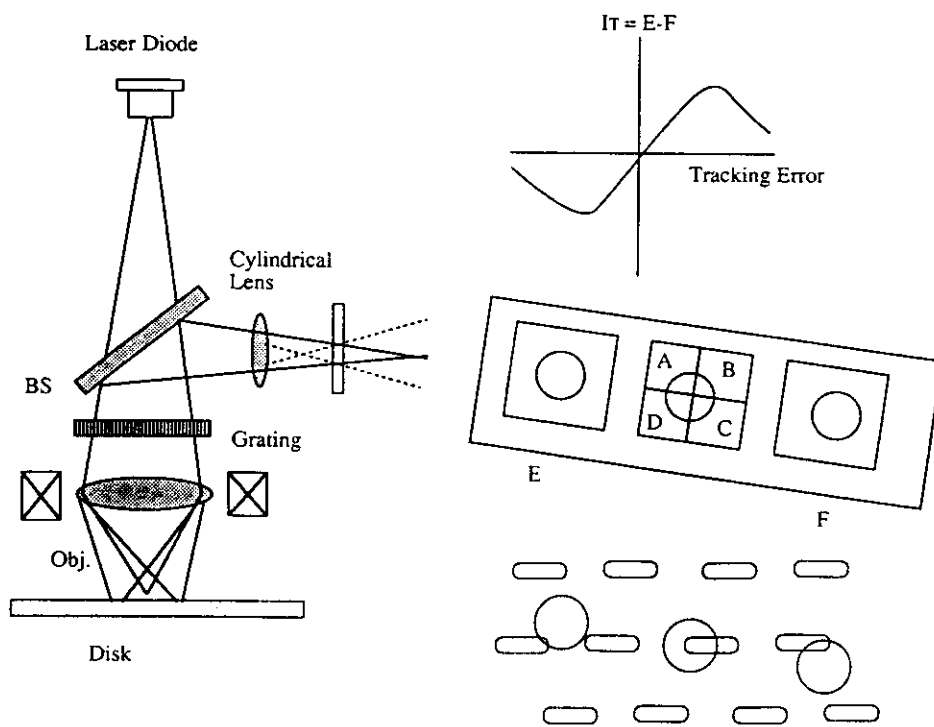
Auto-Focusing



- 1) Astigmatic
- 2) Critical Angle
- 3) Foucault

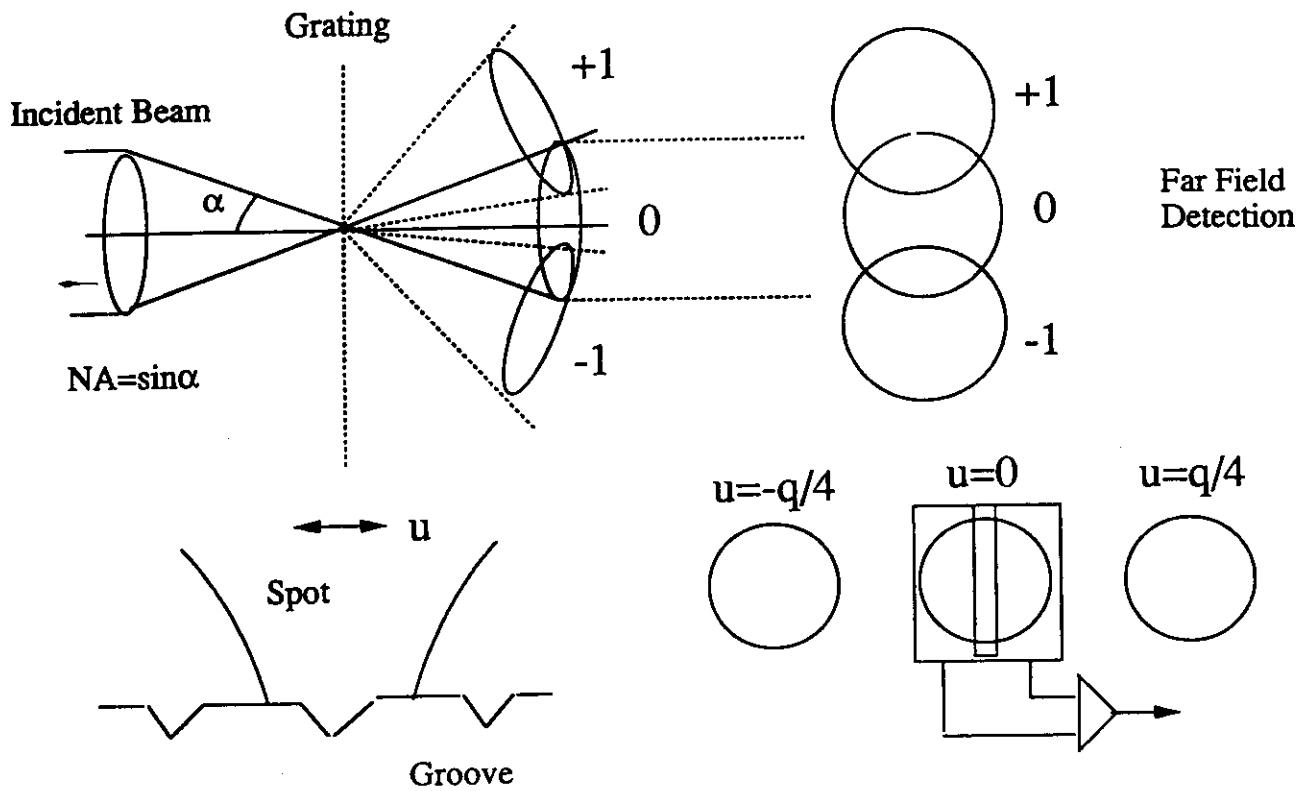


Auto-Tracking

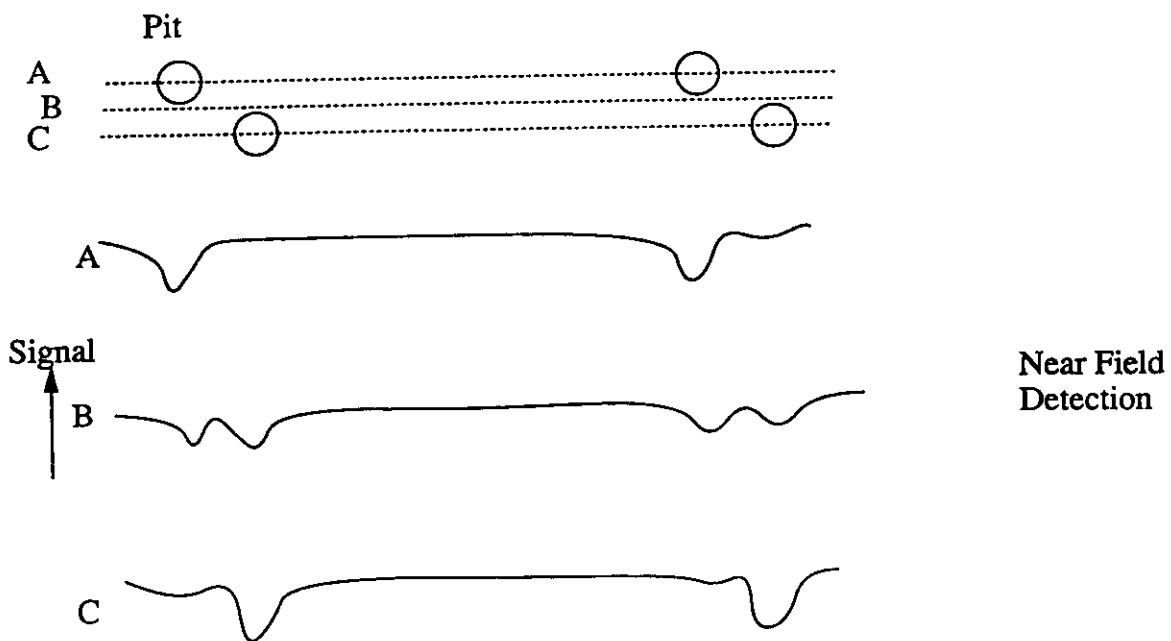


- 1) 3-Spot
- 2) Far Field
- 3) Sampling

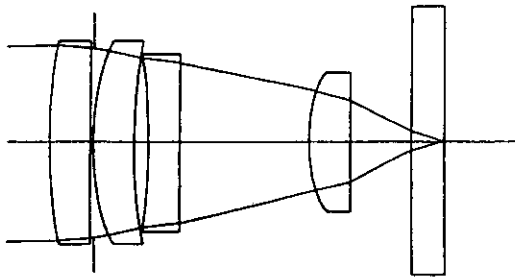
Tracking- Push-Pull



Tracking-Sampled Servo

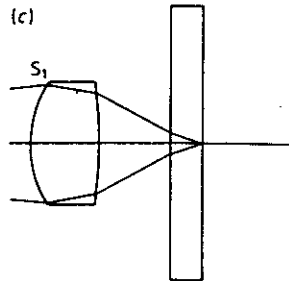


conventional



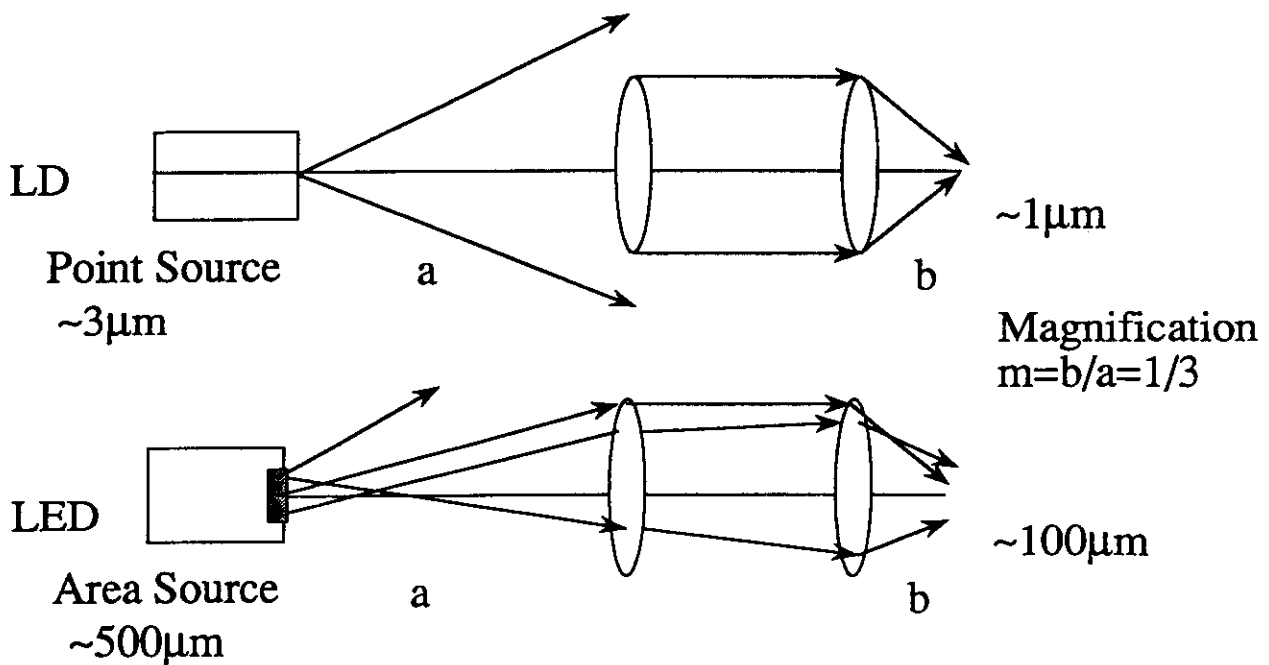
Focal Distance	8mm
NA	0.45
Field Diameter	1.0mm
Field curvature	6 μ m at the rim
Diameter	7.5mm
Length	11mm
Weight	<2g (mount included)

Aspheric

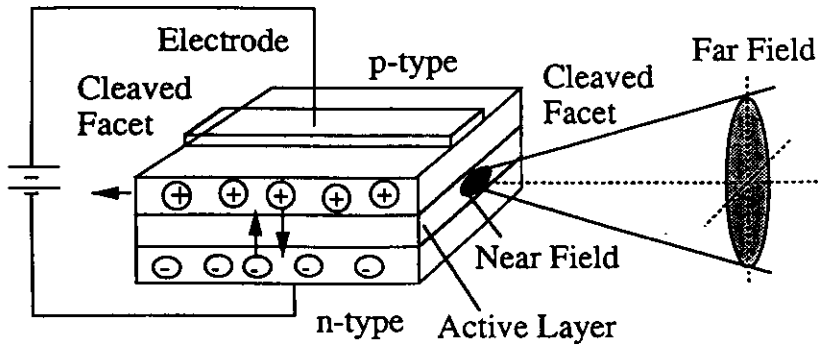


Focal Distance	3.7mm
NA(object side)	0.10
NA(image side)	0.45
Field Diameter	1.0mm
Field curvature	2 μ m at the rim
Asphericity	11 μ m(respect to the best fit sphere)
Diameter	4.1mm
Thickness	3.2mm
Weight	<0.25g (mount included)

Why Laser?



Diode Laser Structure



- 1) Small size: 400*100*100μm
- 2) Highly Efficient
ex. He-Ne < 0.1%
- 3) High Frequency Direct Modulation ~ GHz
- 4) Wide Wavelength Region
- 5) Long Life time
- 6) Mass Production, Low Cost

Electron- Hole Recombination----- $\lambda(\text{nm}) = 1.240/E_g$
 Carrier Density $> 1 \times 10^{18}$ -----Population Inversion (Gain)

- 1) Astigmatism
- 2) Feed-back Noise

3. Optical Characteristics

There are two types of LD chips presently produced by Hitachi, Ltd.: the HLP-1000 and the HLP-2000. Both of these chips are made of DH-structure AlGaAs material, but differ in operating current, output power level and certain other characteristics as shown in Table I. Several types of packages, the HLP-1000 series and the HLP-2000 series, are available from Hitachi, Ltd., as explained in 5.

Table I. Optical and electrical characteristics ($T_{hs} = 25^\circ\text{C}$)

HLP-1000

Item	Symbol	Test Condition	min.	typ.	max.	Unit
Threshold Current	I_{th}			70	100	mA
Output Power	P_o	$I_f = I_{th} + 25\text{mA}$	4	5		mW
Forward Voltage Drop	V_f	$I_f = 100\text{mA}$		1.8		V
Wavelength	λ_p		800	830	850	nm
Beam Divergence				10×30		deg.
Rise and Fall Time	τ_r, τ_f				0.5	ns

HLP-2000

Item	Symbol	Test Condition	min.	typ.	max.	Unit
Threshold Current	I_{th}			20	35	mA
Output Power	P_o	$I_{th} + 5\text{mA}$	0.75	1		mW
Forward Voltage Drop	V_f	$I_f = 25\text{mA}$		1.8		V
Wavelength	λ_p		800	830	850	nm
Beam Divergence				35×40		deg.
Rise and Fall Time	τ_r, τ_f				0.5	ns

$I_{th} \propto I_0 e^{-T/T_0}$

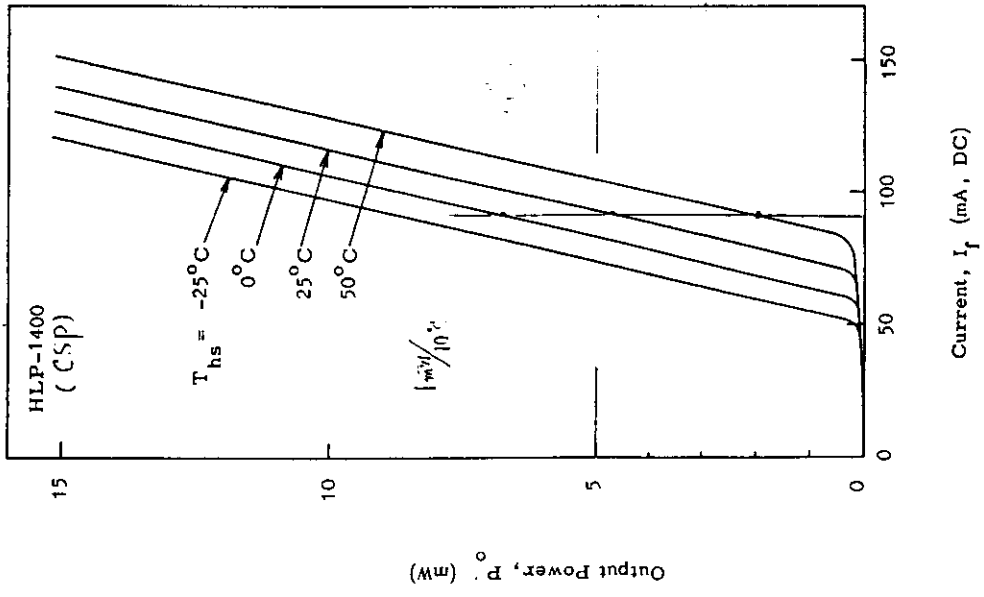


Fig. 2 Typical light vs current characteristics of HLP-1000 diodes.

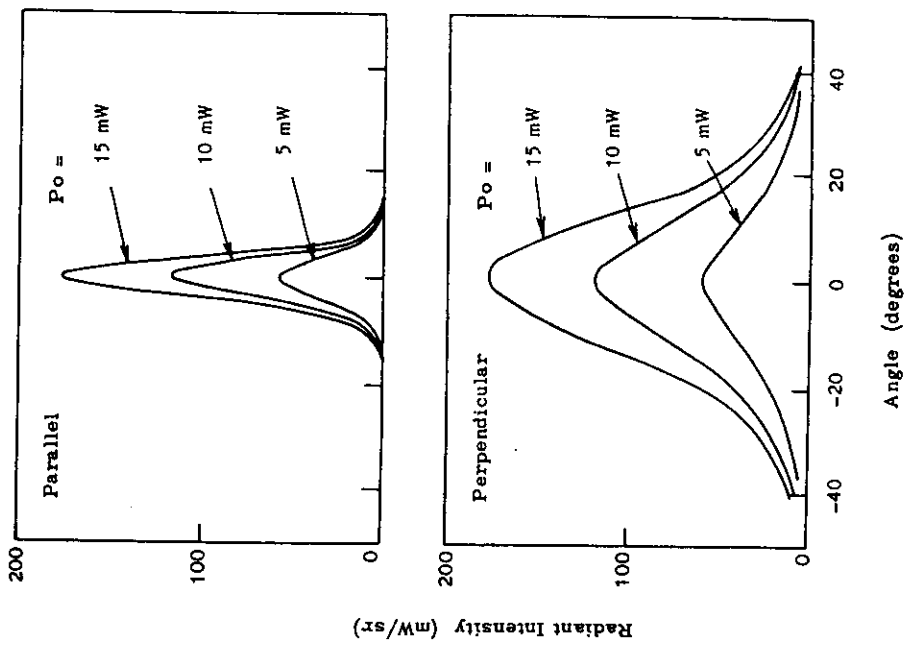


Fig. 6 Typical far-field patterns of HLP-1000 diodes parallel and perpendicular to the junction plane.

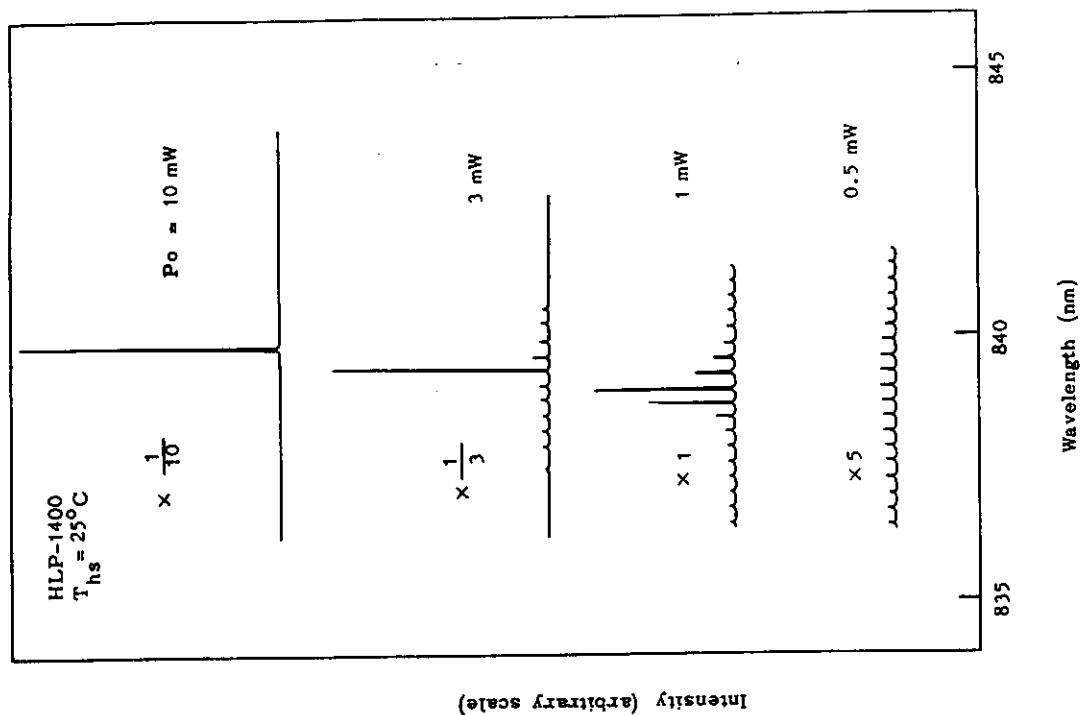
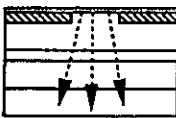
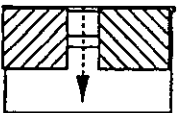
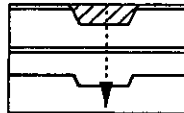
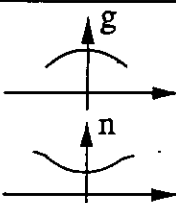
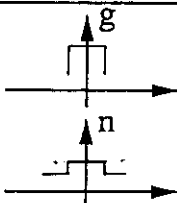
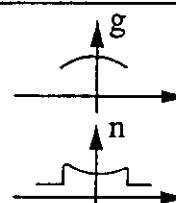
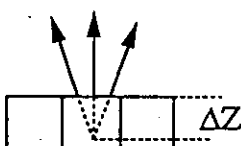
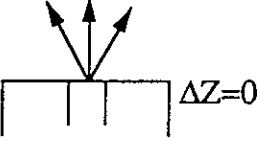
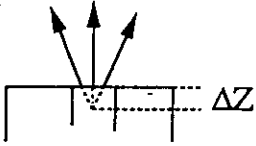


Fig. 8 Typical emission spectra of HLP-1000 diodes at various output power levels.

Laser Specifications for Optical Disks

		Specifications
Output Power	Read	3-5 mW
	Record	>30 mW
		Modulation
Lateral Mode		Fundamental Single
Aberration		0.03λ rms
Noise		< -120dB/Hz
Size		< (10 ϕ ~30mm)
Temperature		0----50°C

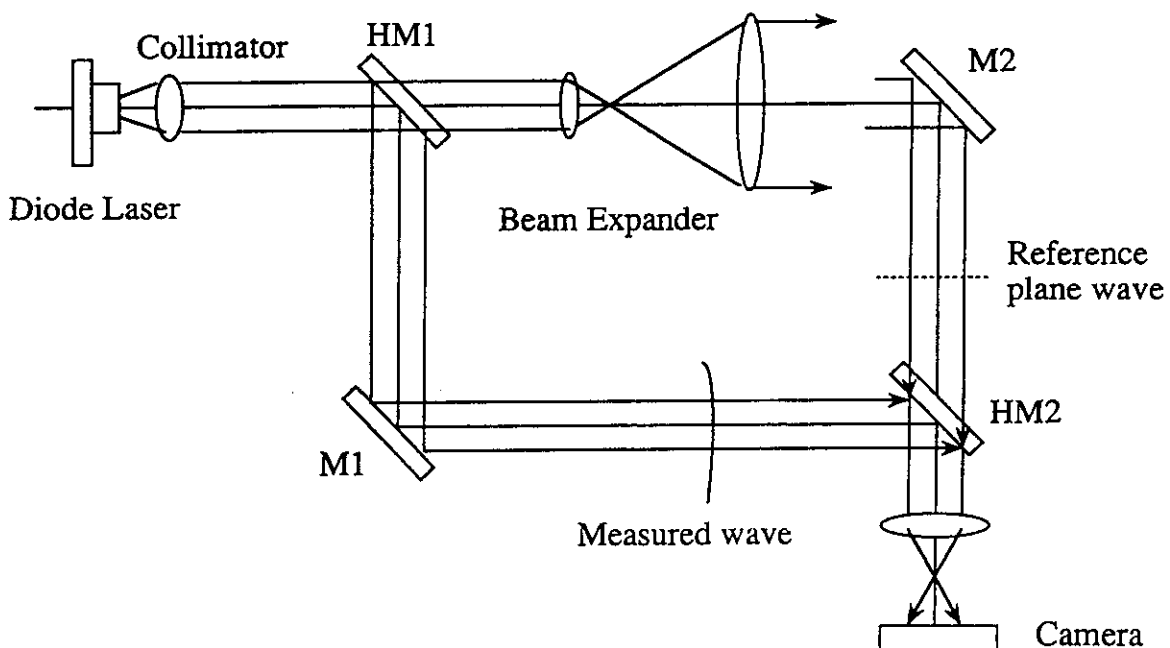
Diode Laser Astigmatism

	Gain Guided	Index Guided	Q-Index Guided
Structure	 Blocking Active Layer Proton Bomb.	 Buried Hetero	 Channeled Substrate
Gain Ref. Index			
Top View	 ΔZ	 $\Delta Z=0$	 ΔZ

ΔZ : Astigmatic Distance

17

Interferometric Measurement



19

19



(a)

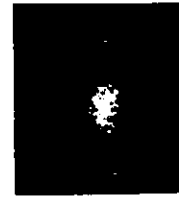


(b)

BH (830nm)

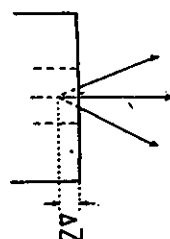
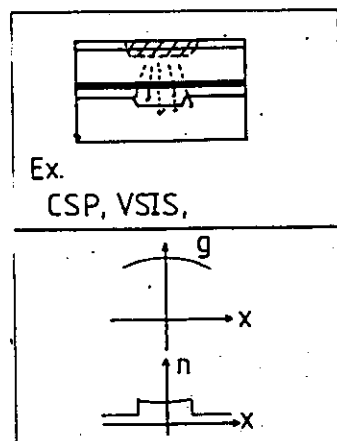
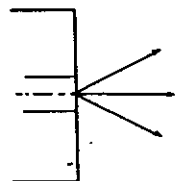
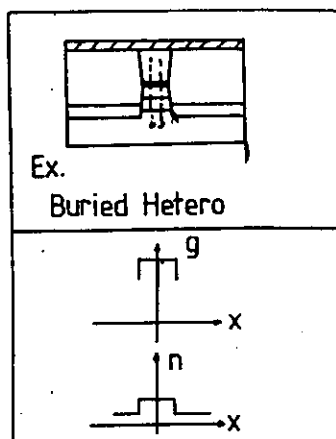


(a)



(b)

CSP (750nm)



Index Guide

Quasi-index Guide

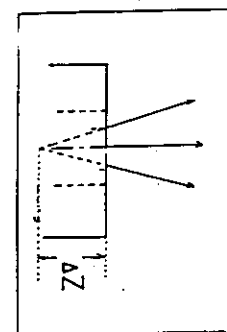
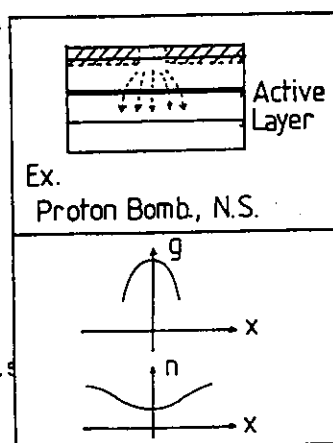
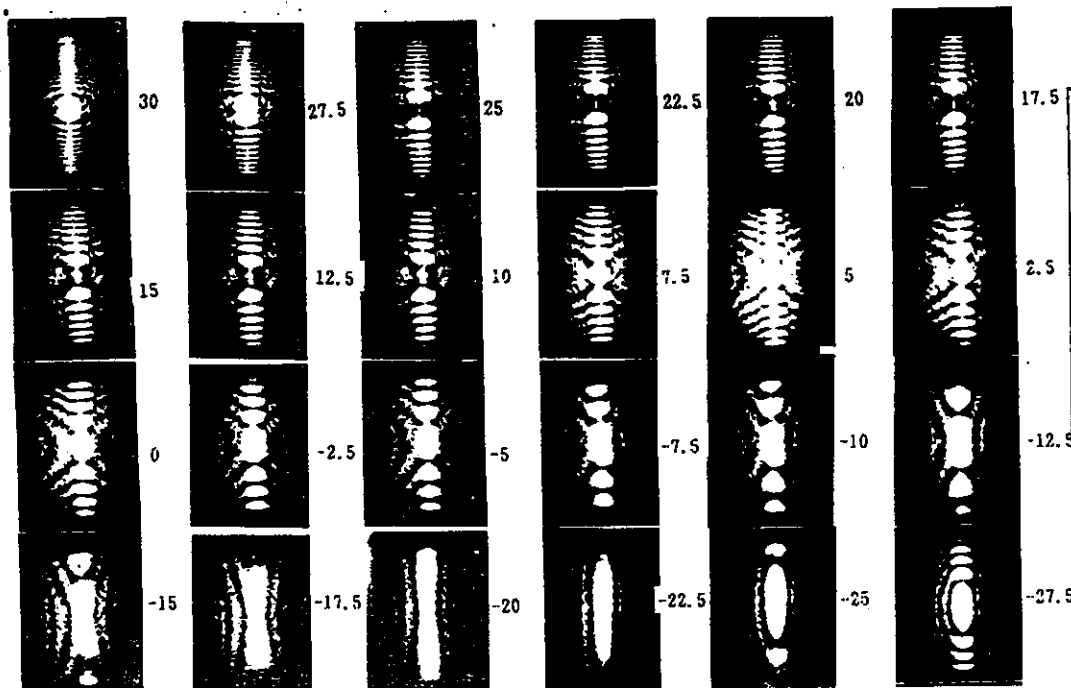
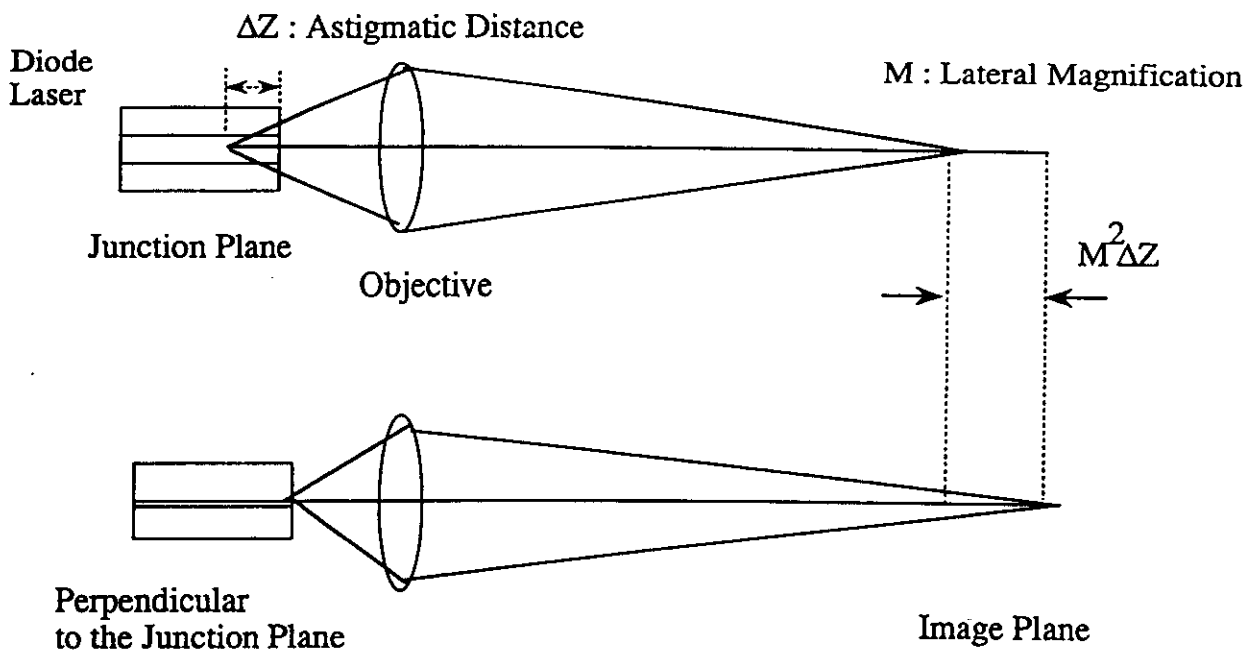


図 3-10 利得ガイド型レーザの干渉縞 (1) 数字はコリメータレンズの送り、 Δa (mm) を示す。

Near Field Measurement



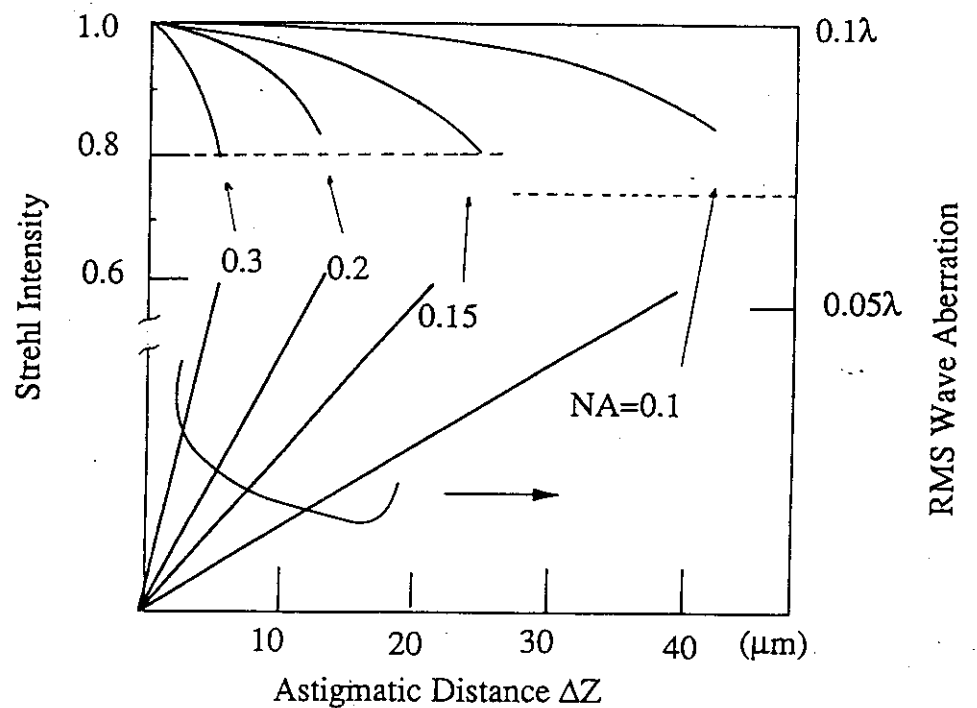
20

Astigmatism Tolerance for the Diode Lasers

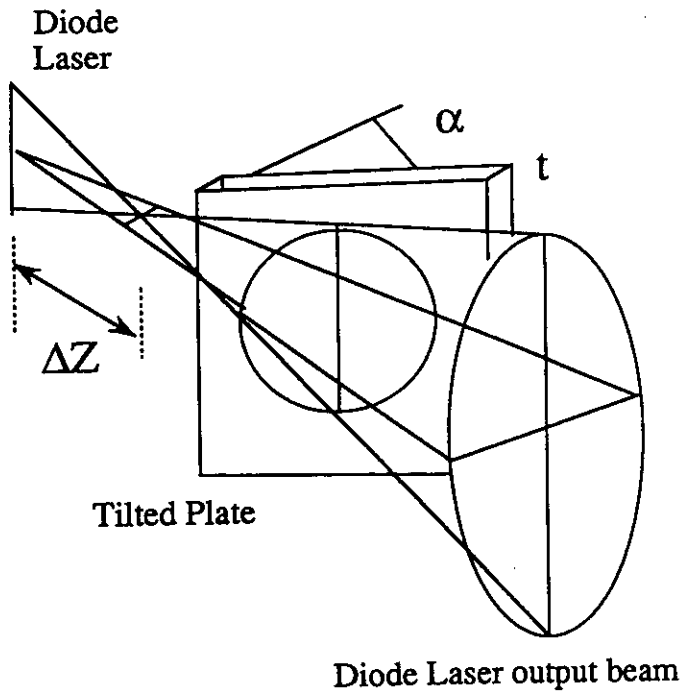
Astigmatism:

$$\Phi(\rho, \theta) = A_{22}^z \rho^2 \cos 2\theta$$

$$A_{22}^z = \Delta Z \text{NA}^2 / 4$$



Astigmatism Correction



$$\Delta Z = \frac{t(n^2 - 1)\alpha^2}{n^3}$$

ΔZ : Astigmatic distance

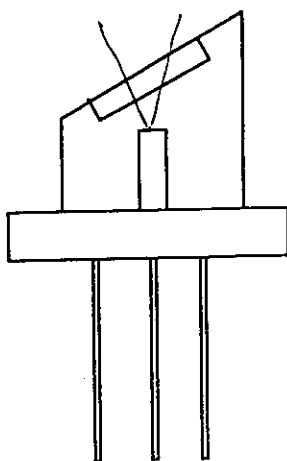
t : Thickness of plate

n : Refractive index of plate

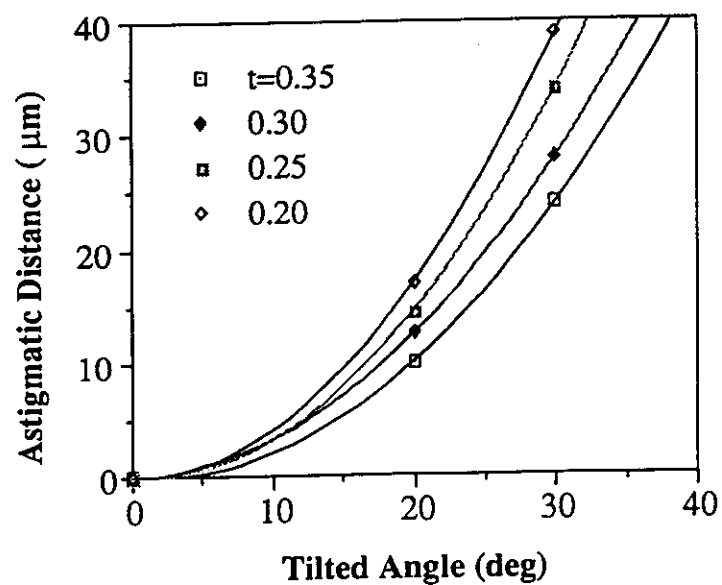
α : Tilted angle

21

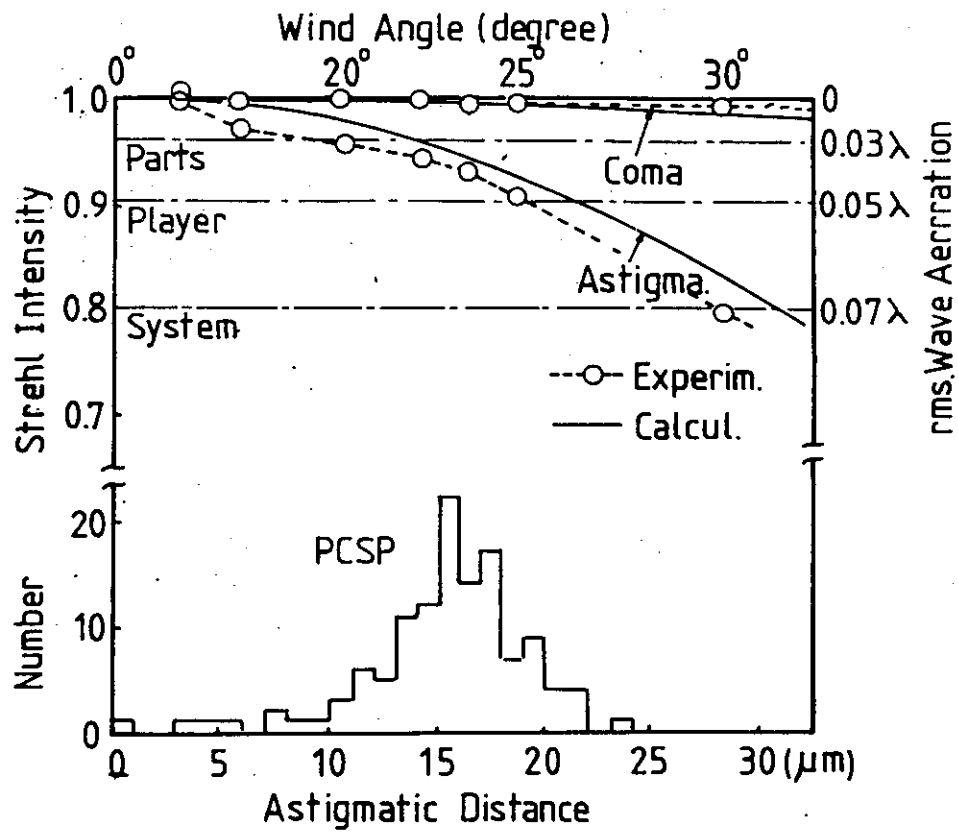
Tilted Window Diode Laser



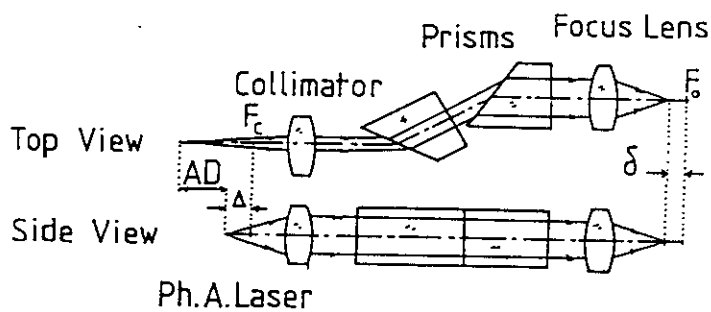
Side View



55 millions/year



Astigmatism correction with prisms



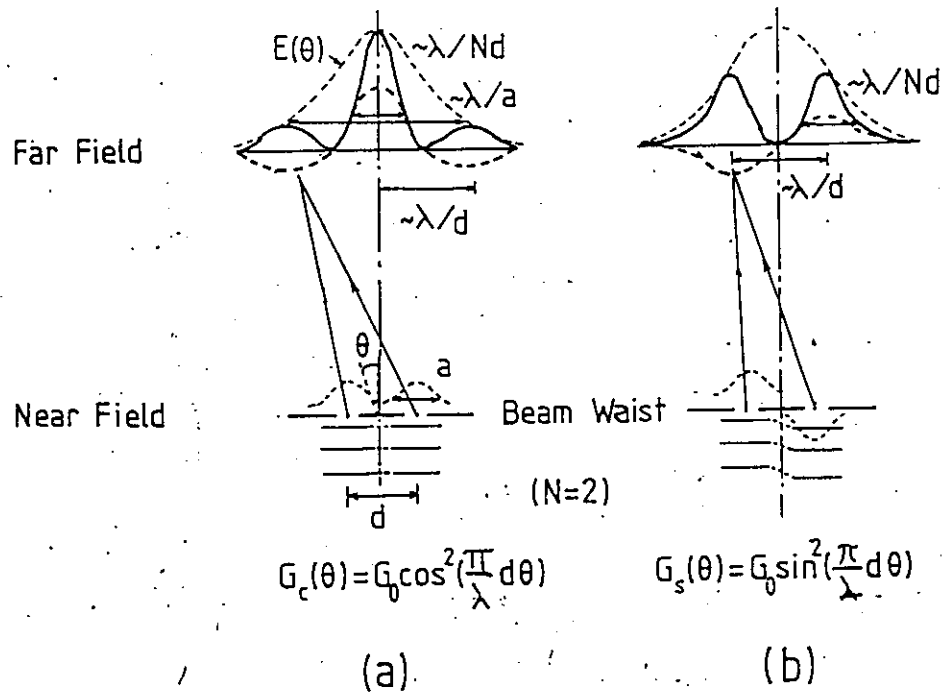
$$AD + \Delta = M_T^2 \delta_T$$

$$\Delta = M_S \delta_S$$

$$\delta = \delta_T = \delta_S$$

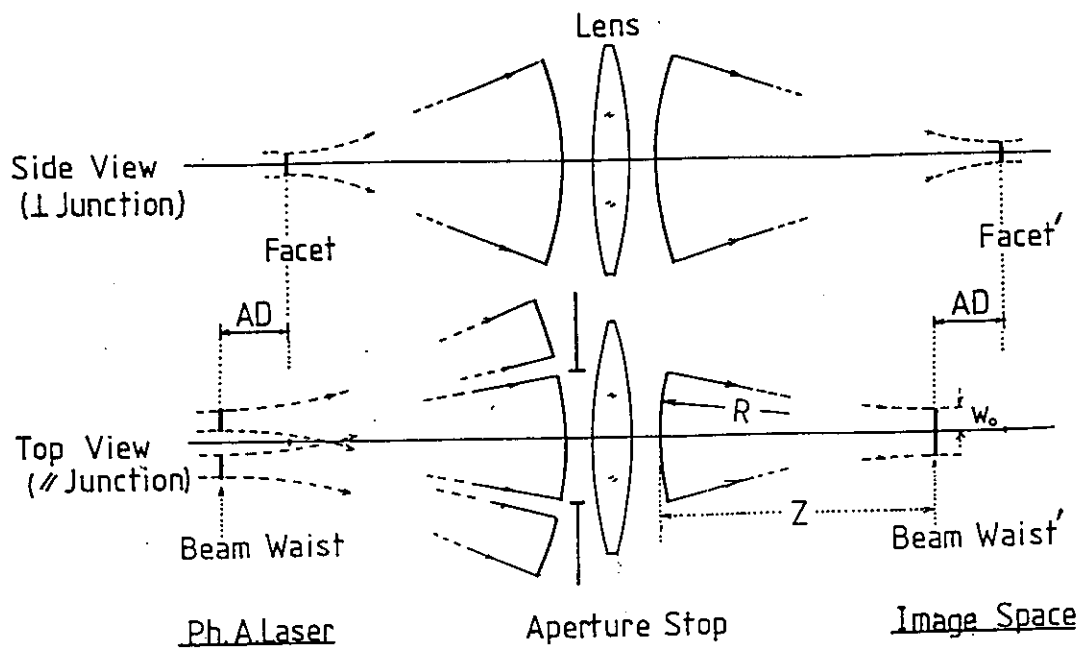
$$AD = (M^2 - 1) \Delta, \quad M = M_S / M_T$$

Far field pattern of phase coupled array lasers



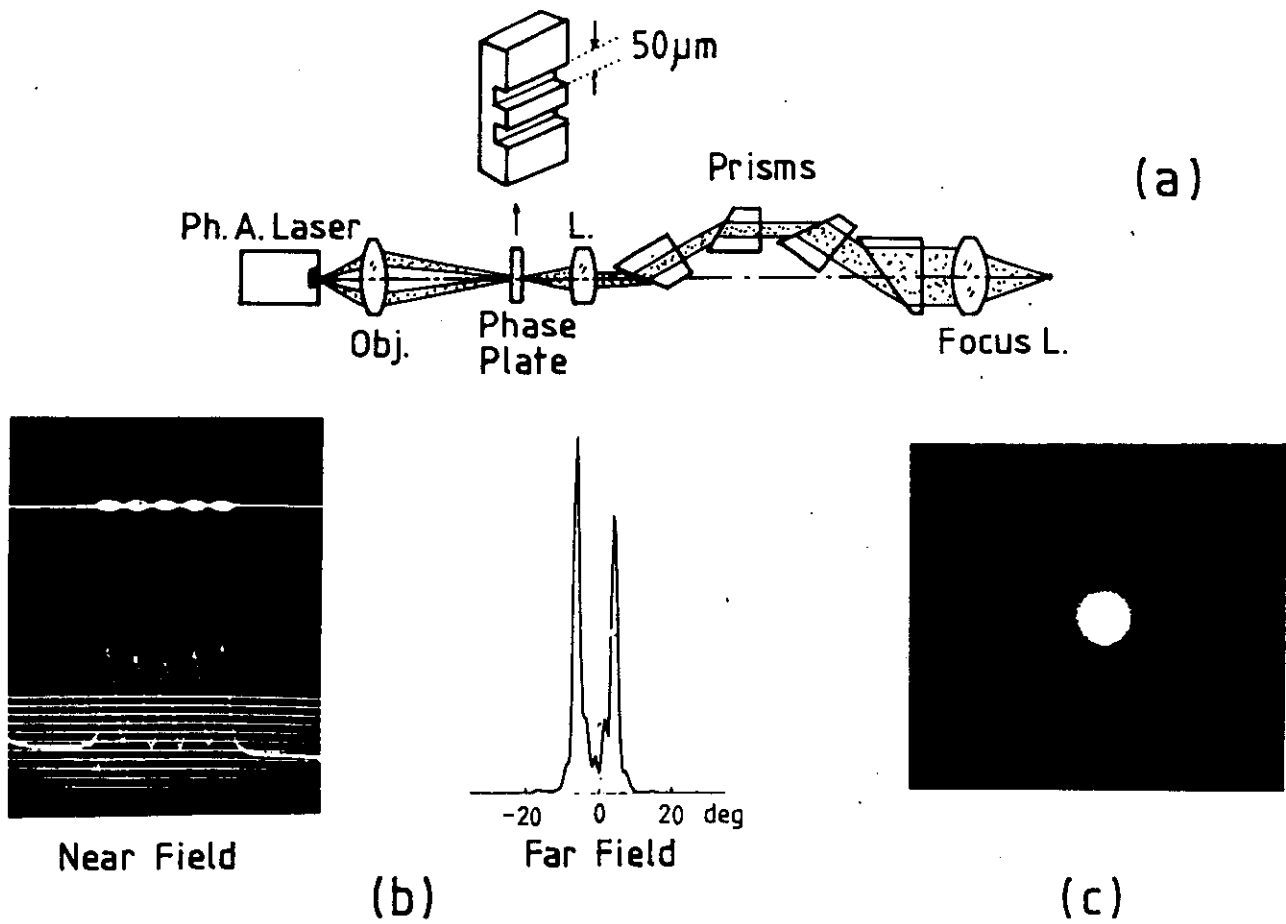
24

Optical Path Analysis for the Phase Coupled Array Lasers

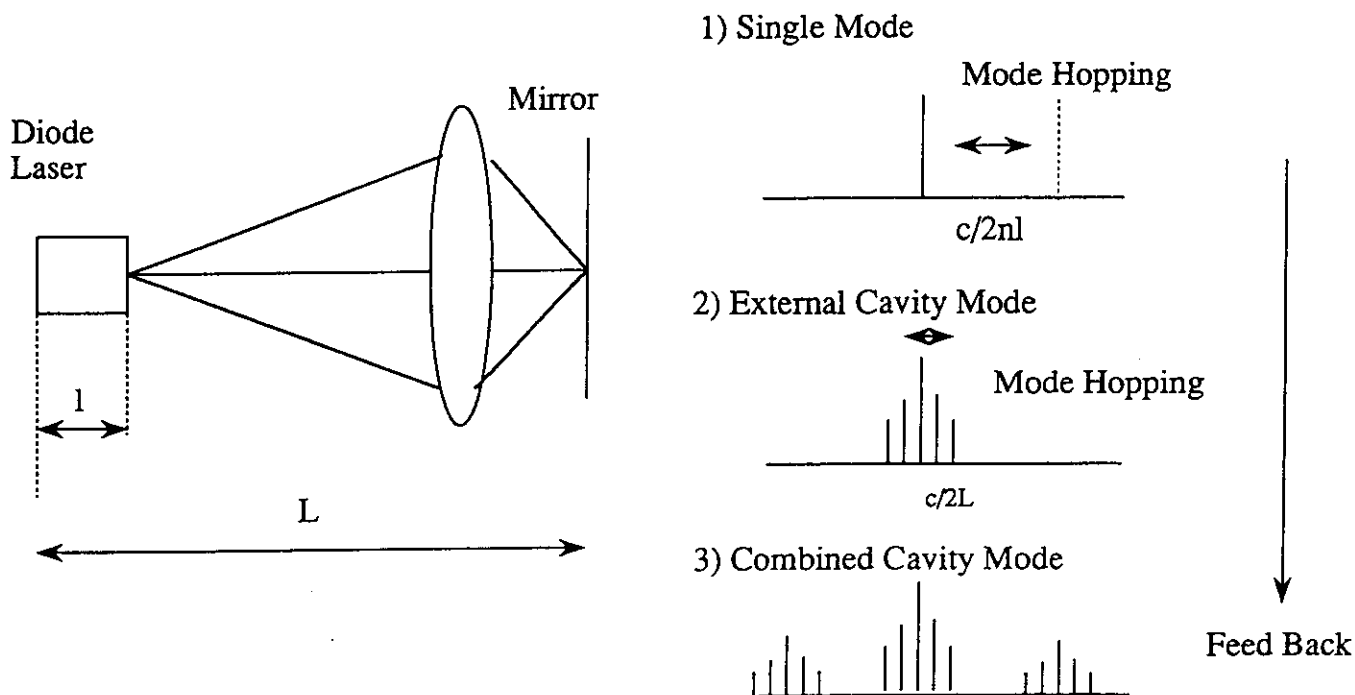


24

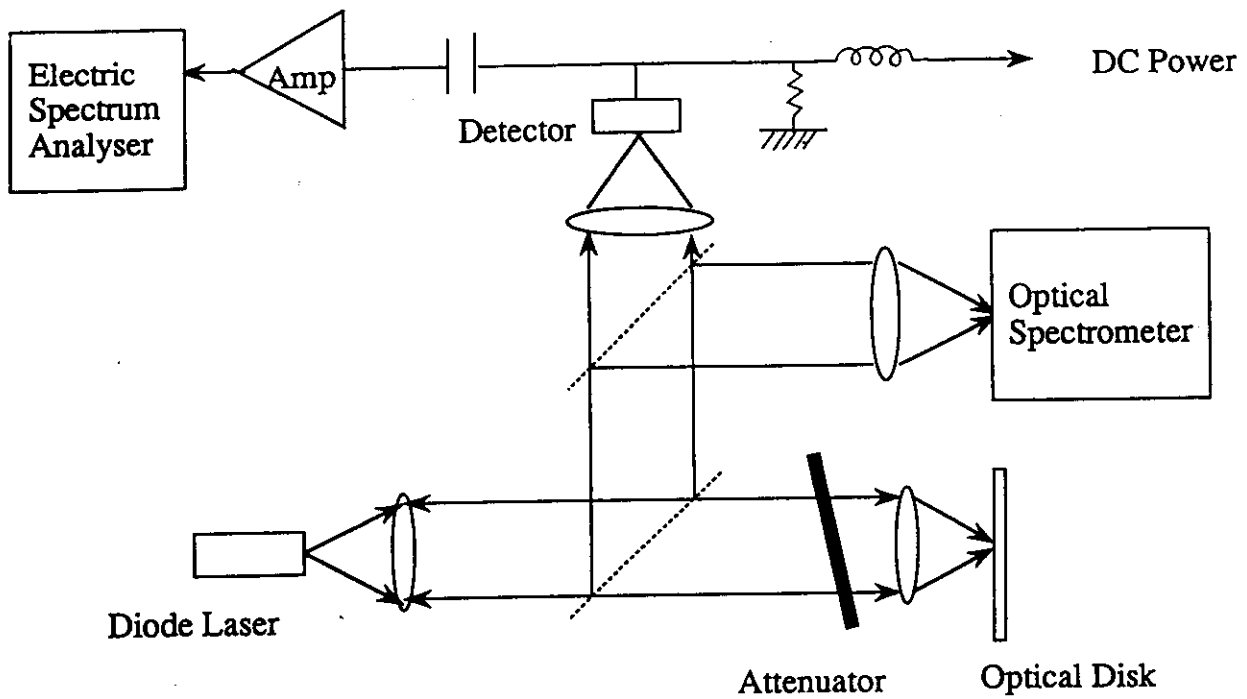
25



Cavity Modes & Diode Laser noise

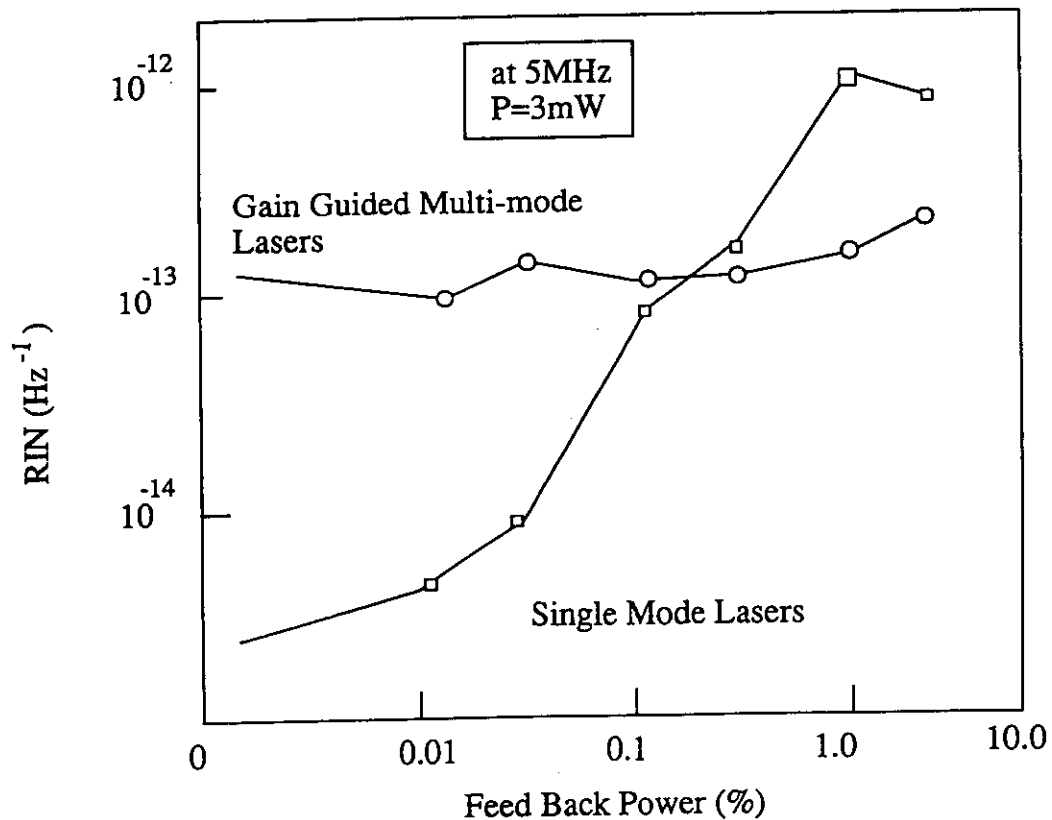


Noise Measurement Set-up



27

Diode Lasers noise



26

28

Relative Intensity Noise

$$RIN = \frac{\Delta P^2}{P^2 \Delta f} \quad (1)$$

$$V = k P, \quad \Delta V = k \Delta P \quad (2)$$

ΔP : Noise Power
 P : DC Power
 Δf : Measurement Band Width
 V : detecting Voltage
 k : Conversion ratio

Noise power indicated on a Spectrum Analyser with 50Ω impedance is given by $\Delta V^2 / 50 \times 10^3$ (mW). And it is expressed as x dBm. Therefore,

$$\begin{aligned} x &= 10 \log (\Delta V^2 / 50 \times 10^3) \\ &= 20 \log \Delta P + 10 \log (k^2 / 50 \times 10^3) \end{aligned} \quad (3)$$

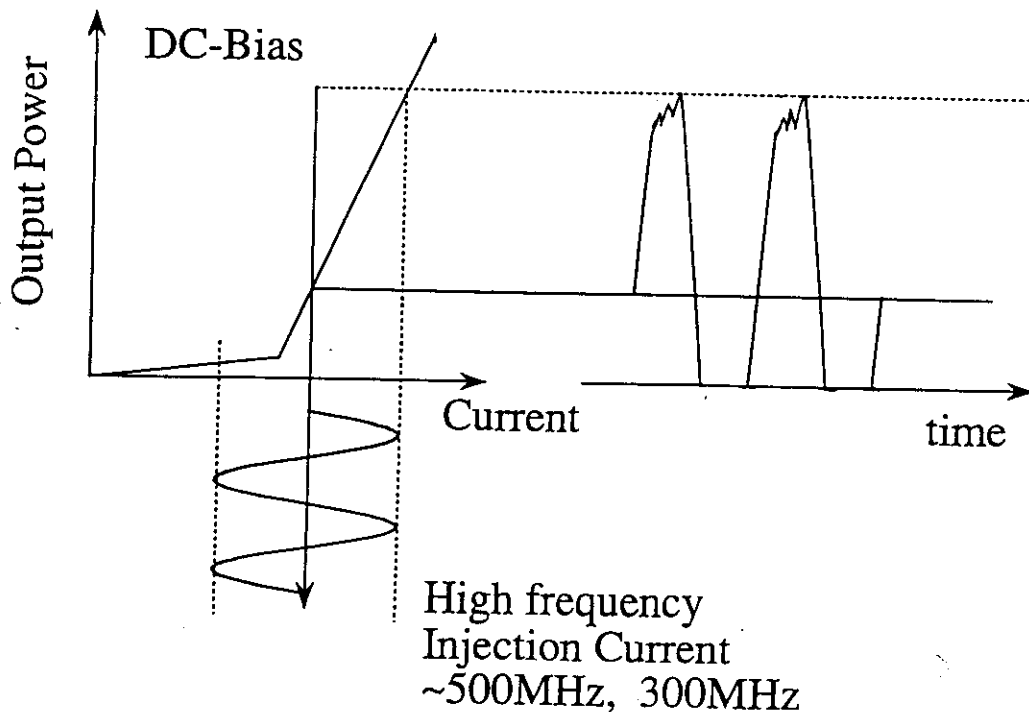
Equations (1), (2) and (3) gives

$$10 \log RIN = x - 20 \log(V) - 10 \log(\Delta f) - 13 \quad (4)$$

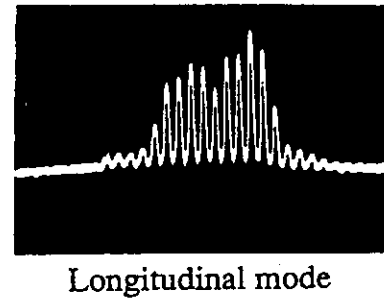
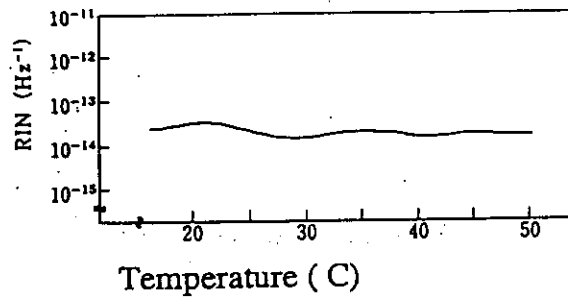
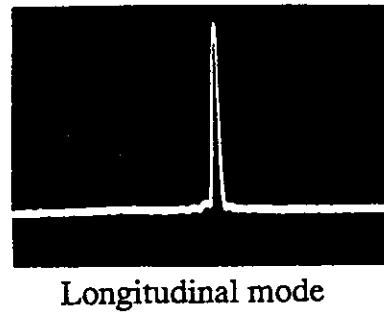
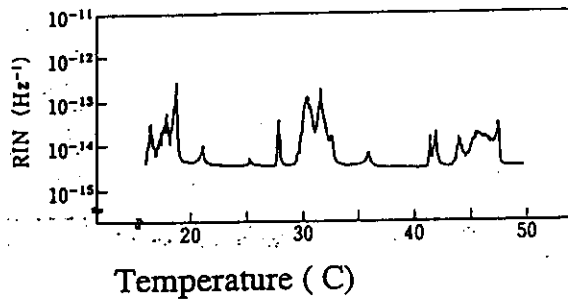
Ex. $RIN = -122$ dB, when $x = -90$ dBm, $V = 0.05$ V, and $\Delta f = 30$ kHz

29

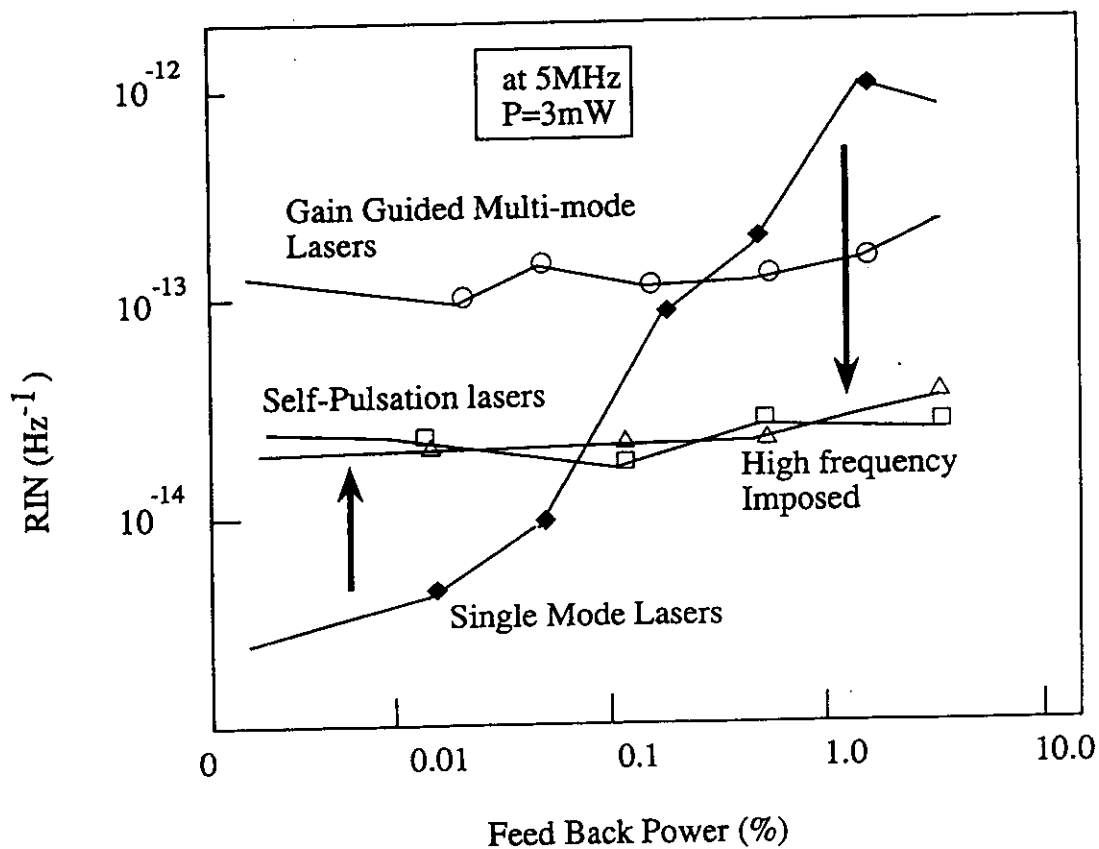
Noise Reduction with High Frequency Superimposing



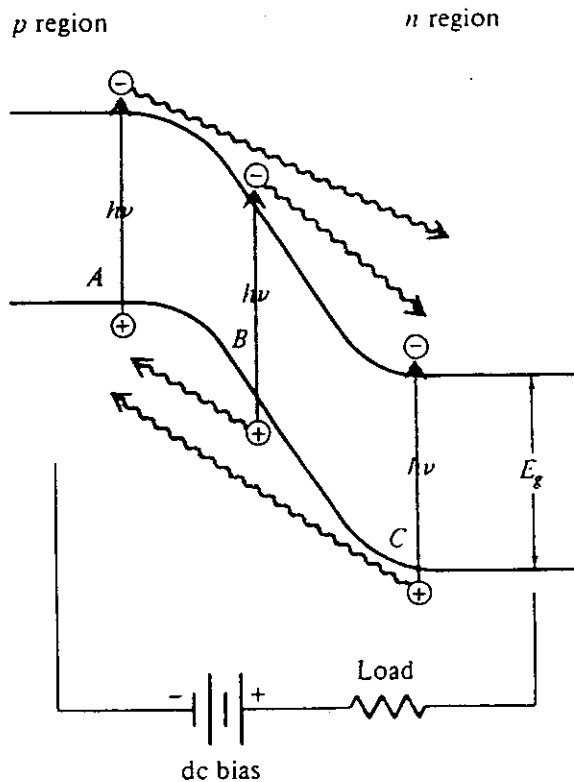
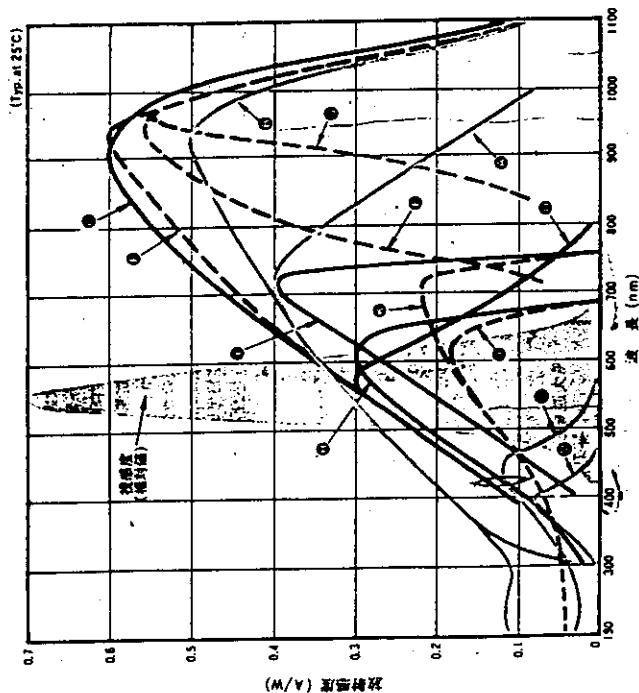
Noise Reduction with High Frequency Superimposing-Results-



31

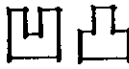


●フォトダイオードの分光感度特性(代表例)



品名	構造・仕様	検出域 (nm)	ピーク波長 (nm)	記号	ページ
シリコンフォトダイオード	紫外～可視域用	190~1000	720	SI226, SI227 シリーズ	12・13
	紫外～可視域用	190~1100	920	SI336, SI337 シリーズ	14・15
	可視域～紫外域用	400~1100	900	S2386, S2387 シリーズ	16・17
	可視域～紫外域用	320~730	560	SI087, SI133, S2832 etc.	18・19
	可視域～紫外域用	300~1100	900	SI097-01, SI133-01 etc.	
PINシリコンフォトダイオード	高速応答	400~1000	800	S2839, S2840	
	高速応答	400~1060	900	SI18A, S2216, SI171 etc.	
	高速応答	400~1100	920	SI190, SI223 etc.	
	高速応答	700~1100	950	S2506	
	高速応答	840~1100	980	S2508-01	
GaAsPフォトダイオード (広帯域)	大口径受光用	190~1060	920	SI723-05 etc.	
	可視域用	300~680	610	GI115, GI116, GI117 etc.	24・25
	可視域用	400~760	710	GI735, GI736, GI737 etc.	
	可視域用	190~680	610	GI125-02, GI126-02 etc.	26・27
	可視域用	190~760	710	GI745, GI746, GI747	
GaPフォトダイオード (シリコン型)	可視域用	190~520	440	GI961, GI962, GI963	28・29
	可視域用	280~410	380	GI961-01, GI962-01	
	可視域用	350~1050	820	S2381, S2382, S2383, S2384, S2385	30・31

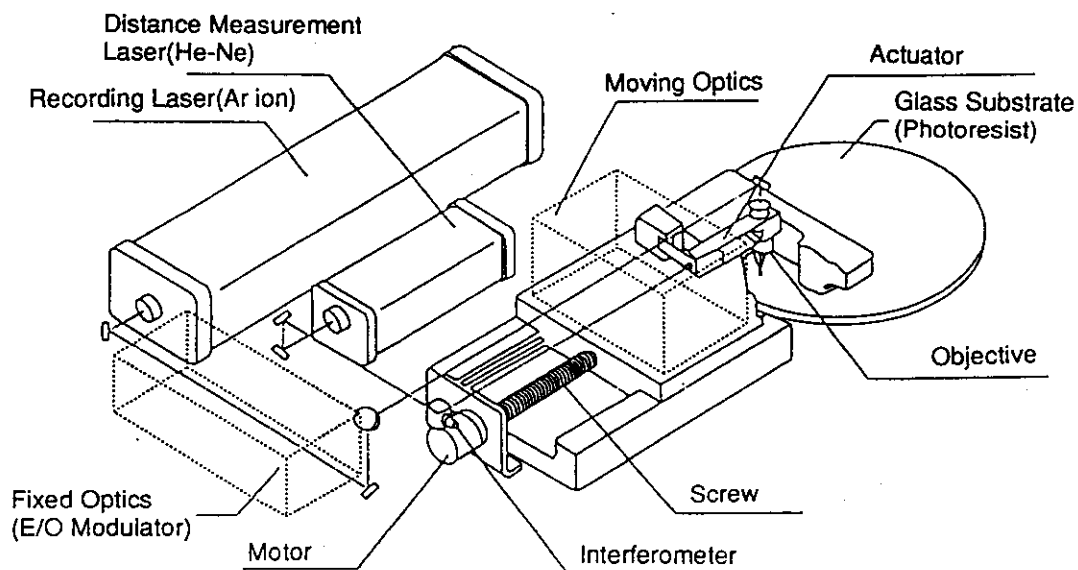
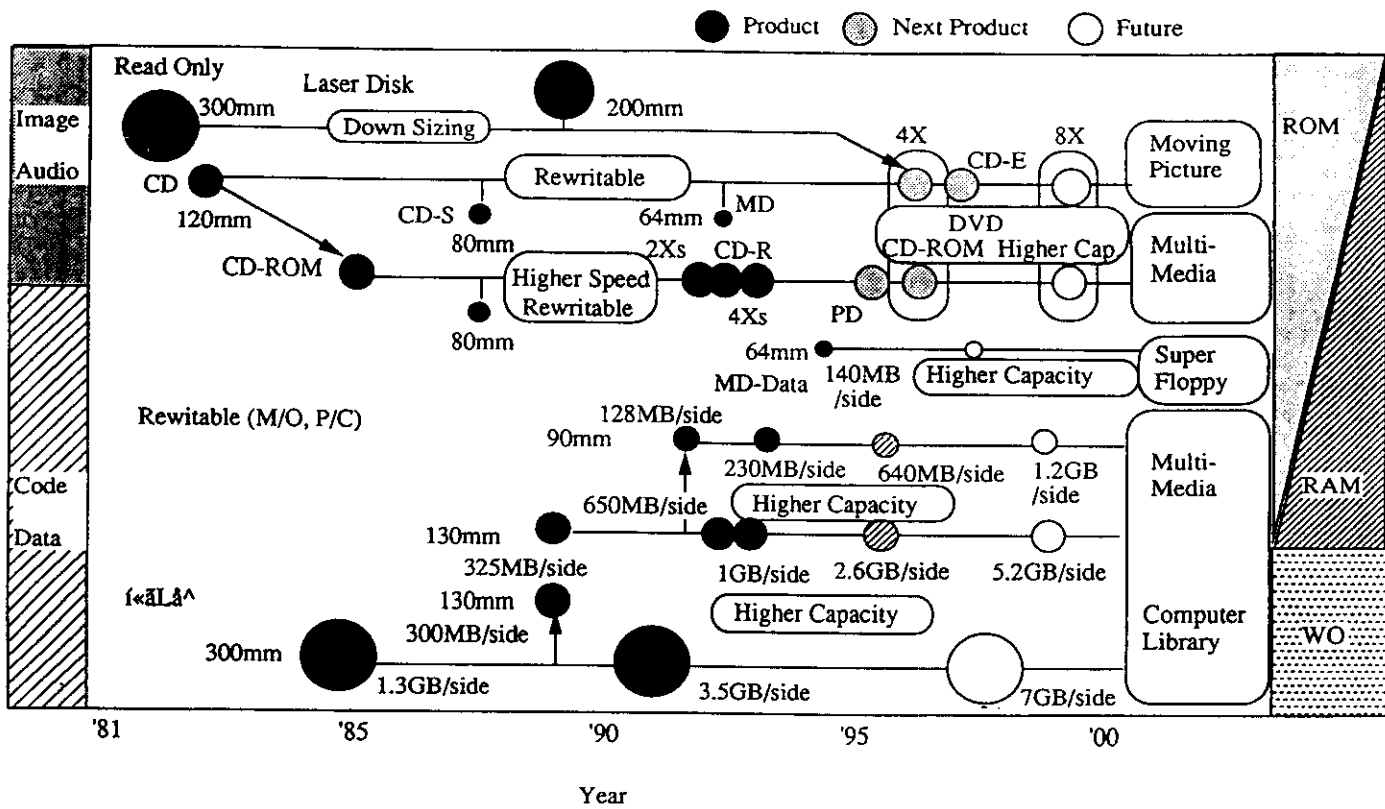
Optical Disk Types

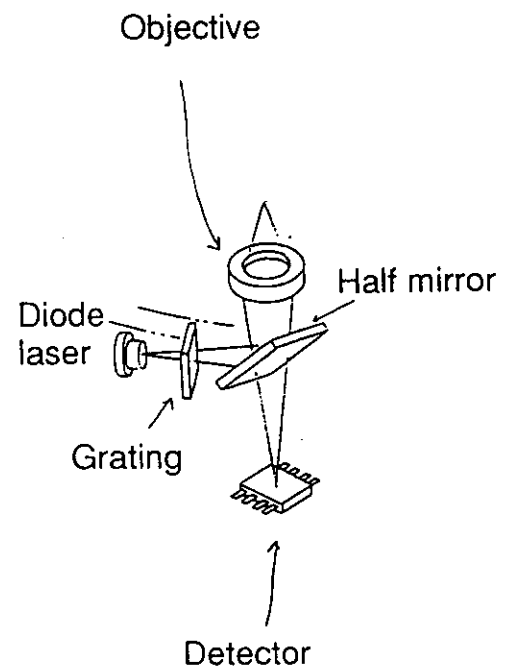
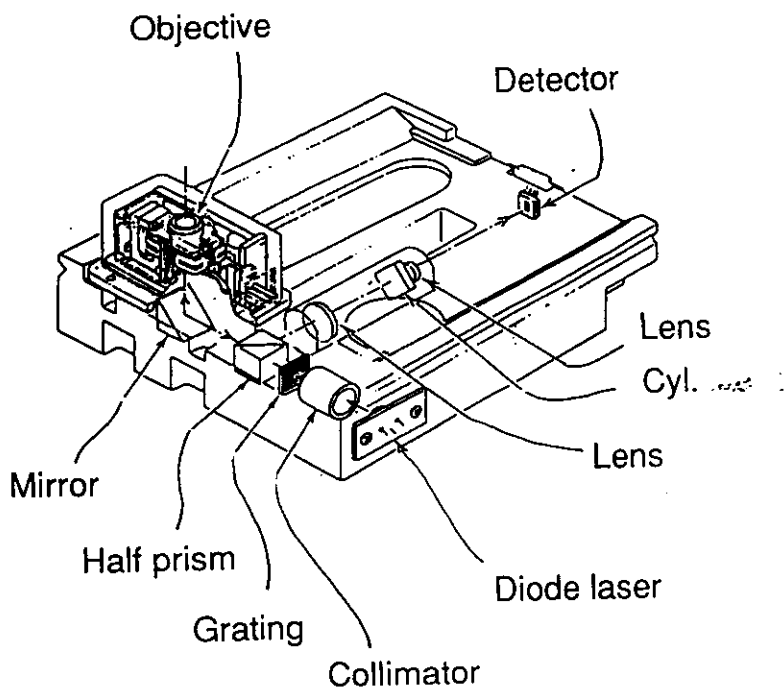
Read Only	————	 Pits
Write Once	————	Hole Making Phase Change Organic Dye
Rewritable	————	Magneto-optic Phase Change

Optical Disks

Type		Pit	Applications
Read only		Depression 	CD CD-ROM Video Disc
Write once		Hole making 	Document Filing Computer File Video File
Rewritable	Magneto-optical	Magnetization 	Computer File CD-E, MD Digital Video
	Phase Change	Crystal/Amorphas 	Video-File CD-R, E Video File

Optical Disk Map





Hirachi Pick-up for CD-Player

Generation		I	II	III	IV
Obj.	Opt.	Infinity	←	←	Conj.
	Type	Triplet	←	Aspheric Plastic	←
Col.	NAC	0.118	←	0.113	0.09
	Eff. (%)	27	27.4	15.7	18.6
Fd Bck(%)		1.5	1.6	0.9	1.1
Beam Spl.		Half Prism	←	Half Mirror	←
Path Length (mm)		80	44	48	25
No. of Opt. Comp.		8	6	6	3
Year		1982	1983	1985	1988

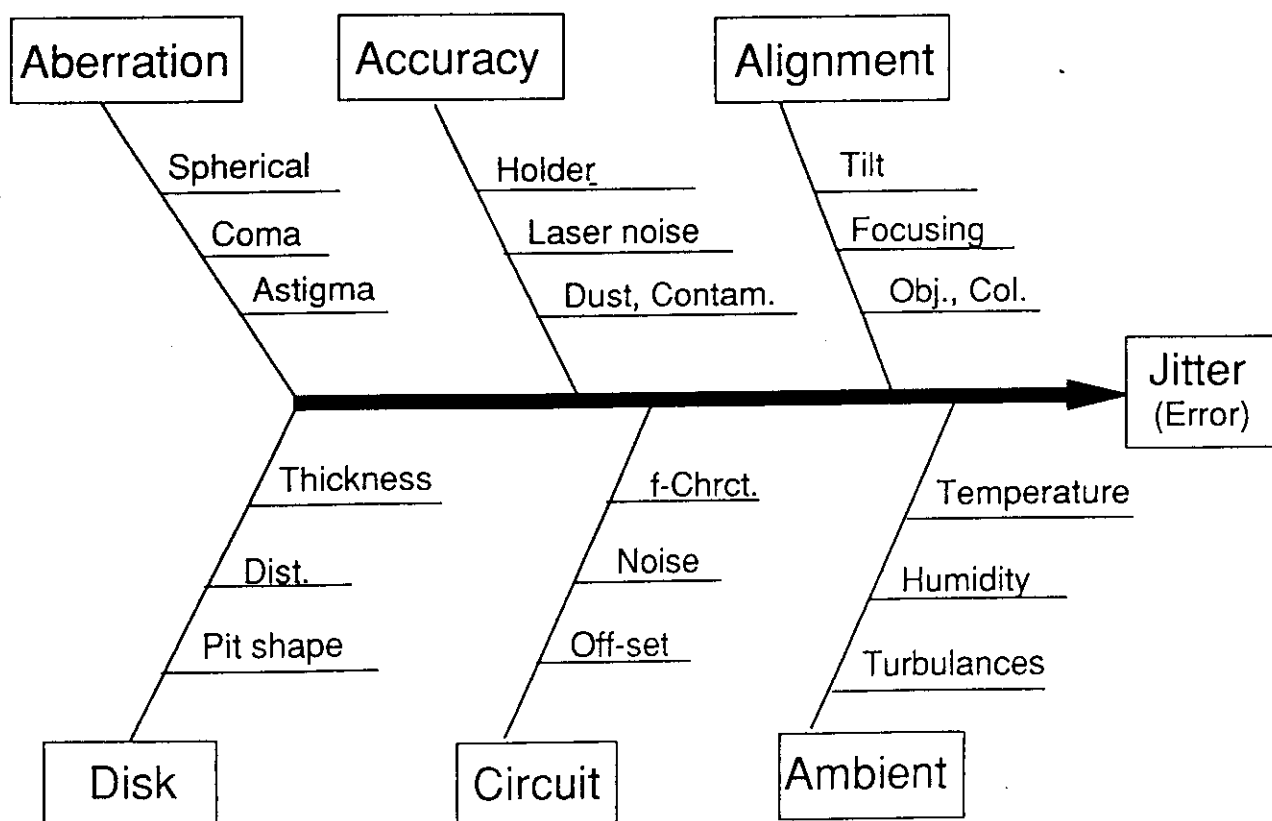
Auto-focus: Astigmatic, Tracking: 3-spots

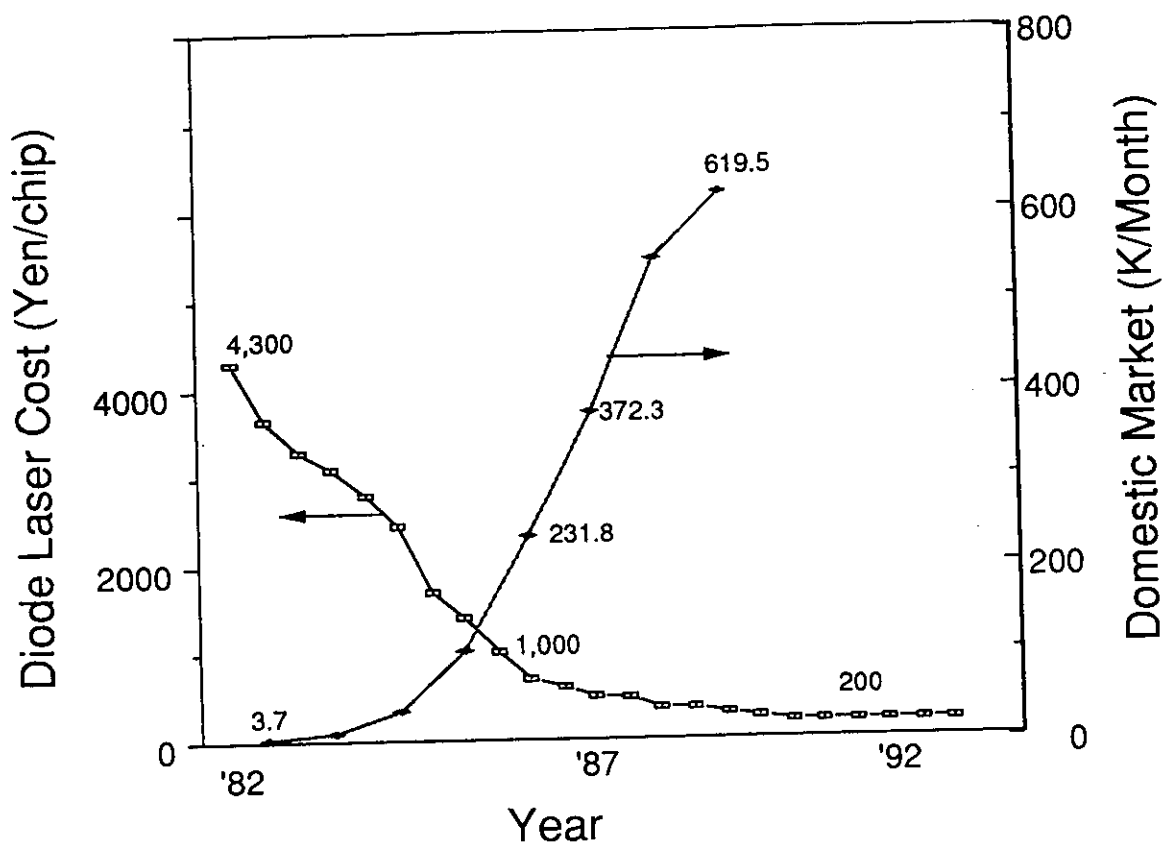
Diode Lasers for Hitachi Pick-ups

Generation Year		I 1982	II 1983	III 1985	IV 1988
Type		Single mode	Pulsation	Gainguided	Pulsation
I _{th} (mA)		50	50	60	35
Q.Eff		0.25	←	0.3	
Op. Curr.(mA)			65	70	45
Op. Vol.(V)			1.75	1.9	←
Beam Div. (deg.)	H.	14	11	19	11
	V.	27	33	38	37
Ast. Dis. (μm)		< 5	< 10	< 40 Tilted Wndw	<10
Noise Red.		Mult. Fd Bck	Self Pulsation	Multi.	Self Pulsation

P_o=5mW(APC), Wavelength= 780~785nm

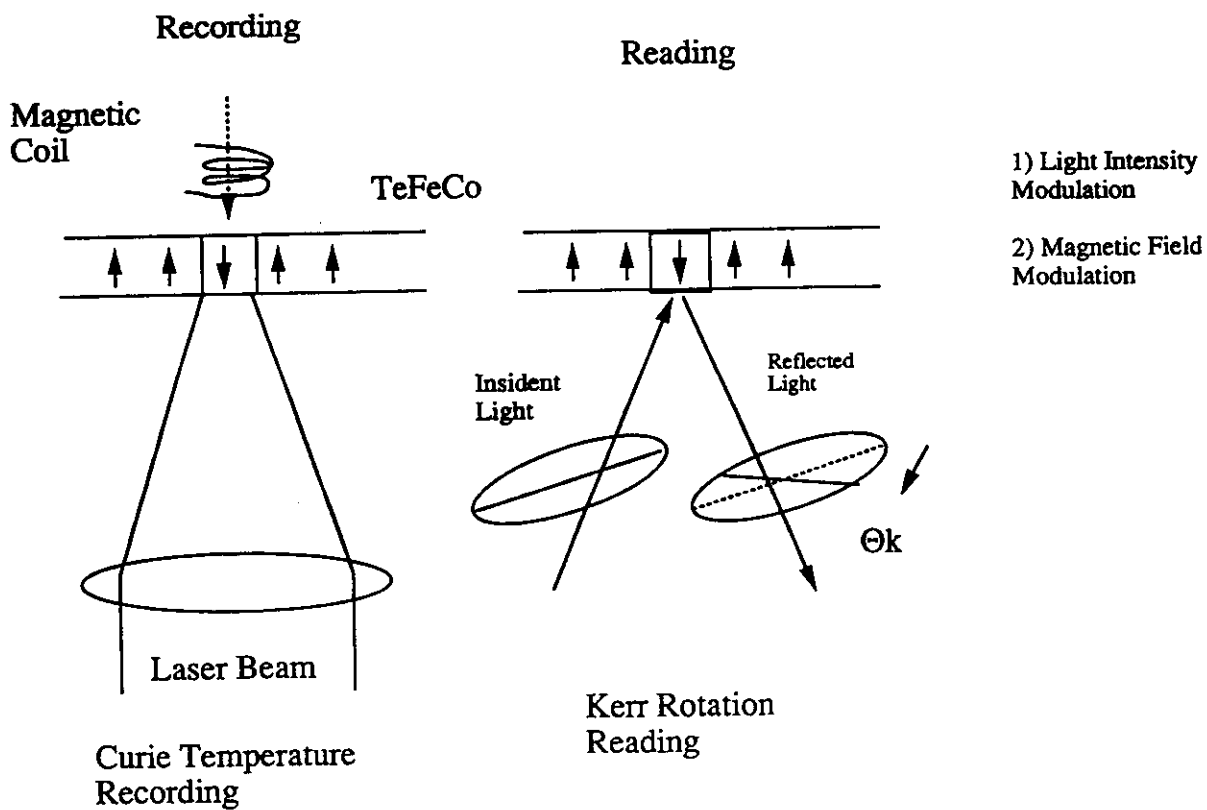
Jitter Analysis



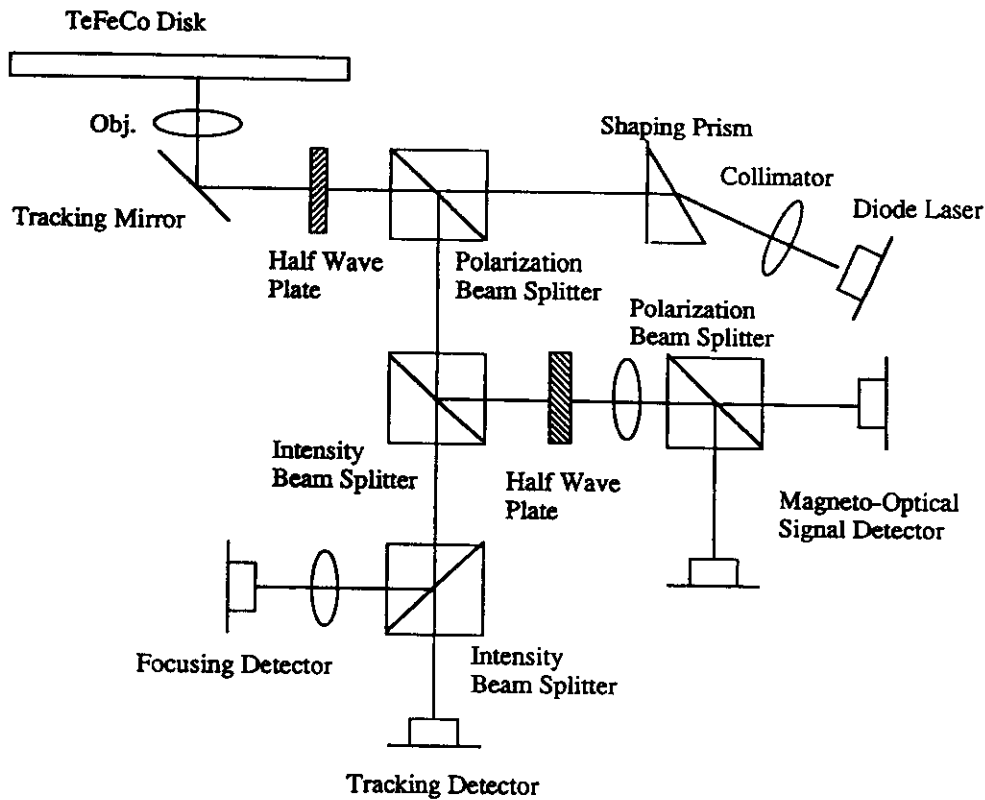


Market size and the Diode Laser Cost

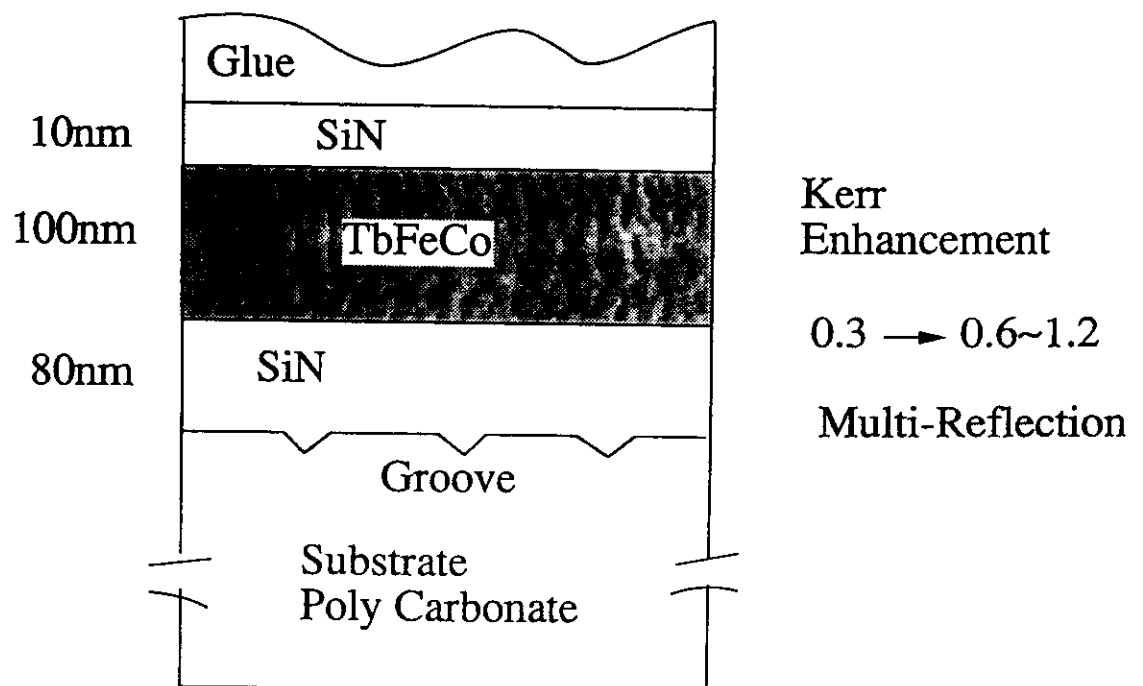
Principles of Magneto-Optic Memory



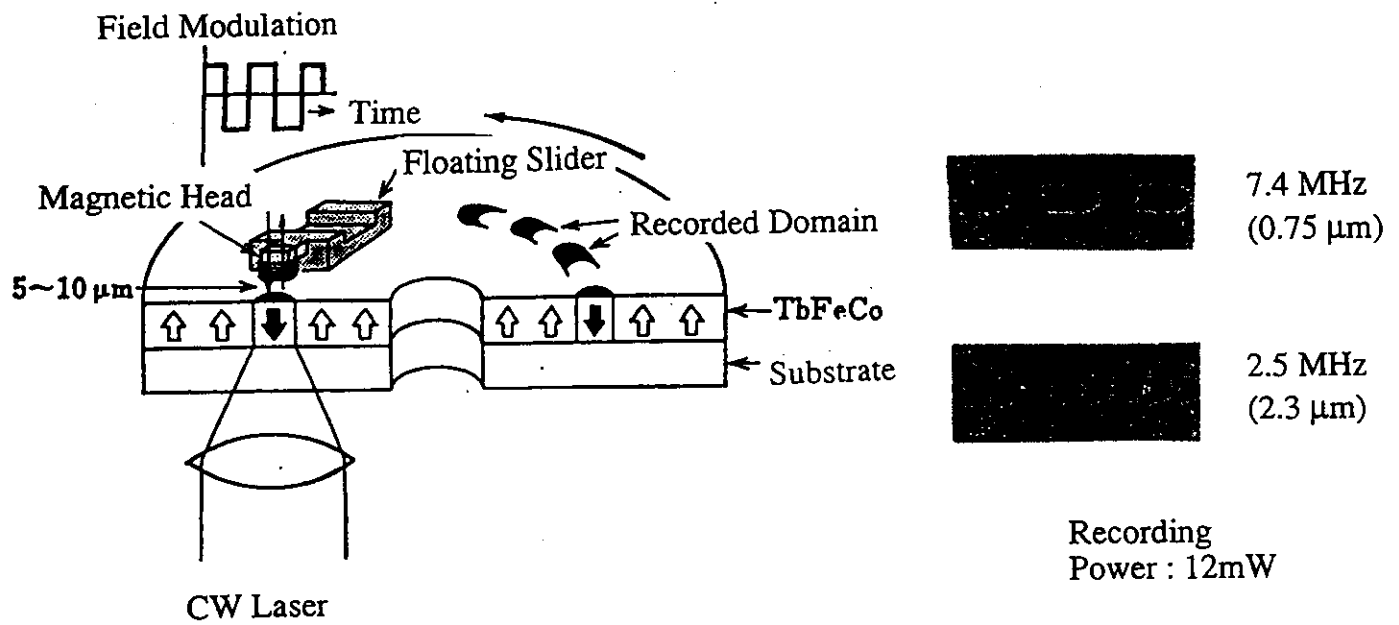
Magneto- Optical Head Structure



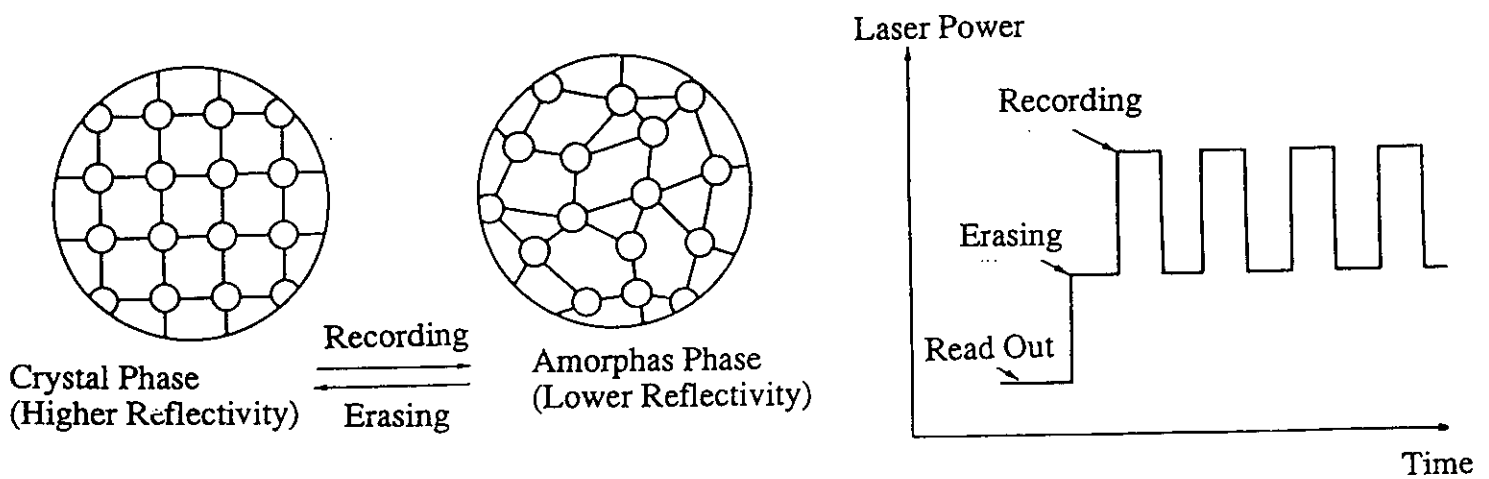
Magneto-Optical Disk Structure



Magnetic Field Modulation M/O Disk

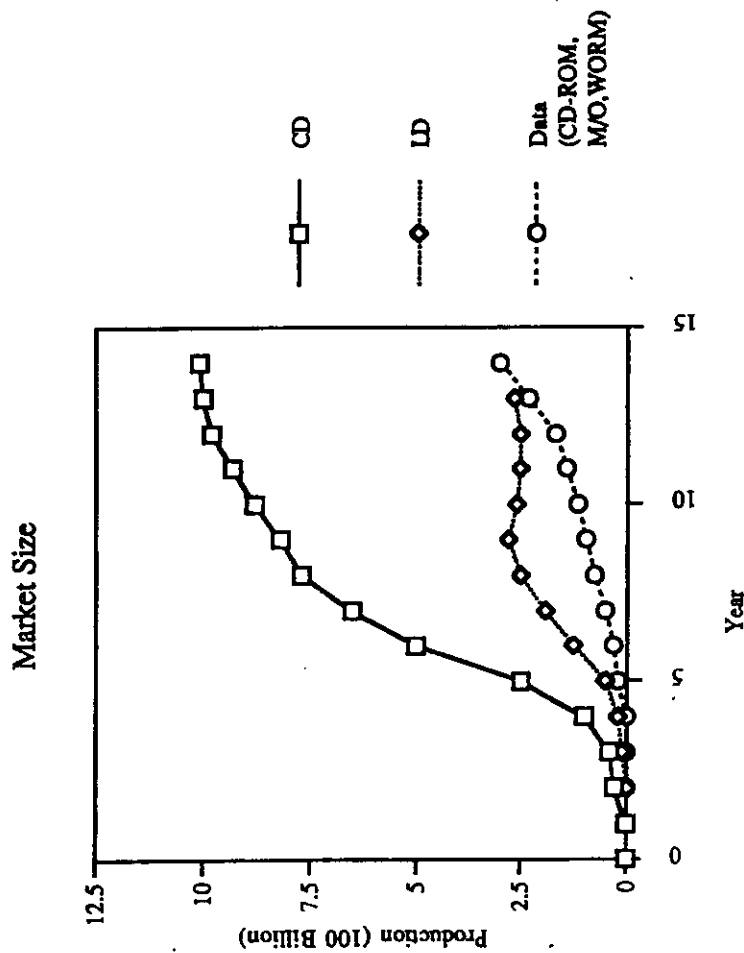
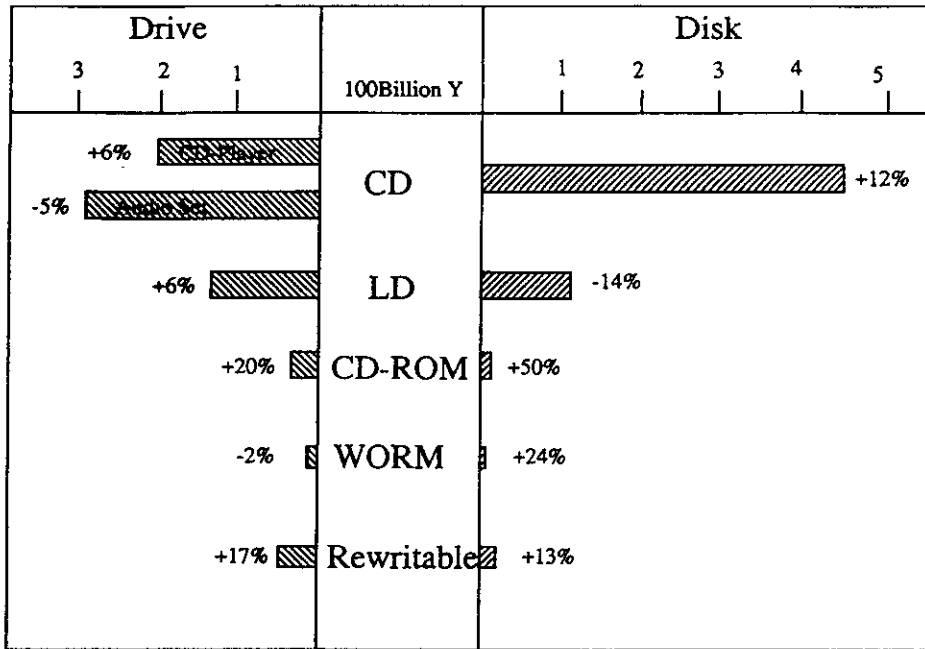


Phase Change Erasable Optical Disk

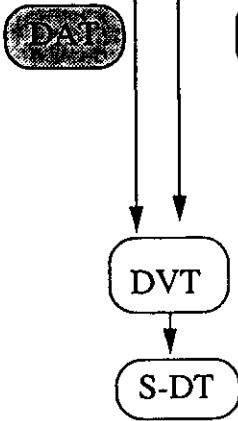
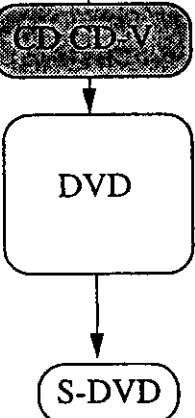
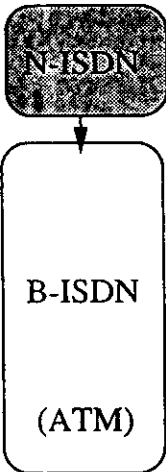


Domestic Optical Disk Production

1992



Multimedia and PKG/Telecom/Broad Cast

	Bit Rate	Image Quality	Package		Telecom	Broad Cast	Intrn. Stndrd
			Tape	Disk			
Analog		TV	Casset VHS β 8mm	LP LD	PSTN	VHF/UHF /CATV	NTSC/PAL /SECAM
Digital	64 k 384 k 1.5 M 2 M 4M 9M	VHS TV-R TV-T					
	15~ 20M 30~ 60M 150m	HDTV-R HDTV-T					

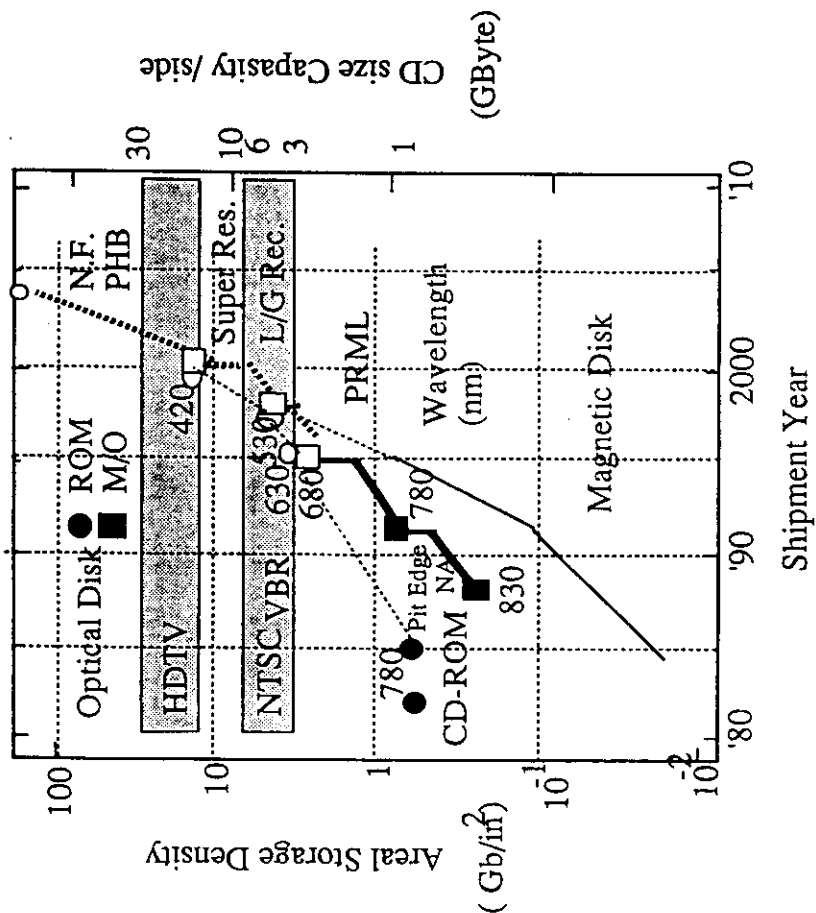
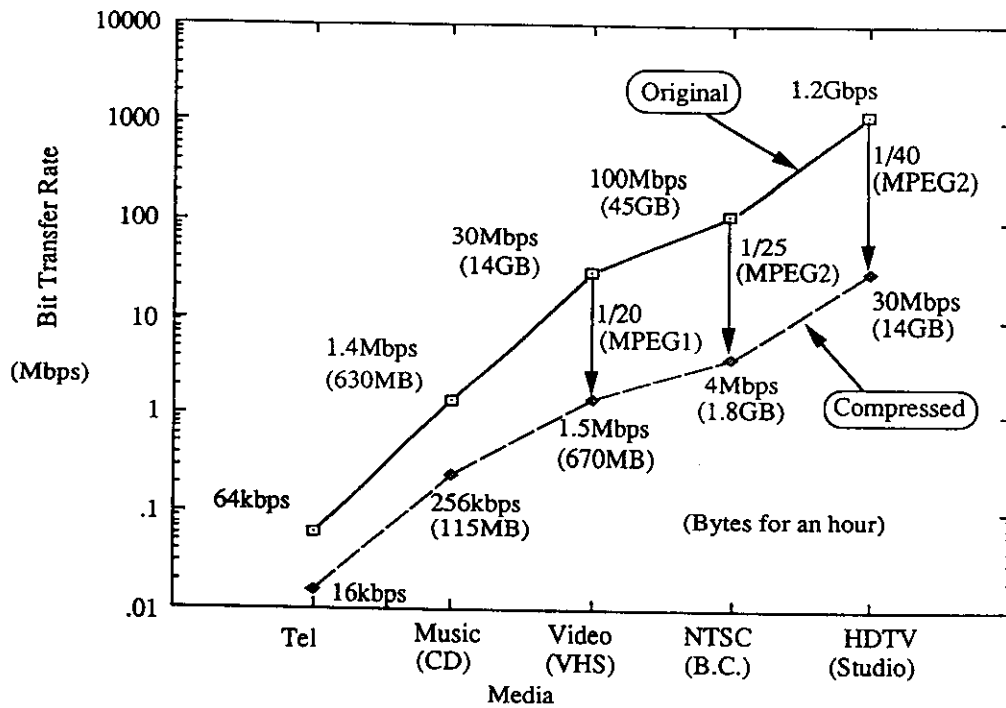
PSTN:Public Switched Telephone Network
 NTSC:National Television System Committee
 PAL:Phase Alternation by Line

SECOM:Sequentia a Memoire Color Television
 ISDN:Integrated Services Digital Network
 ATM:Asynchronous Transfer Mode

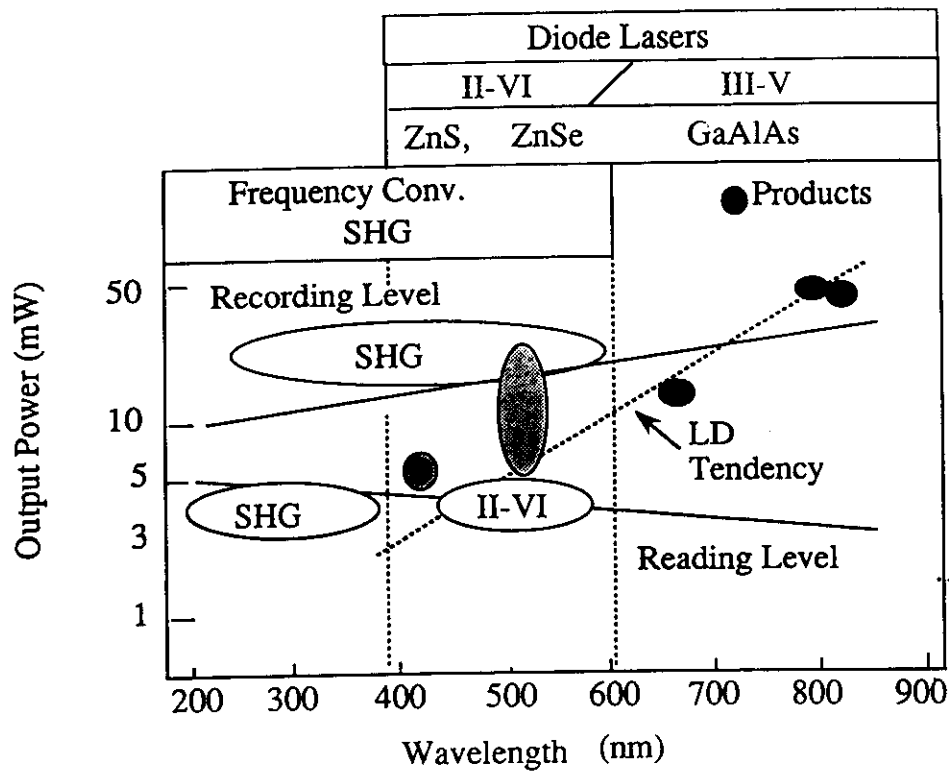
Digital Data Compression

Image Quality	Standarization	Bit Tr Rate	Ratio	Data/hour
TV-Telephone	H.261 (CCITT)	64Kbps ~1.9Mbps	~1/30	
PKG media CD-V CD-Karaoke	MPEG 1 (ISO/IEC)	~1.5Mbps	1/26	650MB
High Quality PKG media	MPEG 2	NTSC [VBR] 3.0Mbps 4.5Mbps	1/50 1/40	1.5GB 2.4GB
Braod Cast		[Fxd] 8.4Mbps	1/20	3.8GB
Hi-Vision		HDTV 24Mbps	1/40	10.8GB

Digital Data Compression



Lasers for Optical Disks



Second Harmonic Generation

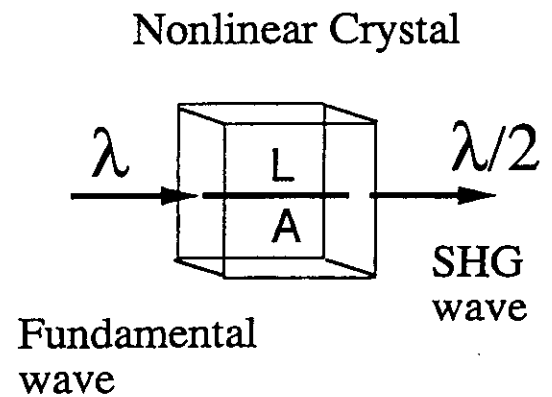
1. Phase Matchig Condition

Birefringence : $n(\lambda/2) = n(\lambda)$

2. Conversion Efficiency

$$P\left(\frac{\lambda}{2}\right) \propto \frac{P^2(\lambda)}{A} d^2 L^2$$

$P(\lambda)$	Fundamental
A	Beam Cross Section
d	Nonlinear Coefficient
L	Interaction Length

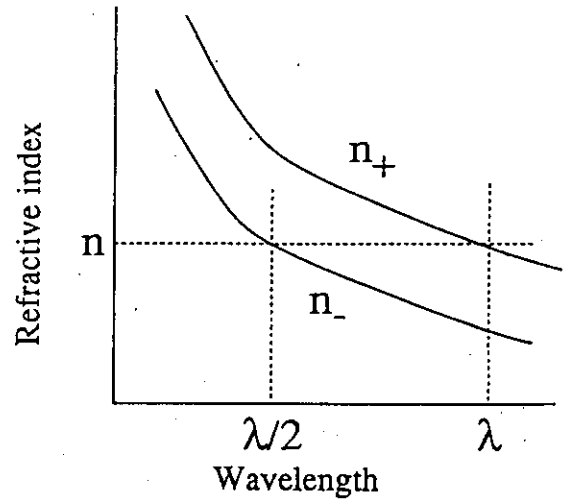
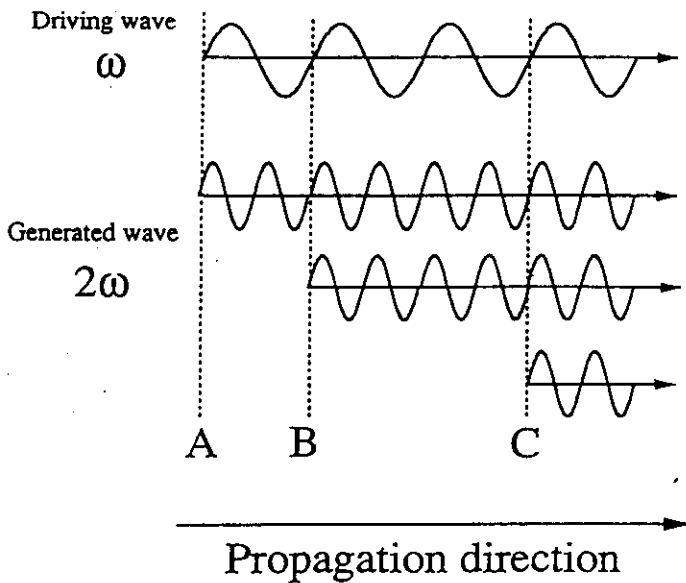


Phase Matching Condition

$$\Delta k = 0$$

$$v(\omega) = v(2\omega) = c/n \rightarrow n_-(\lambda, \theta, \phi) = n_+(\lambda/2, \theta, \phi)$$

(1) Wavelength dependency



(2) Propagation direction dependency (θ, ϕ)

40

SHG Characteristics

$$S_{2\omega} = \frac{2\mu_0^{\frac{3}{2}} \epsilon_0^{\frac{1}{2}} \omega^2 d^2 L^2}{\pi \omega_0^2 n_{2\omega} n_\omega^2} S_\omega^2 \frac{\sin^2(\Delta k L/2)}{(\Delta k L/2)^2}$$

I) when $\Delta k = 0$

SHG power is proportional to

1) the square of the fundamental power

2) d^2/n^3 : figure of merit

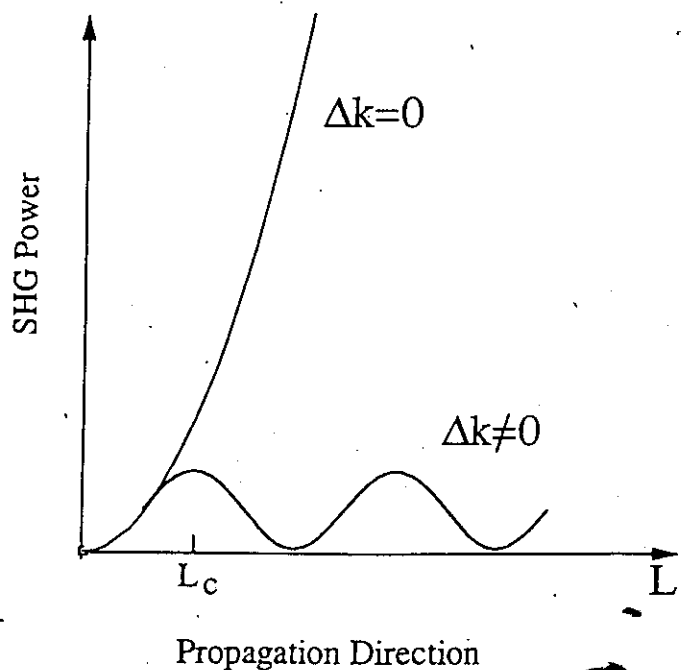
3) L^2/λ^2

II) when $\Delta k \neq 0$: sinusoidal

→ Maker Fringe

Coherence length is given by

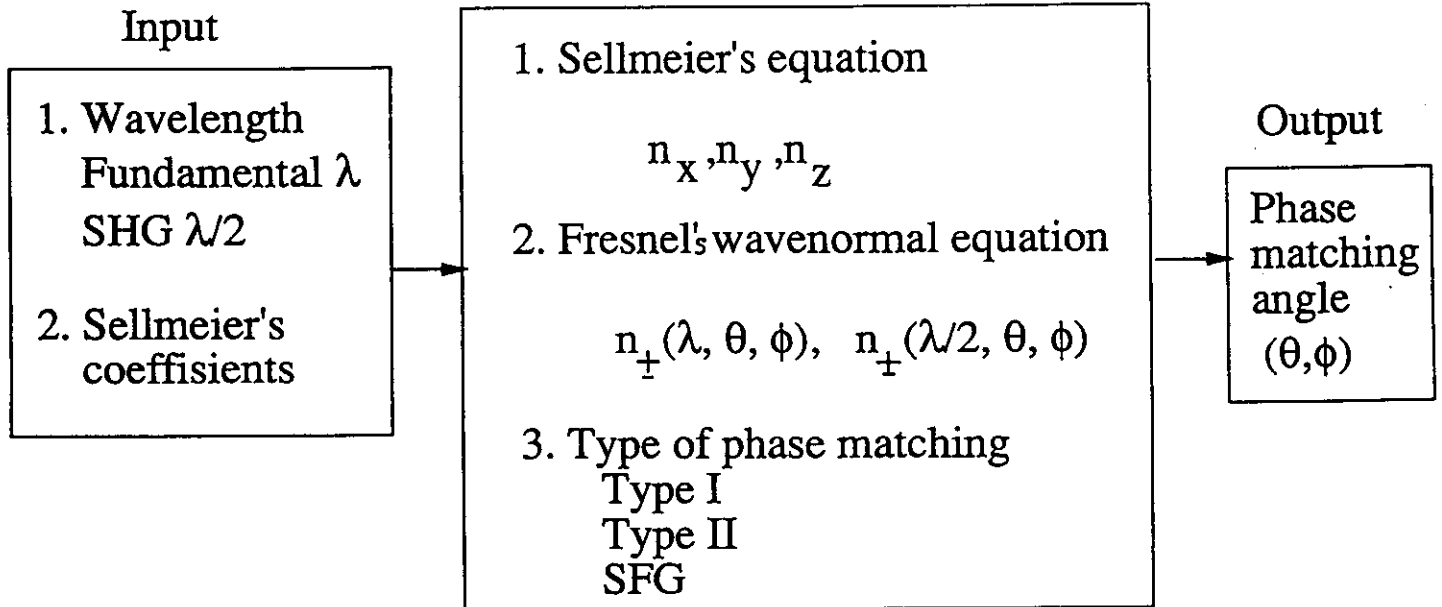
$$L_c = \lambda / 4 (n_{2\omega} - n_\omega) \sim 3 \mu\text{m}$$



41

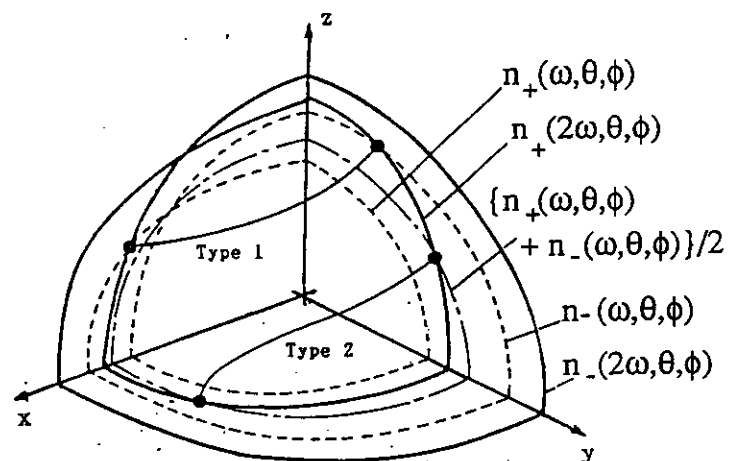
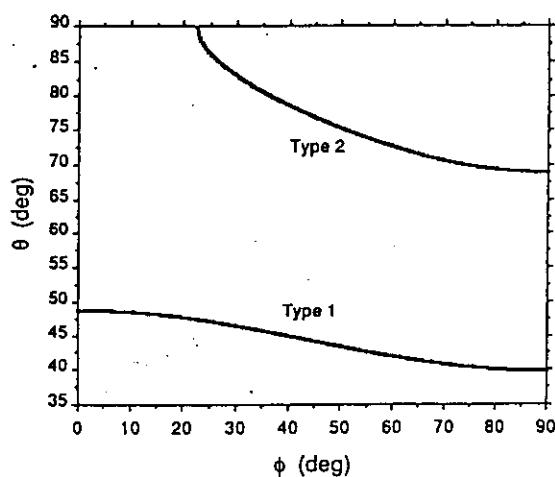
Phase matching angle calculation

CPU



47

Phase Matching Angle for KTP



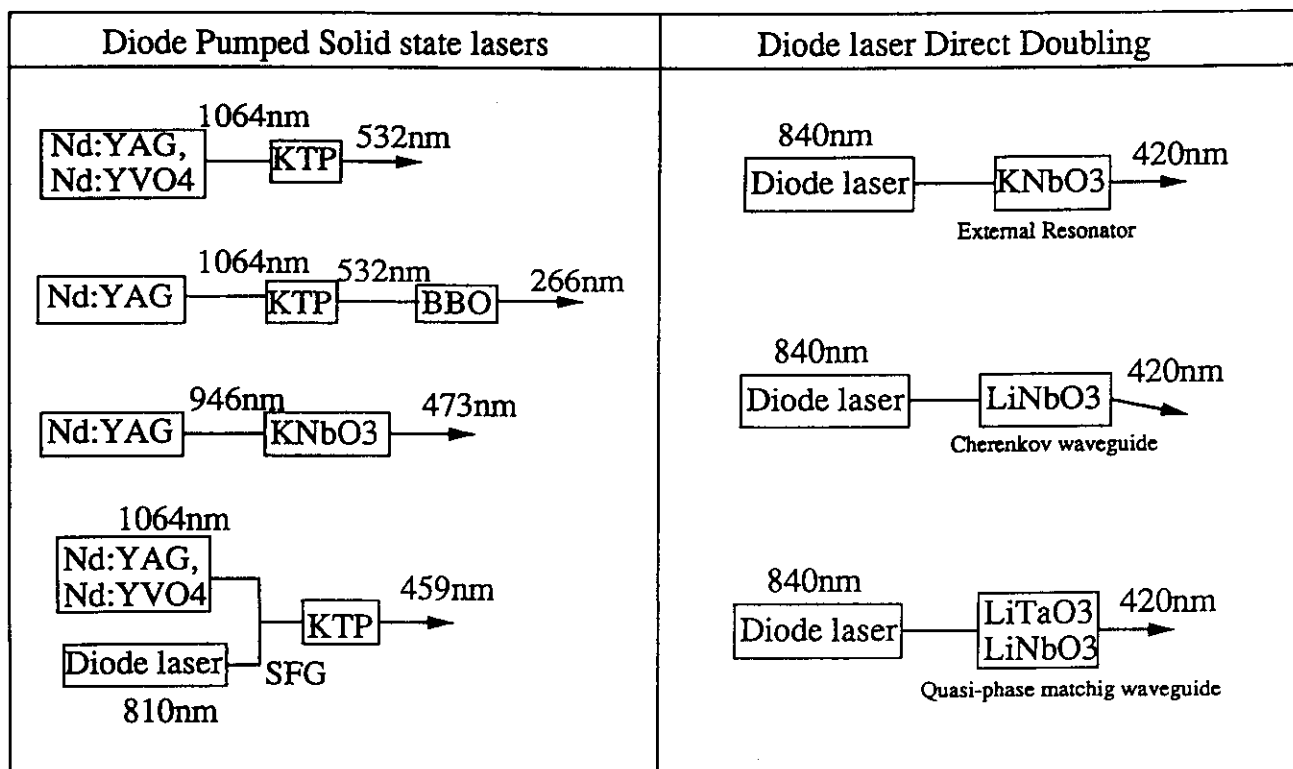
42

SHG Crystals

Crystal	Transparent Wavelength (μm)	Nonlinear Coefficient (pm/V)	Temperature Tolerance ($^{\circ}\text{C}$)	Crystal Size (cm)
LiNbO_3 (LN)	0.4~4.4	$d_{31} = -6.5$ $d_{33} = -34.0$	0.7	CZ 9 ϕ x10
LiTaO_3 (LT)	0.28~4.4	$d_{33} = 26$		
KTiOPO_4 (KTP)	0.35~4.0	$d_{24} = 7.0$ $d_{33} = 13.7$	25.0	Flux 2x3x5
KNbO_3 (KN)	0.3~4.0	$d_{31} = -12$ $d_{33} = -20$	0.3	TSSG 2x2x4
$\beta\text{-BaB}_2\text{O}_3$ (BBO)	0.19~3.5	$d_{11} = 1.6$	55.0	CZ 1.5 ϕ x5

35

Harmonics Generation



43

36

Comparison of SHG devices

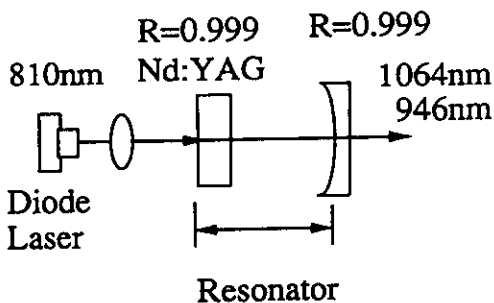
	Phase matching	Structure	Evaluations
Bulk	Intracavity		Efficiency Difficulty Single mode Direct modulation
	External Resonator		High Efficiency Diode wavelength control
Waveguide	Cherenkov $\cos\alpha = N(\omega)/n(2\omega)$		Wavelength tolerance Collimation Difficulty
	Quasi-phase matching		Point source Wavelength tolerance ~ 0.2nm

50

Intracavity SHG

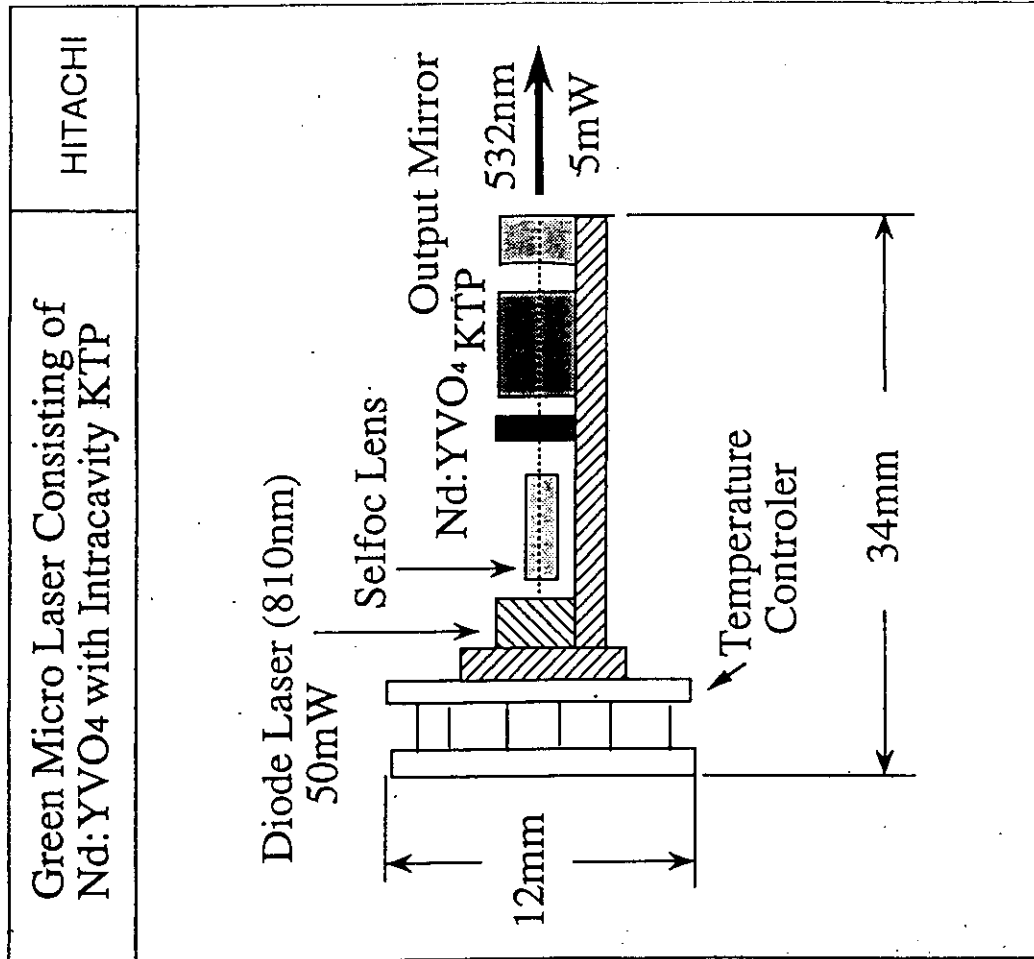
Diode laser pumped solid state laser

$$I_{th} \propto \sigma \tau$$



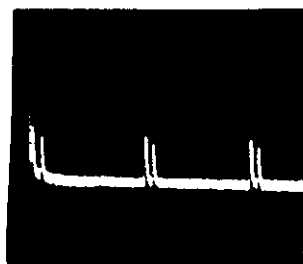
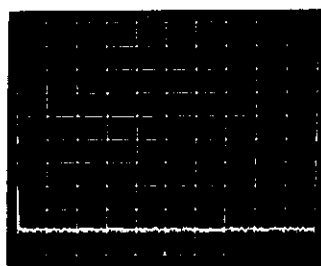
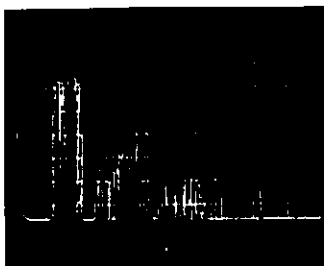
1. Laser itself tune resonance frequency
2. Impedance matching

	λ nm	emission cross sec. σ cm^2	life time τ μs	$\lambda_{\text{abs.}}$ nm	abs. cm^{-1}
Nd:YAG	1064 946	4.6E-19	230	809	7.5
Nd:YVO ₄	1064	2.5E-18	90	809	40
LNP	1047	1.7E-19	130	805	115
NYAB	1062	10E-19	60	804	6.8
Nd:GdVO	1064	6E-19		808	70.0
Nd:S-VAP (Sr ₅ (VO ₄) ₃ F)	1064	5E-19	230	809	

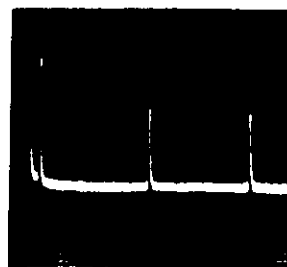


Green Problem = Intracavity Problem

Noise spectrum



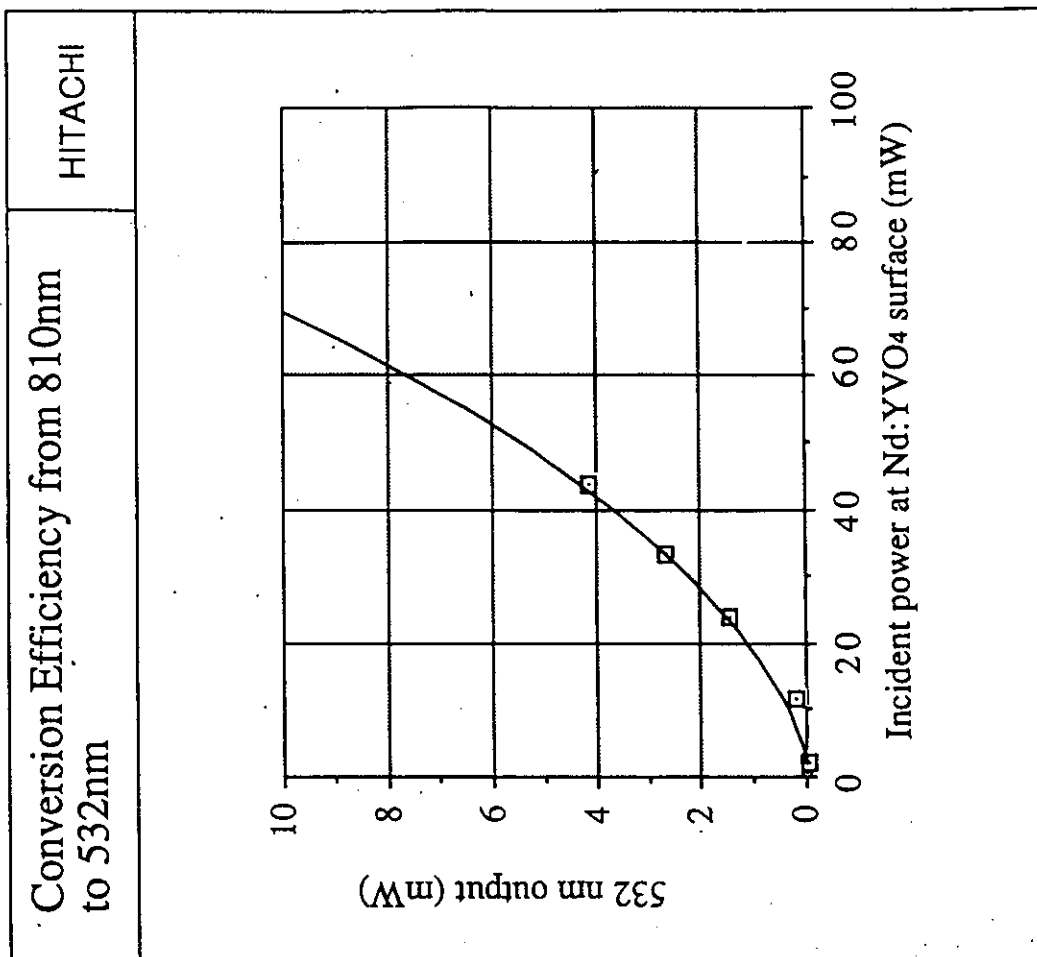
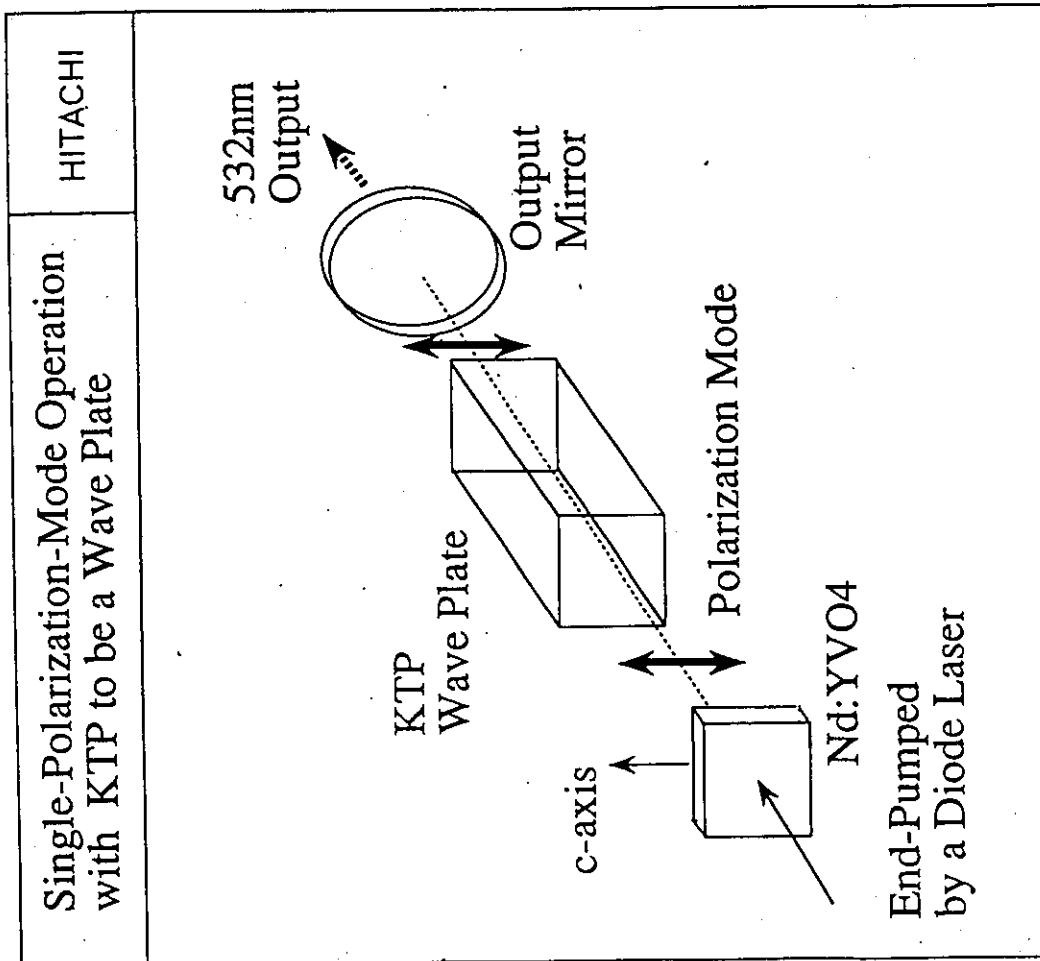
Multimodes

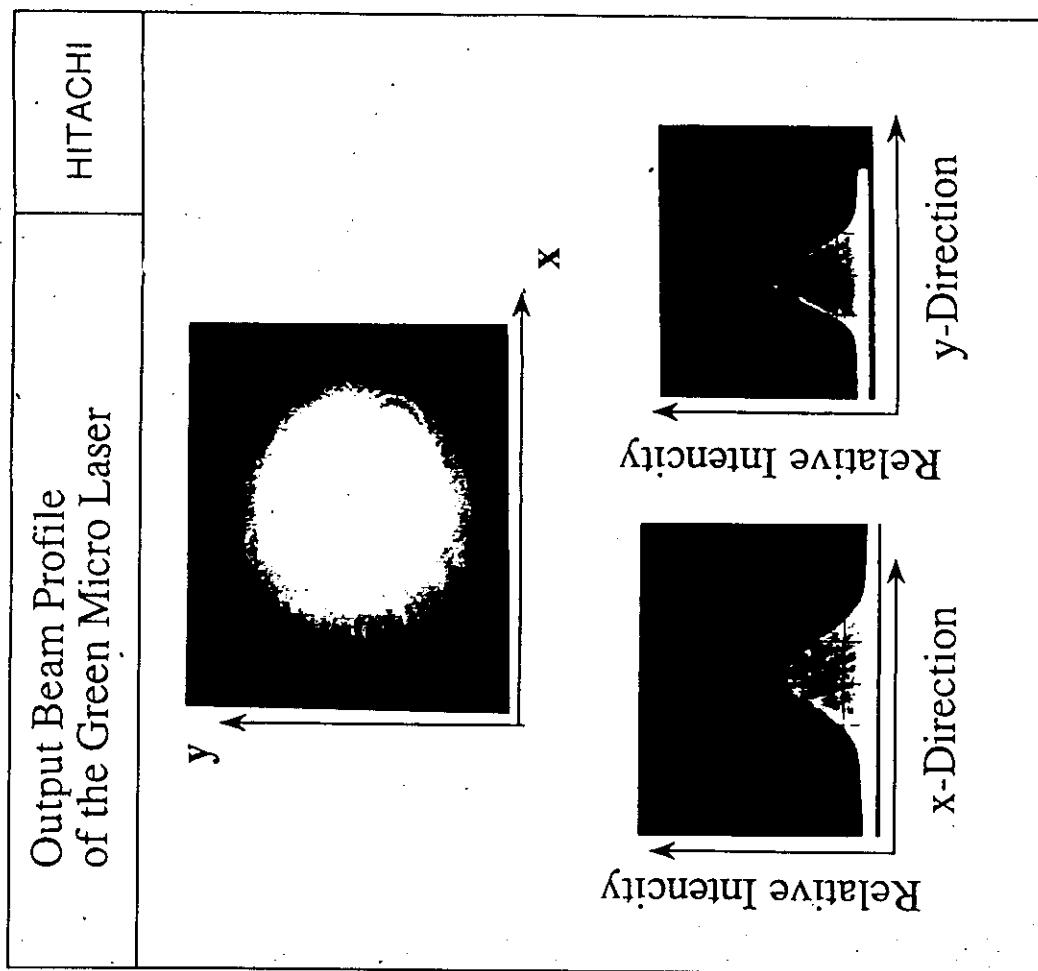


Single mode

Noise suppression in Intracavity SHG

Axial mode
1. Elimination of spatial holeburning
Twisted mode
Traveling wave ring resonator
2. Mode selection
Etalon
Polarization mode
1. KTP to be a Total wave plate
2. Quarter wave plate





Sum-frequency Generation

$$\omega_3 = \omega_1 + \omega_2, \quad v = \omega\lambda/2\pi$$

$$k_3 = k_1 + k_2, \quad k = 2\pi/\lambda$$

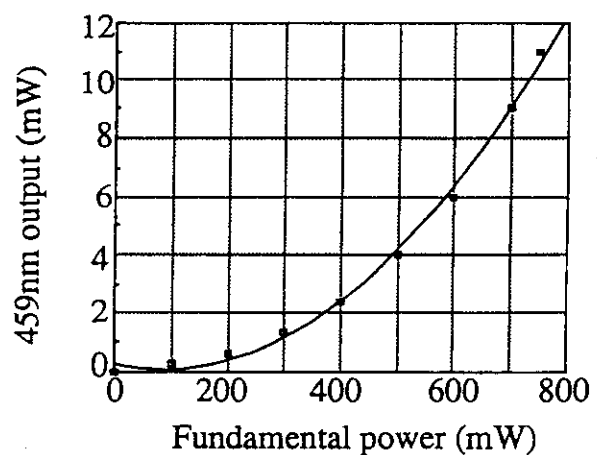
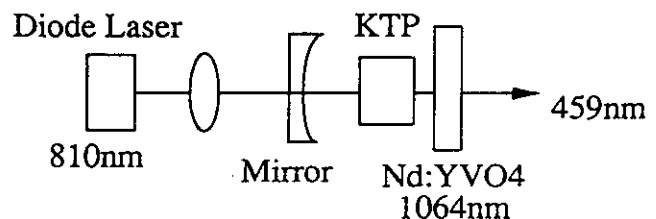
$$\omega_3 n_3 = \omega_1 n_1 + \omega_2 n_2$$

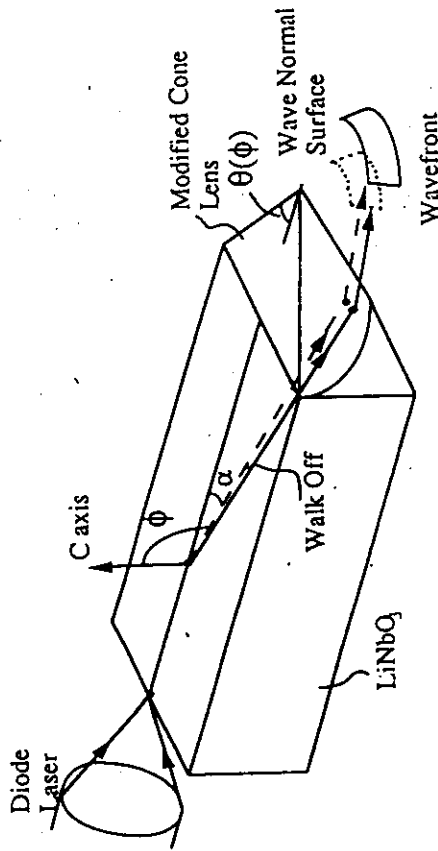
$$\omega_1 \neq \omega_2 : \text{SFG}$$

$$\omega_1 = \omega_2 : \text{SHG}$$

$$n_1 = n_2 : \text{Type I}$$

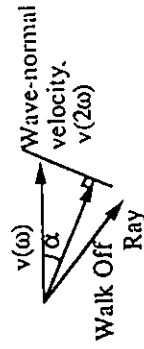
$$n_1 \neq n_2 : \text{Type II}$$





1) Phase Matching Condition

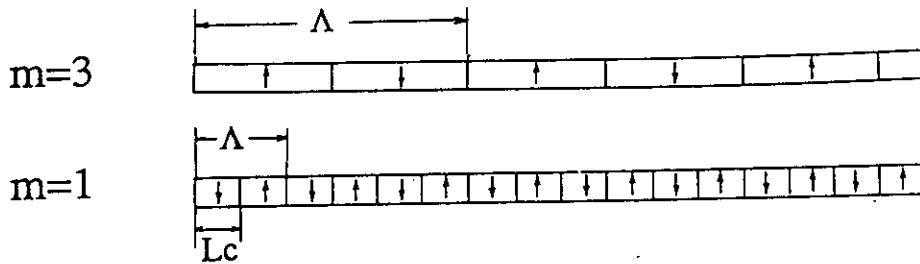
$$\cos\alpha = \frac{N(\omega)}{n_e(2\omega)}$$



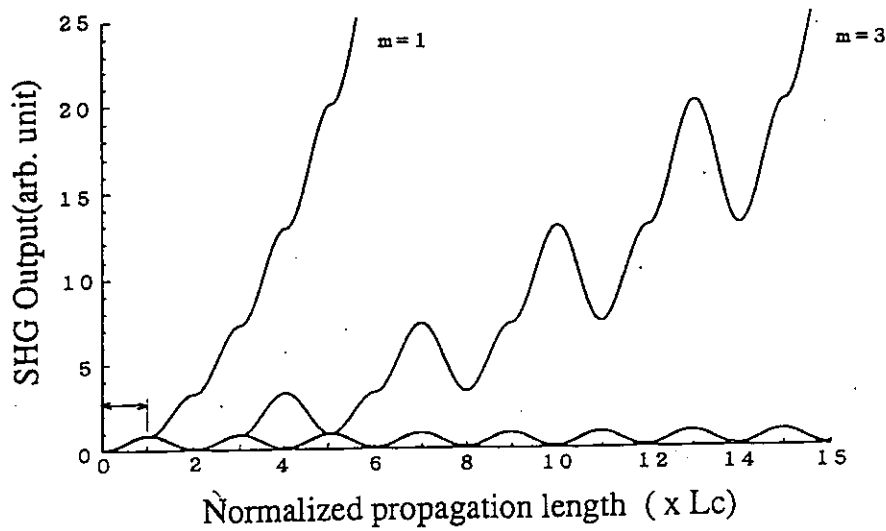
2) Modified Apex Angle of Conic Lens

$$\theta(\phi) = \frac{\pi}{2} - \tan^{-1} \left[\frac{\sin\alpha(\phi)}{\cos\alpha(\phi) - \frac{1}{n_e(\phi)}} \right]$$

Quasi-phase Matching



$$\Lambda = 2mL_c, \quad m : \text{odd integer}$$



Equation (2)

$$\frac{\partial E}{\partial z} = -i \frac{2\omega^2}{k_{2\omega}} \epsilon_0 \mu_0 \chi^{(2)} E_{\omega}^2 \exp(i\Delta k z) \quad , \quad d = \chi^{(2)}/2$$

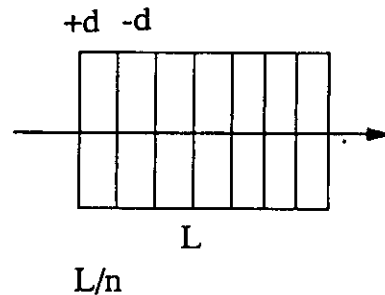
L is divided into n parts and sign of d changes periodically in the integration

when $L/n = mL_c = m\pi/\Delta k$ m : odd number

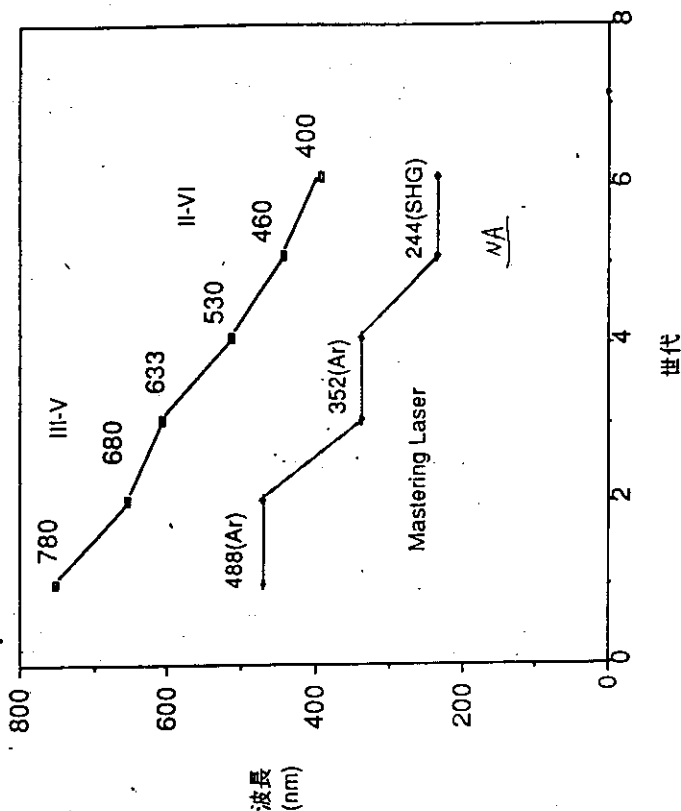
$$E(2\omega) \propto i(2d_{\text{eff}}/m\pi)L$$

Quasi-phase matching nonlinear coefficient is given by

$$d_{\text{QPM}} = (2/m\pi) d_{\text{eff}}$$



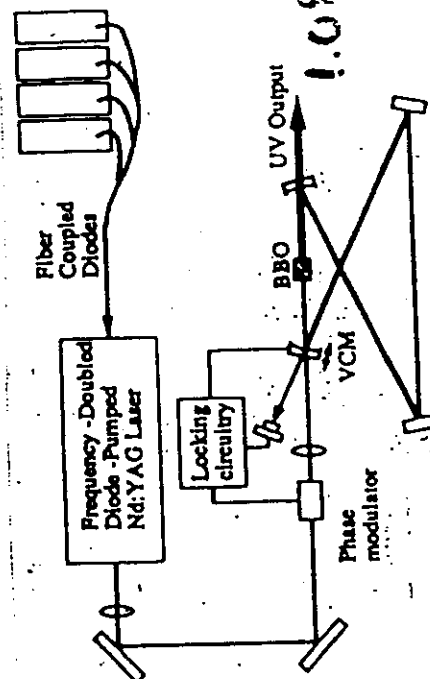
UV-SHGの必要性



特性	Ar レーザ	紫外SHGレーザ	エキシマレーザ
波長 nm	488/352	257, 244	248, 193
出力 mW	100mW	100mW/1W(Ar)	1W/100W
発振	連続	←	パルス
モード	横	←	高次、多数
	縦	←	多数
スペクトル幅	1pm以下	←	数pm/0.5nm
狭スペクトル化	不要	←	フィルタ要

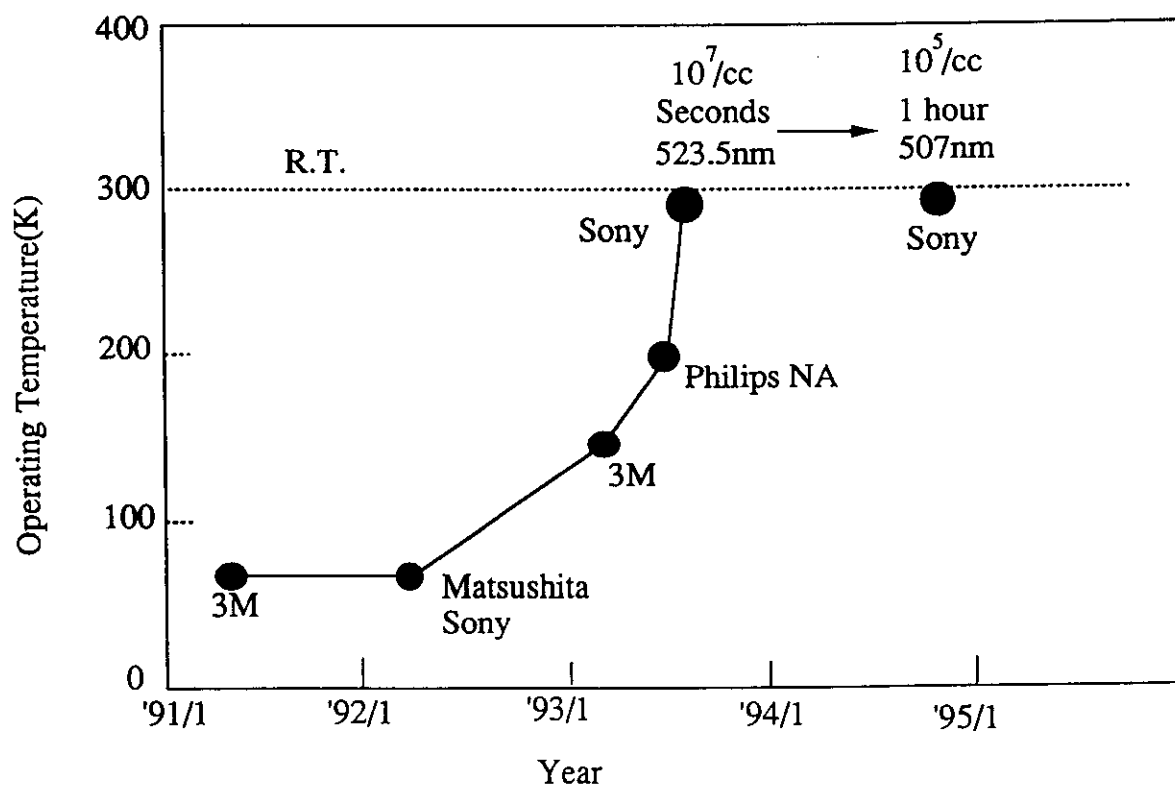
1-W cw 266-nm radiation from an external resonant cavity using a novel voice-coil-motor actuator

M. Oka, N. Eguchi, L. Y. Liu,
W. Wiechmann, S. Kubota, Kubota
Optoelectronics Laboratory, Sony Corporate
Research Laboratories, 6-7-35,
Kitashinagawa, Shinagawa-ku, Tokyo, 141
Japan



CThM1 Fig. 2. Schematic of cw frequency quadrupled diode-pumped Nd:YAG laser.

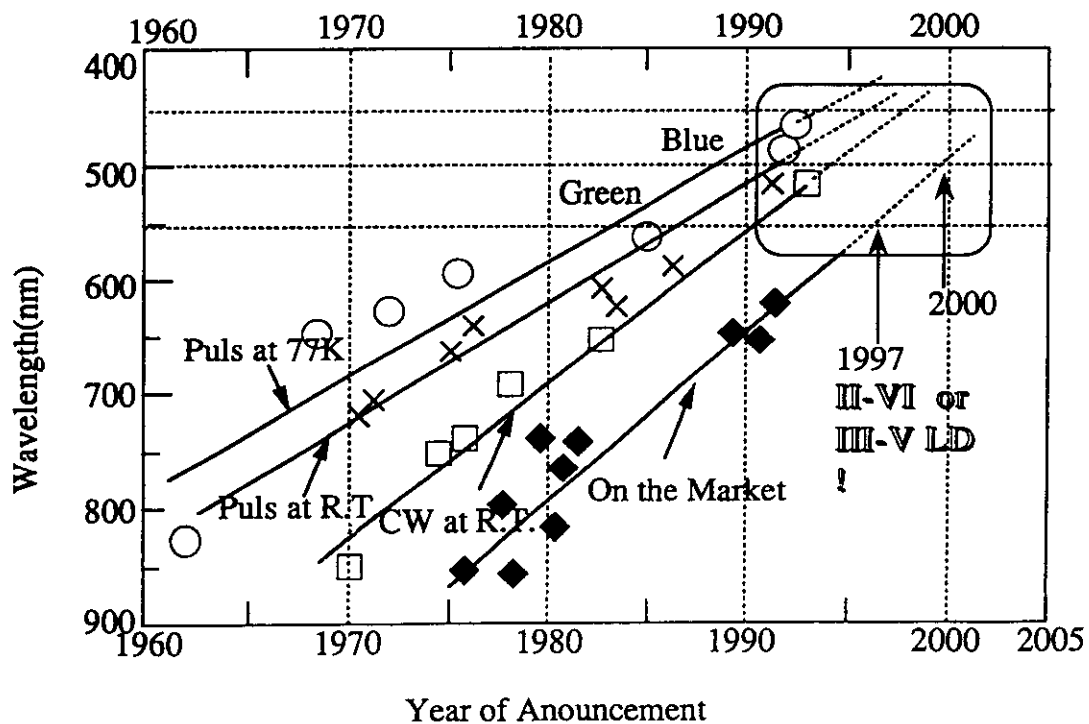
CW Operation Temperature



II-VI lasers today's status

	Requirements for practical use	II-VI lasers Status (507nm)
CW operation	3-5mW at RT	1mW/5 μ m at RT
Lateral mode	Diffraction limited	Multimode
* Longitudinal	Single or Multi	Multimode
Output power	>300mW at RT	70mW pulsed at RT
Operating Temp.	0~50 C	CW to 293K
Voltage	2.0 V	6~7V
Device lifetime	10,000 hours	1 hour CW at RT

A. Ishibashi & S. Itoh:LEOS'94 PD-1-1(Boston) Oct.31~Nov 3

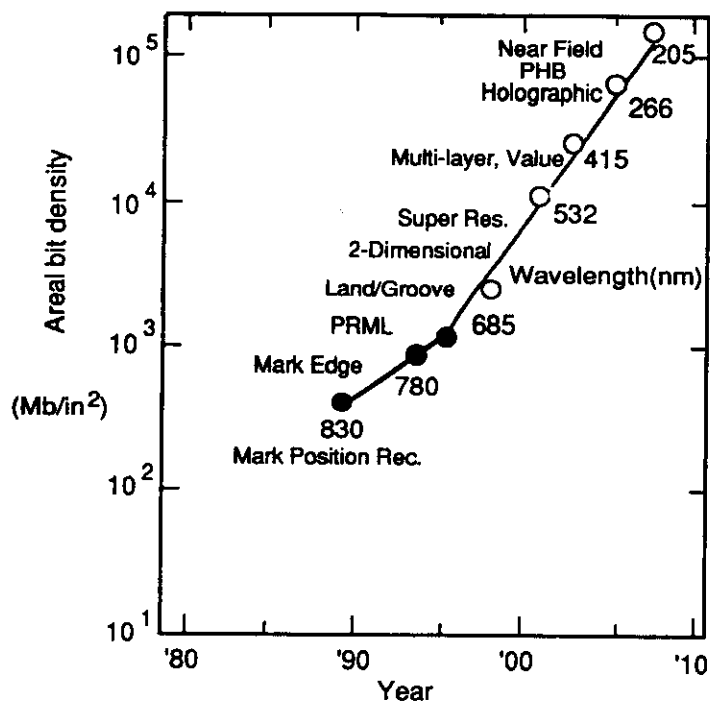


Progress of compact blue/green lasers for optical storage

Type	SH-Crystal	Wave-length	SHG Scheme	Conv. efficiency SH/LD	Size	Application	Maker	Ref
Bulk	KTP	532	LDpump-Nd:YAG Intracavity	5mW/150mW	8cc	Read only	Sony	[5]
		532	LDpump-Nd:YVO Intracavity	5mW/50mW	5cc	M/O-SH read/ LD write	Hitachi	[3]
	KN	429	LD direct External cavity	54mW/125mW	1000cc	M/O direct mod.	IBM Coherent	[6]
Waveguide	KTP	430	BPM- Segment	2mW/150mW	3.5cc	—	DuPont SDL	[7]
	LT	429	QPM Proton ex. heat	2mW	8cc	—	Matsushita	[8]
LD	ZnCdSe	508	—	1mW, 60min RT	0.1cc	—	Sony	[9]
LED	GaN	450	—	(2mW)	0.1cc	—	Nichia	—

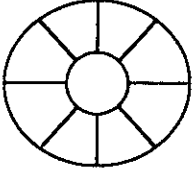
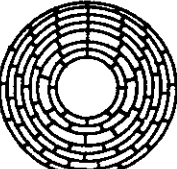
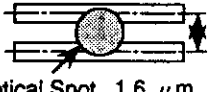
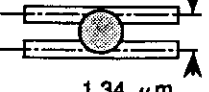
Status of Blue/Green Light Sources for Optical Disks

	Approaches		Status
SHG	Diode pumped laser Intracavity		Single mode operation for the Long term stability, Size, Cost
	Direct doubling of diode lasers	External cavity	Diode laser stability, λ locking, Size, Cost
		QPM-Waveguide	Diode laser stability, λ locking, Efficiency, Size, Cost
Diodes	Wide band gap		II-VI Reduction of Defects to realize 10,000 hrs
			III-V 80,000 hrs LED Lasing

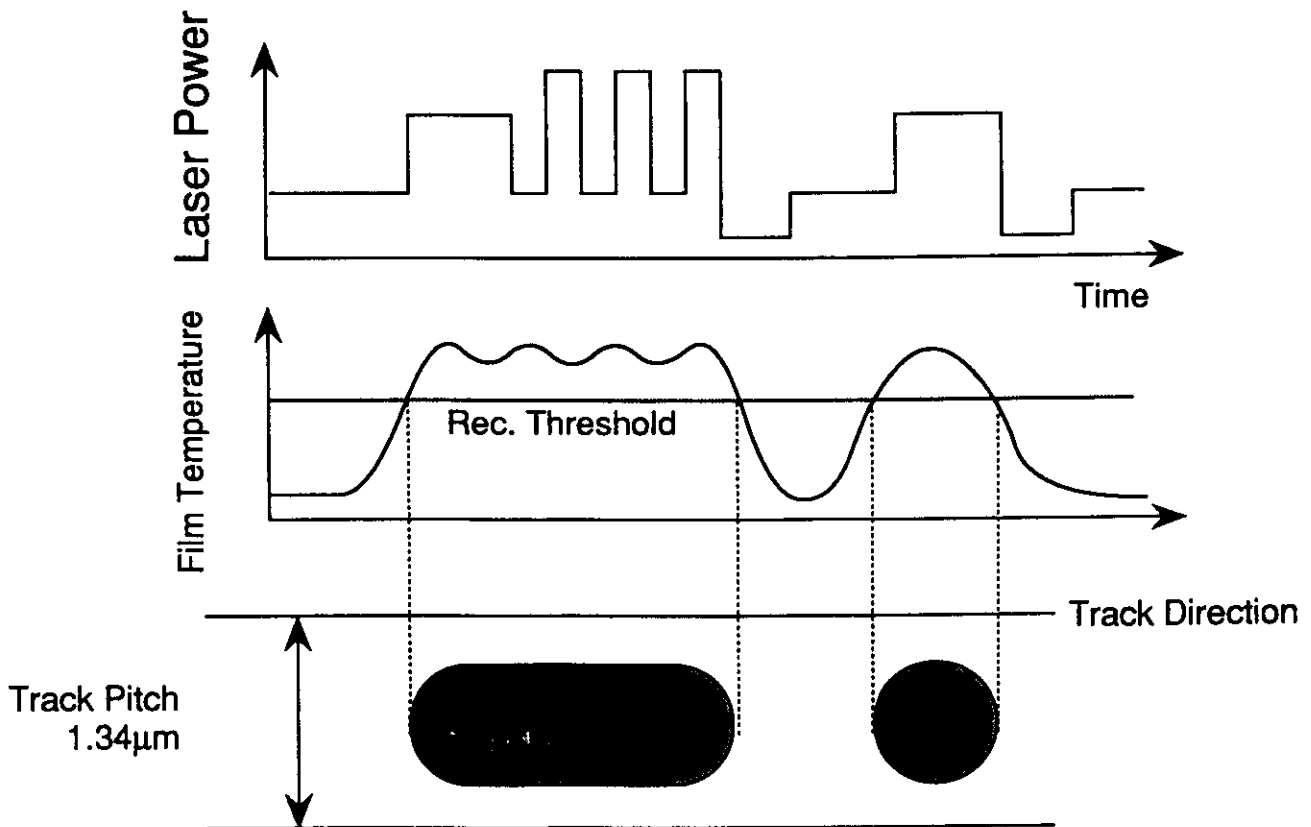
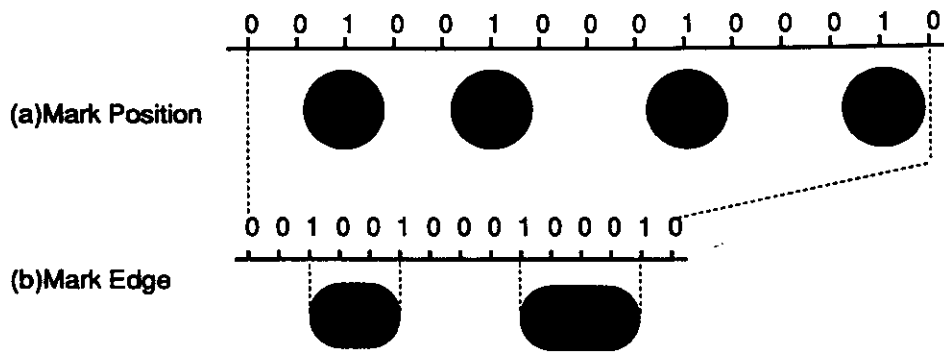


Approaches for M/O higher density

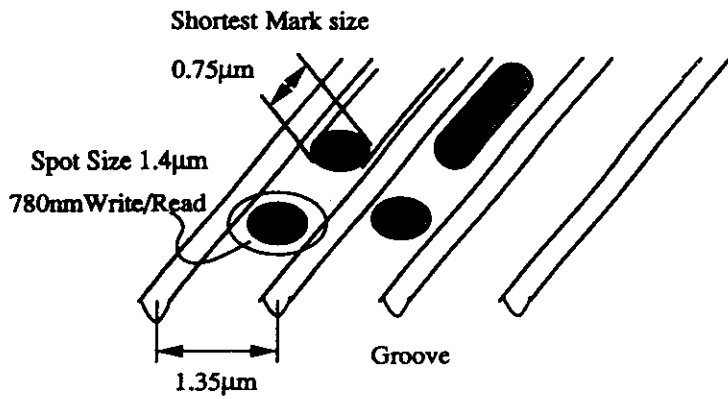
Mark Edge Recording

	1st Gen.	2nd Gen. (3 X)	Enhance
Rec. Method	Mark Position  1 0 1	Mark Edge  1 0 1 0 1 0 0 1	1.8 X
Disk Format	 CAV Inn. Dens. > Outer Dens.	 Zoned CAV Uniform Dens.	1.5 X
Track Pitch	 Optical Spot 1.6 μm	 1.34 μm	1.2 X

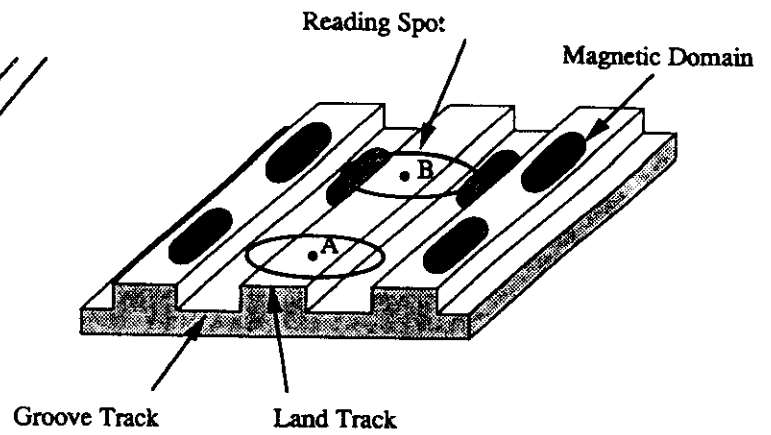
Mark Edge Recording



Recording Pulse Control

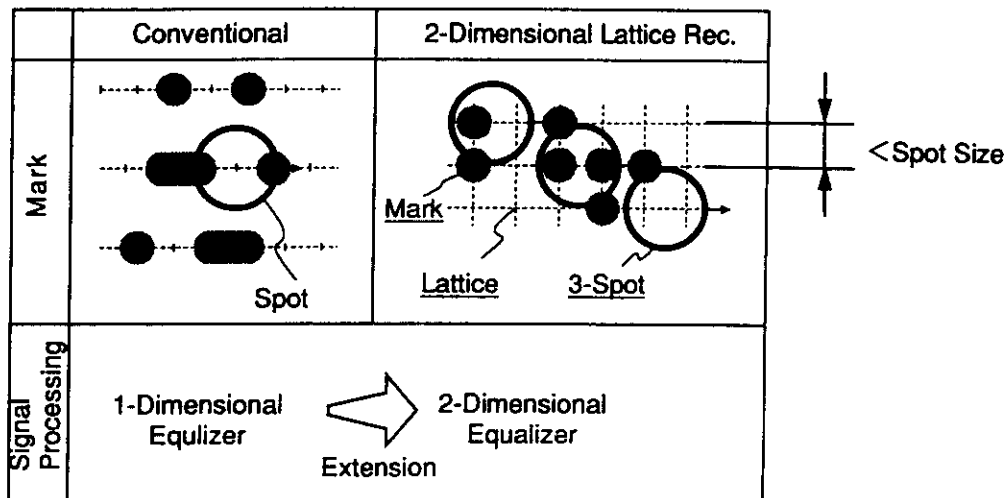


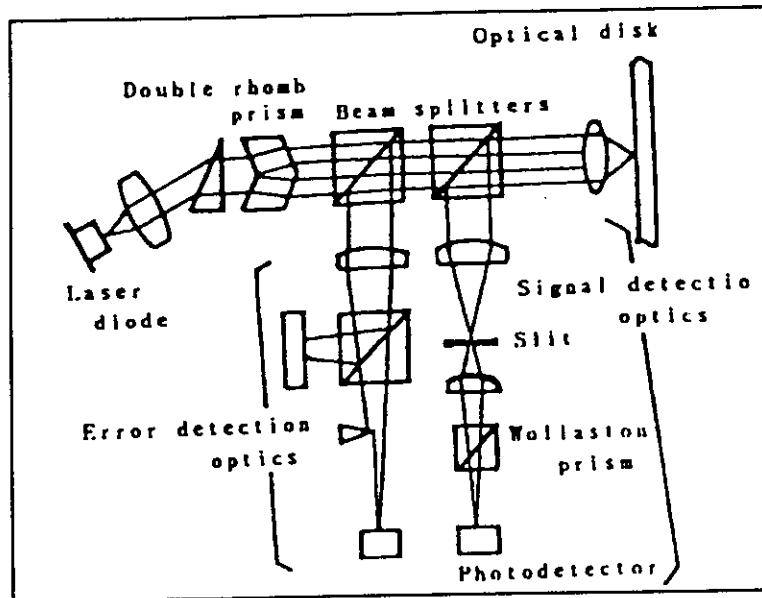
Conventional M/O Disk Structure



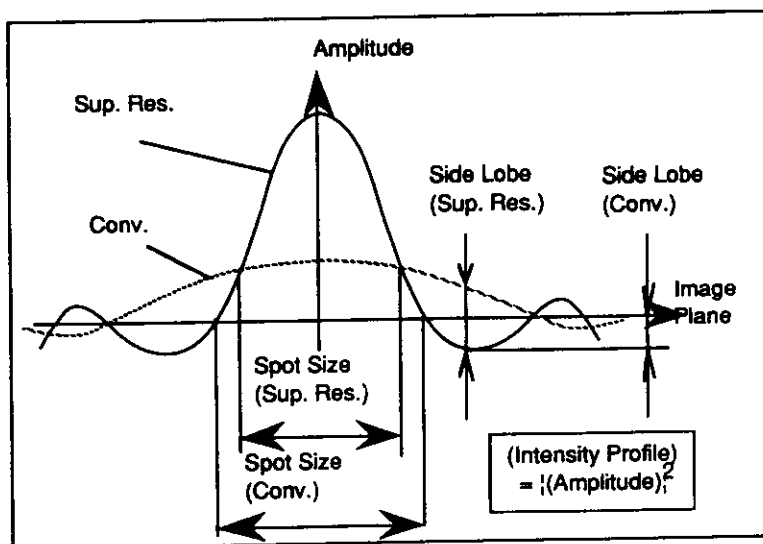
Land/Groove Recording

2-Dimensional Lattice Recording

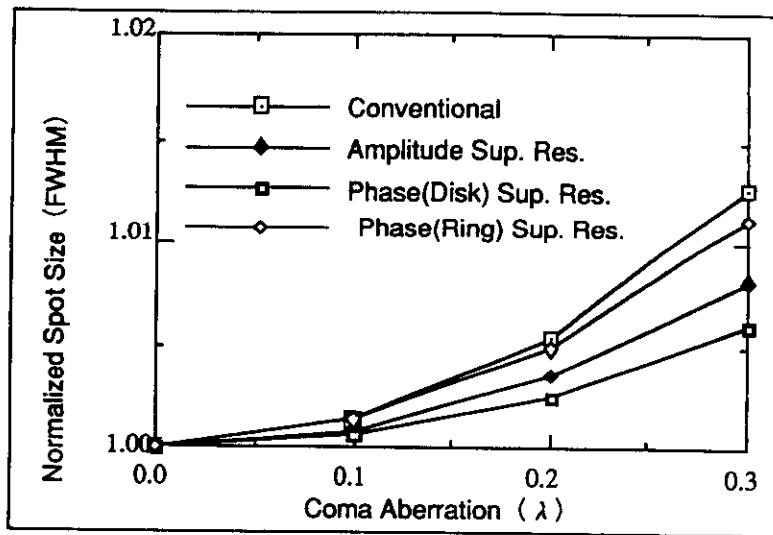




Super Resolution Optical Head

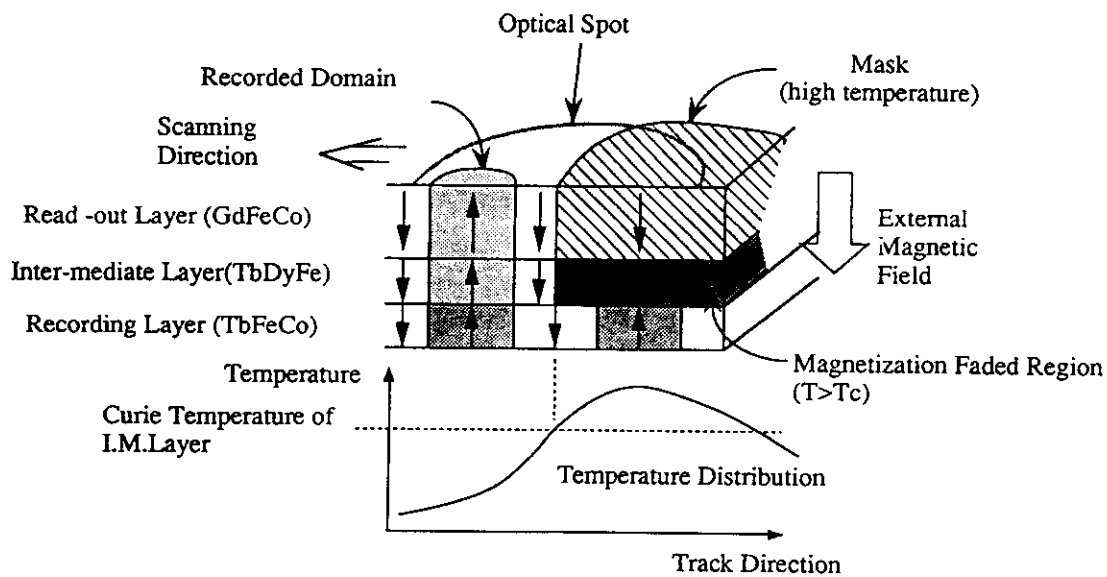


Optical Super Resolution

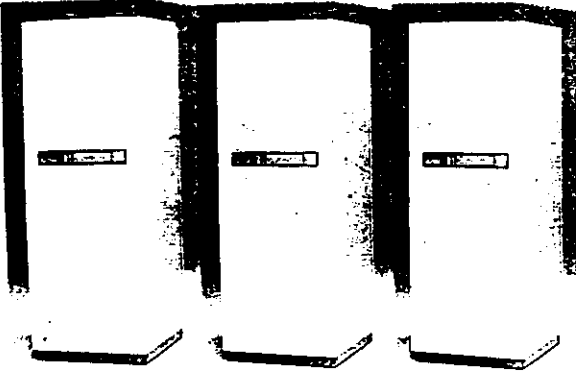
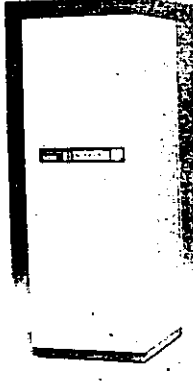


Super Res. vs Coma Aberration

Magnetic Super Resolution (FAD)



TByte File & Wavelength

Wavelength	780nm(New Products '93)	530nm	420nm	Evanescent Wave
	 OL 152-180			
Size (mm)	(1850 h X 700 d X 650 w) X 3	1850 h X 700 d X 650 w	700 h X 700 d X 490 w	On your hand
5.25" M/O Disk	494 pieces	192	60	1

HCRL-940127-6-3

HITACHI

Optical Disks VS Wavelength

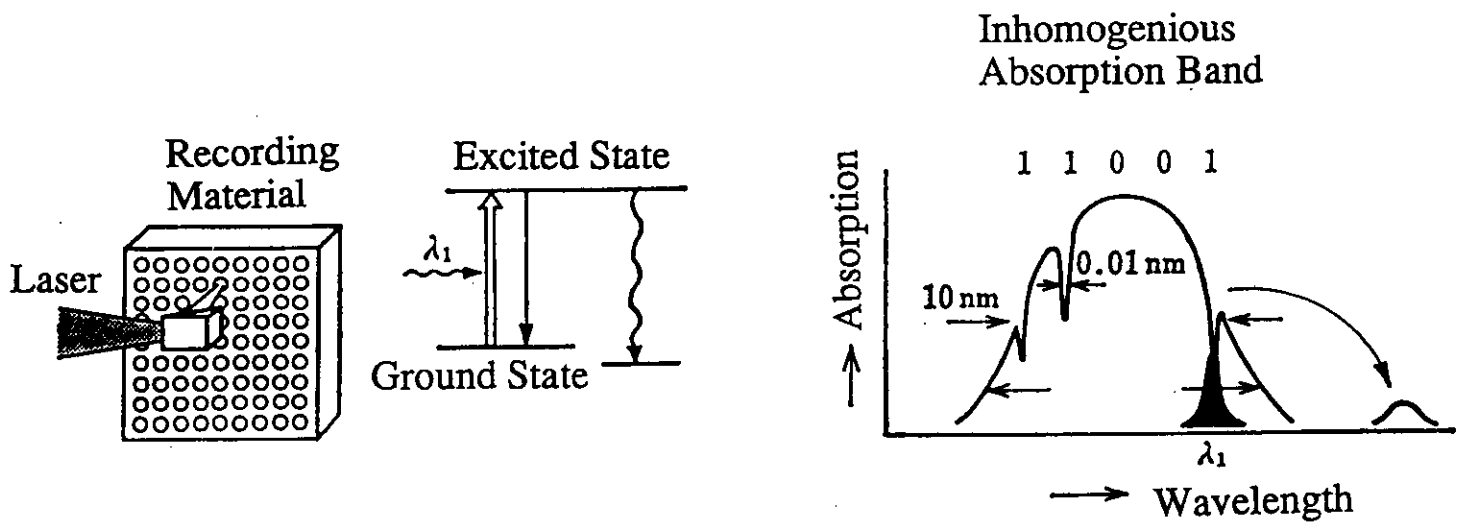
Generation / Wavelength	Audio-Video (5", 3.5", 2.5")	Personal Comp. (3.5", 2.5")	Juke Box Library (5", 12")
1st / IR '82~	CD, DVD(60min) MPEG 1	CD-ROM 650MB 3.5" 128MB M/O	300GB/unit
2nd/ Red '96~	DVD(140min /side) MPEG2	CD-ROM 5GB 3.5" 650MB M/O, PC	500GB/unit
3rd / Green Blue '99~	3.5" DVD 5" HDTV	2.5" >500MB 3.5" >GB M/O, PC	> TB/unit



Fig.2 Schematic diagram of optical coupling between laser diode and optical fiber.



Photo-chemical Hole Burning



Optical Network & Optical Disks

